1.8V 1G-bit/2G-bit/4G-bit Serial NAND Flash Memory

MX35UFxGE4AD

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Contents

1. FEATURES 5

2. GENERAL DESCRIPTIONS 6

Figure 1. Logic Diagram 6

3. ORDERING INFORMATION 7

4. BALL ASSIGNMENT AND DESCRIPTIONS 8

Figure 2. 8-WSON (8x6mm) 8
Figure 3. 24-Ball BGA (5x5 Ball Array) 8

5. PIN DESCRIPTIONS 8

6. DEVICE OPERATION 9

Figure 4. Serial Mode Supported 9

7. ADDRESS MAPPING 10

8. COMMAND DESCRIPTION 11

Table 1. Command Set - Standard Operation 11

8-1. WRITE Operations 12

8-1-1.Write Enable 12

Figure 5. Write Enable (WREN) Sequence 12

8-1-2.Write Disable (04h) 12

Figure 6. Write Disable (WRDI) Sequence 12

8-2. Feature Operations 13

8-2-1.GET Feature (0Fh) and SET Feature (1Fh) 13

Table 2. Configuration Registers 13
Table 3. Register status of Reset (FFh) command operation 14
Table 4. I/O Strength Feature Table 14
Figure 7. GET FEATURE (0Fh) Timing 15
Figure 8. SET FEATURE (1Fh) Timing 15

8-3. READ Operations 16

Table 5. Supported Read Command Table for Different Modes 16
Table 6. Data Output Range Per Page 16

8-3-1.PAGE READ (13h) 16

8-3-2.QE bit 16

Figure 9. PAGE READ (13h) Timing x1 17
Figure 10. READ From CACHE (03h or 0Bh) Timing 18
Figure 11. READ FROM CACHE x 2 19
Figure 12. Read From Cache Dual IO 1-2-2 20
Figure 13. READ FROM CACHE x 4 21
Figure 14. Read From Cache Quad IO 1-4-4 22

8-3-3.Page Read Cache Random (30h)/Page Read Cache Sequential (31h)/Page Read Cache End (3Fh) 23

Figure 15. Page Read Cache Random (30h) 23
Figure 16. Page Read Cache Sequential (31h) 24
Figure 17. Page Read Cache End (3Fh) 25
Figure 18. Page Read Cache Flow 26

8-3-4.Continuous Read Operation 27

Figure 19. Continuous Read Waveform 27
Table 7. Command Set - Continuous Read Operation Enabled 28

8-3-5.Special Read for Data Recovery 29

Figure 20. Procedure of Entering/Exiting the Special Read for Data Recovery operation 29
Table 8. Feature Settings 29

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8-4. READ ID (9Fh) 30
Table 9. READ ID Table 30
Figure 21. READ ID (9Fh) Timing 30
8-5. Parameter Page 31
Table 10. Parameter Page - MX35UF1GE4AD 31
Table 11. Parameter Page - MX35UF2GE4AD 33
Table 12. Parameter Page - MX35UF4GE4AD 35
8-6. UniqueID Page with PUF Type Code Structure 37
8-7. Internal ECC Status 37
8-7-1.Internal ECC Enabled/Disabled 37
Table 13. The Distribution of ECC Segment and Spare Area - 1Gb/2Gb 37
Table 14. The Distribution of ECC Segment and Spare Area - 4Gb 38
Table 15. The Distribution of ECC Segment and Spare Area - 4Gb (Cont'd) 38
8-7-2.Read ECCSR (7Ch) command for ECC Status Read 39
8-8. Flexible ECC Bit Flip Threshold Setting & Read ECC Warning Page Address 40
Table 16. Flexible ECC Bit Flip Threshold Setting & Read ECC Warning Page Address 40
Figure 22. ECC Warning Timing 41
8-9. Program Operations 42
8-9-1.PAGE PROGRAM 42
Figure 23. PROGRAM LOAD (02h) Timing 42
Figure 24. PROGRAM LOAD RANDOM DATA (84h) Timing 43
8-9-2.QUAD IO PAGE PROGRAM 44
Figure 25. PROGRAM LOAD X4 (32h) Timing 44
Figure 26. QUAD IO PROGRAM RANDOM INPUT (34h) Timing 45
Figure 27. PROGRAM EXECUTE (10h) Timing 46
8-10. BLOCK OPERATIONS 47
Figure 28. Block Erase (BE) Sequence 47
9. SPI NOR Compatible Command 48
Table 17. Command Set - SPI NOR Like Protocol Enabled 48
Table 18. Command Set - SPI NOR Like Protocol Enabled & Continuous Read Operation 49
Figure 29. Read From Cache x1 (NOR like) 50
Figure 30. Read From Cache x1 (Alternative, NOR like) 51
10. Feature Register 52
10-1. Configuration Feature Operation 52
10-1-1.Type: Volatile Register [Symbol: V] 52
10-1-2.Type: Volatile Register with OTP Fuse Default Value [Symbol: V2] 52
10-1-3.Type: One-time Setting Register [Symbol: OTP] 52
Figure 31. Setting of Volatile Configuration Register 52
Figure 32. Setting of Volatile Configuration Register (Type: V2) 52
10-2. OTP "Configuration" Register Solid Protection 53
Figure 33. Special OTP Configuration Register Program Operation (for V2/OTP Type of Configuration Register Bits) 53
10-3. Block Protection Feature 54
Table 19. Definition of Protection Bits 55
10-4. Secure OTP (One-Time-Programmable) Feature 56
Table 20. Secure OTP States 56
11. Configuration Registers and Status Registers 57
11-1. Status Register 57
11-1-1.Get Feature command (0Fh) 57
11-1-2.Read Status command (RDSR, 05h) 57
Figure 34. Read Status Register (RDSR) 57
Table 21. Status Register Bit Descriptions 58
Table 22. Configuration Register Bit Descriptions 59

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12. SOFTWARE ALGORITHM 60

12-1. Invalid Blocks (Bad Blocks) 60
Figure 35. Bad Blocks 60
Table 23. Valid Blocks 60

12-2. Bad Block Test Flow 61
Figure 36. Bad Block Test Flow 61
Figure 37. BBM Table 62
Figure 38. Write BBM Command (A1h) 62
Figure 39. Read BBM Command (A5h) 63
Figure 40. Bad Block Management 64
Table 24. BBM Address Definition 64

12-3. Failure Phenomena for Read/Program/Erase Operations 65
Table 25. Failure Modes 65

13. DEVICE POWER-UP 66

13-1. Power-up 66
Figure 41. Power Up/Down and Voltage Drop 66
Table 26. Power-Up/Down Voltage and Timing 66

14. PARAMETERS 67

14-1. ABSOLUTE MAXIMUM RATINGS 67
Figure 42. Maximum Negative Overshoot Waveform 67
Figure 43. Maximum Positive Overshoot Waveform 67
Table 27. AC Testing Conditions 67
Table 28. Capacitance 68
Table 29. Operating Range 68
Figure 44. SCLK TIMING DEFINITION 68
Table 30. DC Characteristics 69
Table 31. General Timing Characteristics 69
Table 32. Program/ Read/ Erase Characteristics (1Gb/2Gb) 70
Table 33. Program/ Read/ Erase Characteristics (4Gb) 70
Figure 45. WP# Setup Timing and Hold Timing during SET FEATURE when BPRWD=1 71
Figure 46. Serial Input Timing 71
Figure 47. Serial Output Timing 71
Figure 48. Hold Timing 72

15. PACKAGE INFORMATION 73

15-1. 8-WSON (8x6x0.8mm) 73

15-2. 24-BGA (6x8x1.2mm) 74

16. REVISION HISTORY 75

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1. FEATURES

- **1Gb, 2Gb, 4Gb Serial Flash**
  - Bus: x4
  1Gb/2Gb: page size: (2048+64) byte, block size: (128K+4K) byte[Note1]
  4Gb: page size: (4096+128) byte, block size: (256K+8K) byte[Note1]
- **Fast Read Access**
  - Supports Random data read out by x1 x2 & x4 modes, (1-1-1,1-1-2, 1-1-4, 1-2-2, 1-4-4)[Note 2]
  - Latency of array to register: 80us for 1Gb/2Gb, 120us for 4Gb
  - Frequency: 133MHz[Note3]
  - Continuous read supported
- **Page Program Operation**
  - Page program time: 360us(typ.) for 1Gb/2Gb, 400us(typ.) for 4Gb
- **Block Erase Operation**
  - Block erase time: 4ms(typ.)
- **Single Voltage Operation:**
  - VCC: 1.7 to 1.95V
- **BP bits for block group protection**
- **Unique ID Read with PUF type code structure**
- **Low Power Dissipation**
  - Max 40mA
  Active current (Read/Program/Erase)
- **Standby Mode**
  - 110uA (Max) standby current
- **High Reliability**
  - Special Read for data recovery : Enabled by Set Feature
  - Program / Erase Endurance: Typical 60K cycles with 8-bit ECC per (512+32) Byte
  - Flexible ECC Bit Flip Threshold Setting by user
  - Data Retention: 10 years
- **BBM Table (Bad Block Table) supported**
- **Wide Temperature Operating Range**
  -40°C to +85°C
- **Package:**
  1) 8-WSON (8mm x 6mm)
  2) 24-Ball BGA (6x8mm, 5x5 ball array)
  All packaged devices are RoHS Compliant and Halogen-free.

Note 1. *When internal ECC is disable, the page size and block size will be extended to 2KB+128B per page and 128KB+8KB per block (for 1Gb/2Gb), 4KB+256B per page and 256KB+16KB per block (for 4Gb)*

Note 2. *Which indicates the number of I/O for command, address and data.*

Note 3. *fC=133MHz max. for non-continuous read operation.*

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2. GENERAL DESCRIPTIONS

The MX35UFxGE4AD is a 1.8V 1Gb/2Gb/4Gb SLC NAND Flash memory device with Serial interface.

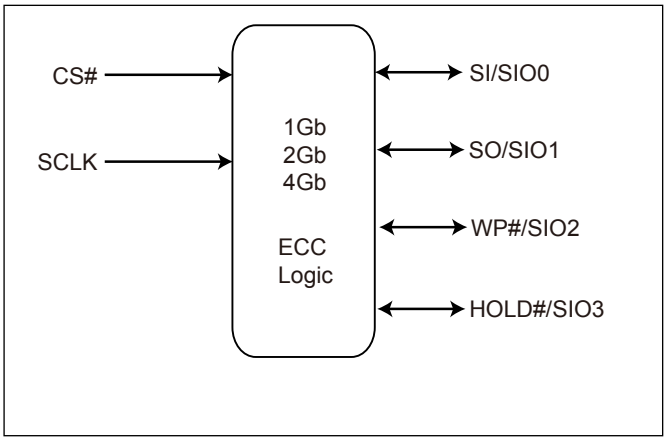
The memory array of this device adopted the same cell architecture as the parallel NAND, however implementing the industry standard serial interface.

An internal 8-bit ECC logic is implemented in the chip, which is enabled by default. The internal ECC can be disabled or enabled again by command. When the internal 8-bit ECC logic is disabled, the host side needs to handle the 8-bit ECC by host micro controller.

The device supports conventional read mode and continuous read modes. If the configuration register bit "CONT" = 0, the device is in conventional read mode which user cannot read across a page without page read command. If the configuration register bit "CONT" = 1, the device is in continuous read mode which user can read consecutive page across page boundary without next page read command.

Considering user effort reduction, the device provides 40 links of BBM (Bad Block Management), which can provide the continuous good blocks to save software effort and increase read throughput. Moreover, user may enhance the P/E endurance cycle of single block by using more than one BBM links for block replacement to same single block. For example, using two BBM links for same single block replacement which may double the P/E cycle of the same single block, using three BBM links may get triple P/E cycle and so on.

Figure 1. Logic Diagram

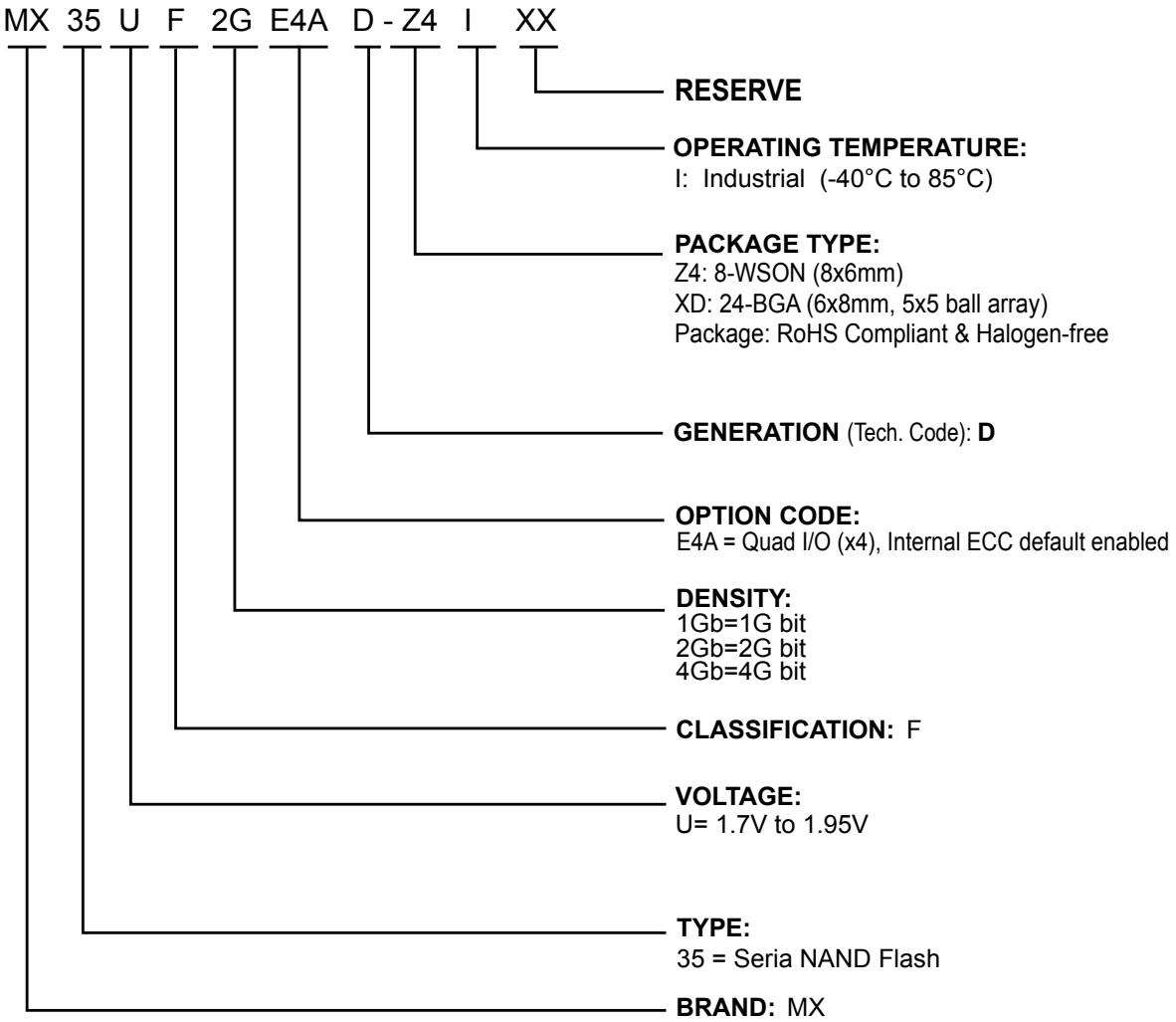


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3. ORDERING INFORMATION

Part Name Description

Macronix New Serial Flash devices are available in different configurations and densities. Verify valid part numbers by using Macronix's product search at http://www.Macronix.com. Contact Macronix sales for devices not found.



Please contact our regional sales for the latest product selection and available form factors.

Part Number	Density	Organization	VCC Range	Package	Temperature Grade
MX35UF4GE4AD-Z4I	4Gb	x4	1.8V	8-WSON	Industrial
MX35UF4GE4AD-XDI*	4Gb	x4	1.8V	24-BGA	Industrial
MX35UF2GE4AD-Z4I	2Gb	x4	1.8V	8-WSON	Industrial
MX35UF2GE4AD-XDI*	2Gb	x4	1.8V	24-BGA	Industrial
MX35UF1GE4AD-Z4I	1Gb	x4	1.8V	8-WSON	Industrial
MX35UF1GE4AD-XDI*	1Gb	x4	1.8V	24-BGA	Industrial

**Advanced Information*

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4. BALL ASSIGNMENT AND DESCRIPTIONS

Figure 2. 8-WSON (8x6mm)

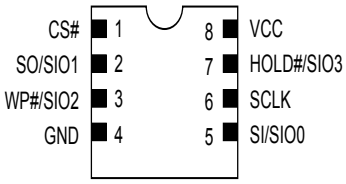
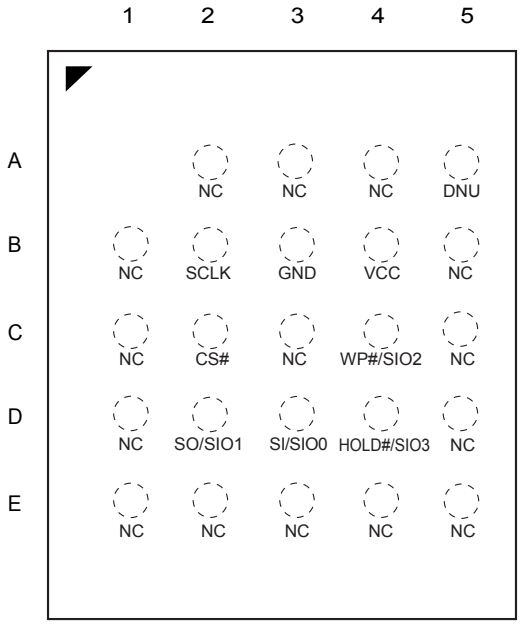


Figure 3. 24-Ball BGA (5x5 Ball Array)



5. PIN DESCRIPTIONS

SYMBOL	DESCRIPTION
CS#	Chip Select
SI/SIO0	Serial Data Input (for 1 x I/O)/ Serial Data Input & Output (For 1-1-2,1-1-4, 1-2-2, or 1-4-4 note1 mode)
SO/SIO1	Serial Data Output (for 1 x I/O)/ Serial Data Input & Output (For 1-1-2,1-1-4, 1-2-2, or 1-4-4 note1 mode)
SCLK	Clock Input
WP#/SIO2	Write protection: connect to GND or Serial Data Input & Output (For 1-1-4 or 1-4-4note1 mode)
HOLD#/ SIO3	Hold or Serial Data Input & Output (For 1-1-4 or 1-4-4note1 mode)
VCC	+ 1.8V Power Supply
GND	Ground
DNU	Do Not Use

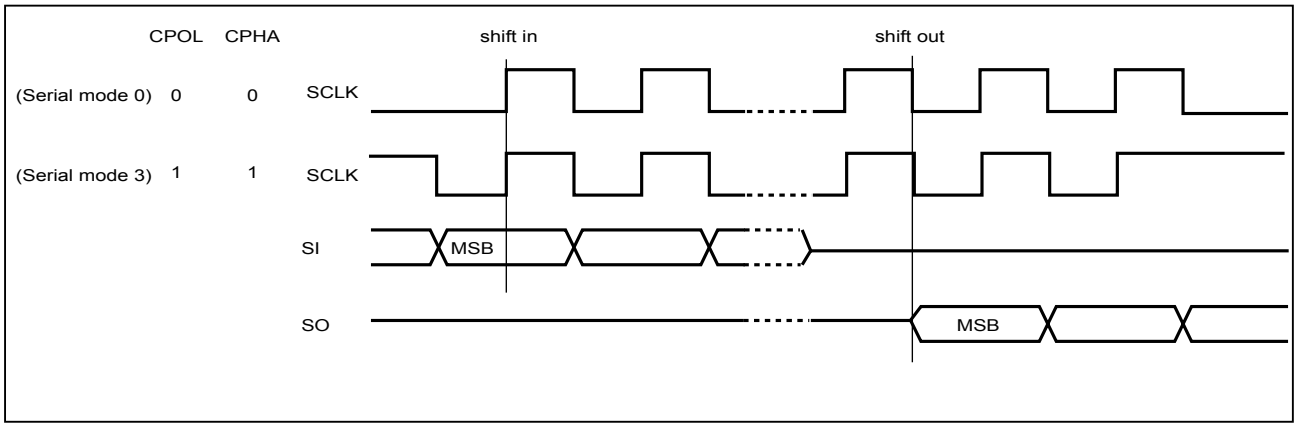
***Note 1**. Which indicates the number of I/O for command, address, and data.*

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6. DEVICE OPERATION

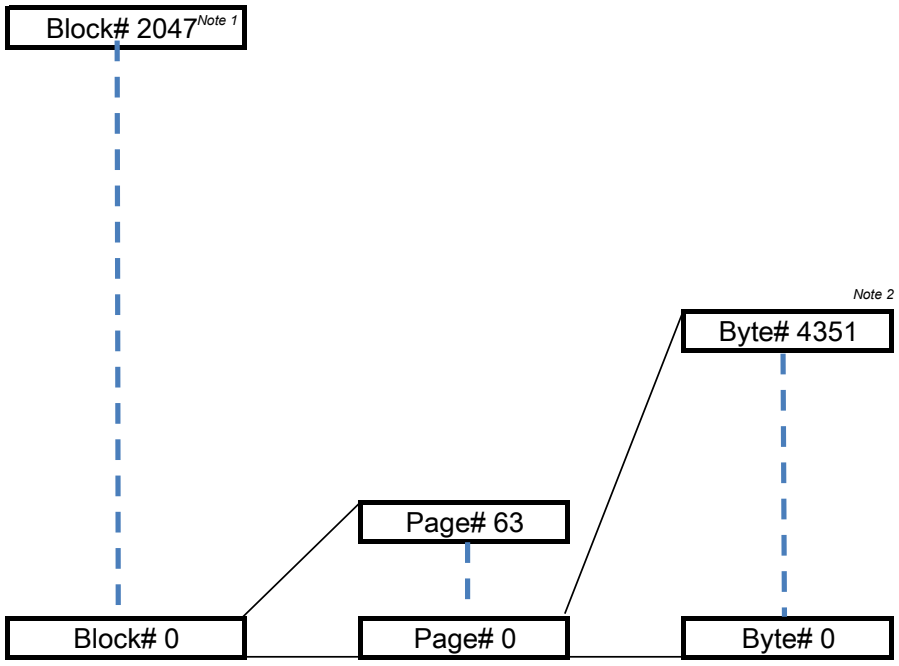
1. Before a command is issued, status register should be checked via get features operations to ensure device is ready for the intended operation.
2. When an incorrect command is written to this device, it enters standby mode and stays in the standby mode until the next CS# falling edge. In standby mode, the device's SO pin should be High-Z.
3. When an correct command is written to this device, it enters active mode and stays in the active mode until the next CS# rising edge.
4. Input data is latched on the rising edge of Serial Clock (SCLK) and data shifts out on the falling edge of SCLK. The difference of Serial mode 0 and mode 3 is shown as **"Figure 4. Serial Mode Supported"**.
5. While a Write Status Register, Program, or Erase operation is in progress, access to the memory array is ignored and will not affect the current operation of Write Status Register, Program, or Erase.

Figure 4. Serial Mode Supported



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7. ADDRESS MAPPING



Block address	Page address	Byte address
2Gb/4Gb: RA [16:6] 1Gb: RA[15:6]	RA [5:0]	CA [12:0]Note 3

Note 1: *2048 for 2Gb/4Gb, 1023 for 1Gb*

Note 2: *Byte#=2175 for 1Gb/2Gb*

Note 3: *CA[11:0] for 1Gb/2Gb*

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8. COMMAND DESCRIPTION

Table 1. Command Set - Standard Operation

(SPI_NOR_EN = 0, CONT = 0)[Note1]

Mode	1st Byte	2nd Byte	3rd Byte	4th Byte	5th Byte	6th Byte	7th Byte	8th Byte
Get Feature	0Fh	ADD	Data					
Read Status	05h	Data						
Set Feature	1Fh	ADD	Data					
Page Read	13h	RADD2	RADD1	RADD0				
Page Read Cache Random	30h	RADD2	RADD1	RADD0				
Page Read Cache Sequential	31h							
Page Read Cache End	3Fh							
Read From Cache x1	03h	CADD1	CADD0	DUMMY	DATA~			
Read From Cache x1 (Alternative)	0Bh	CADD1	CADD0	DUMMY	DATA~			
Read From Cache x2[Note4]	3Bh	CADD1	CADD0	DUMMY	DATA~[*2]			
Read From Cache x4[Note4]	6Bh	CADD1	CADD0	DUMMY	DATA~[*4]			
Read From Cache Dual IO 1-2-2[Note4]	BBh	CADD1[*2]	CADD0[*2]	DUMMY[*2]	DATA~[*2]			
Read From Cache Quad IO 1-4-4[Note4]	EBh	CADD1[*4]	CADD0[*4]	DUMMY[*4]	DUMMY[*4]	DATA~[*4]		
Read ID	9Fh	DUMMY	MID	DID1	DID2			
Block Erase	D8h	RADD2	RADD1	RADD0				
Program Execute	10h	RADD2	RADD1	RADD0				
Program Load x1	02h	CADD1	CADD0	DATA~				
Program Load Random Data x1	84h	CADD1	CADD0	DATA~				
Program Load x4[Note4]	32h	CADD1	CADD0	DATA~[*4]				
Program Load Random Data x4[Note4]	34h	CADD1	CADD0	DATA~[*4]				
Write Enable	06h							
Write Disable	04h							
Reset	FFh							
Read ECCSR	7Ch	DUMMY	SR_ECC					
Write BBM	A1h	LBA	LBA	PBA	PBA			
Read BBM[Note2]	A5h	DUMMY	LBA0	LBA0	PBA0	PBA0	LBA1	LBA1~
ECC Warning Page Address[Note3]	A9h	DUMMY	RADD2_L	RADD1_L	RADD0_L	RADD2_F	RADD1_F	RADD0_F

Notes:

1. *The device supports different feature configurations by configuration register bits. This command table is for standard operation (SPI_NOR_EN = 0, CONT = 0); for details of SPI_NOR_EN, CONT bits, please refer to the relative sections.*
2. *A5h command may read the 40 links of BBM_table (LBAx/PBAx)*
3. *RADDx_L: Last Warning Page Address, RADDx_F: First Warning Page Address*
4. **2 stands for the dual I/O phase and *4 for quad I/O mode.*

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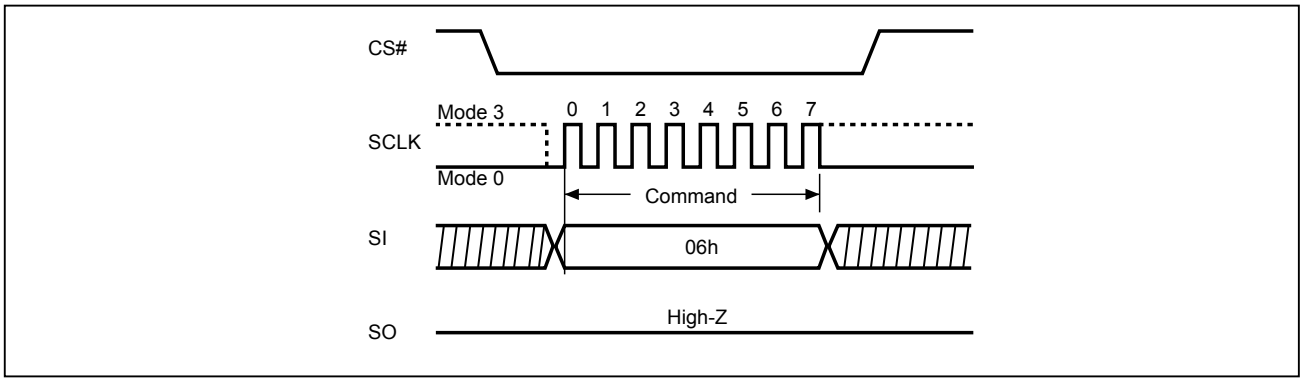
8-1. WRITE Operations

8-1-1. Write Enable

The Write Enable (WREN) instruction sets the Write Enable Latch (WEL) bit. Instructions like Page Program, Secure OTP program, Block erase, and Write BBM that are intended to change the device content, should be preceded by the WREN instruction.

The sequence of issuing WREN instruction is: CS# goes low→send WREN instruction code→ CS# goes high.

Figure 5. Write Enable (WREN) Sequence



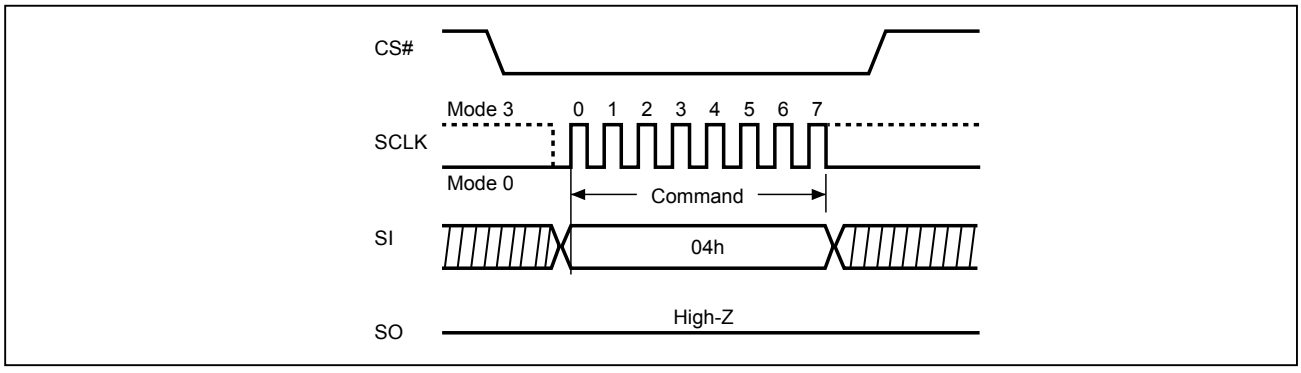
8-1-2. Write Disable (04h)

The Write Disable (WRDI) instruction resets the Write Enable Latch (WEL) bit.

The sequence of issuing WRDI instruction is: CS# goes low→send WRDI instruction code→CS# goes high. It disables the following operations:

- Block Erase
- Secure OTP program
- Page program
- Write BBM

Figure 6. Write Disable (WRDI) Sequence



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8-2. Feature Operations

8-2-1. GET Feature (0Fh) and SET Feature (1Fh)

By issuing a one byte address into the feature address, the device may then decide if it's a feature read or feature modification. (0Fh) is for the "GET FEATURE"; (1Fh) is for the "SET FEATURE".

The RESET command (FFh) will clear the status and special read for data recovery registers, the other feature registers remain until the power is being cycled or modified by the settings in the table below. After a RESET command (FFh) is issued, the Status register OIP bit0 or CRBSY will go high. These bits can be polled to determine when the Reset operation is complete, as it will return to the default value (0) after the reset operation is finished. Issuing the RESET command (FFh) has no effect on the Block Protection and Configuration registers.

The Block Protection and Configuration registers will return to their default state after a power cycle, and can also be changed using the Set Feature command. Issuing the Get Feature command to read the selected register value will not affect register content.

Table 2. Configuration Registers

ADD	Register		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Factory Default Value
10h	Configuration	bit name	BFT3	BFT2	BFT1	BFT0				ENPGM	F0h
		Type	V2	V2	V2	V2				V	
60h	Configuration	bit name							SPI_NOR_EN	OTPRWSP	00h
		Type							OTP	OTP	
70h	Special Read for Data Recovery	bit name						SPEC_RD2	SPEC_RD1	SPEC_RD0	00h
		Type						V	V	V	
A0h	Block Protection	bit name	BPRWD[Note1]		BP2	BP1	BP0	Invert	Comp.	SP[Note2]	38h
		Type	V		V	V	V	V	V	V	
B0h	Configuration	bit name	OTP_PROT	OTPEN		ECC_EN		CONT		QE	10h
		Type	V	V		V		V2		V	
C0h	Status	bit name	CRBSY	BBMT_F	ECC_S1	ECC_S0	P-FAIL	E_FAIL	WEL	OIP	00h
		Type	V	V	V	V	V	V	V	V	
E0h	Configuration	bit name	DS_IO[1]	DS_IO[0]							00h
		Type	V2	V2							

V2: Volatile, The default value of these volatile feature bits can be changed once by Special OTP Configuration Register Program Operation.

V: Volatile.

OTP: one time setting.

Note1: *If BPRWD is enabled and WP# is LOW, then the block protection register can not be changed.*

Note 2: SP bit is for Solid-protection. Once the SP bit sets as 1, the rest of protection bits (BPx bits, invert bits, complementary bits) cannot be changed during the current power cycle.

Note 3: This is the shipment power on default value, user can change the default value of registers of OTP/V2 type by Special OTP Configuration Register Program Operation.

Note 4: All the reserved bits must keep low including the undefined register.

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Table 3. Register status of Reset (FFh) command operation

Registers	Status	
	'CONT'=1	'CONT'=0
ECC_S[1:0]	***Kept***	Clear
P-FAIL	Clear	Clear
E-FAIL	Clear	Clear
WEL	Clear	Clear
OIP	Ready/busy status	Ready/busy status
CRBSY	Ready/busy status	Ready/busy status
SPEC_RD[2:0]	Clear	Clear
Other V type	***Kept***	***Kept***
Other V2 type	***Kept***	***Kept***
OTP types	***Kept***	***Kept***

Notes: *"Clear" means to return to power-on value, and "Kept" meaning Kept the status before the Reset.*

Table 4. I/O Strength Feature Table

DS_IO[1]	DS_IO[0]	Drive Strength
0	0	normal (defaul, 25 ohm typical)
0	1	underdrive 1 (35 ohm typical)
1	X	underdrive 2 (85 ohm typical)

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Figure 7. GET FEATURE (0Fh) Timing

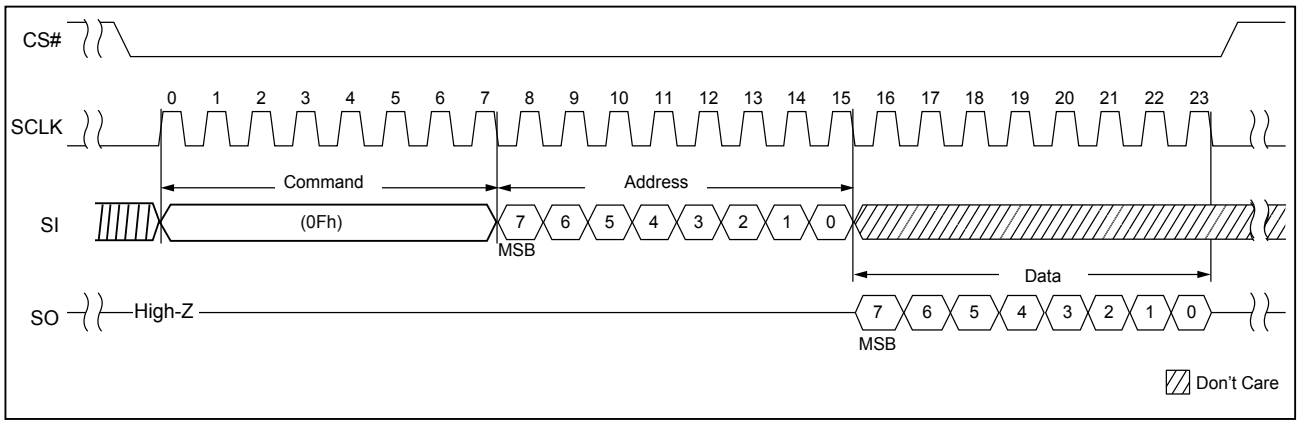
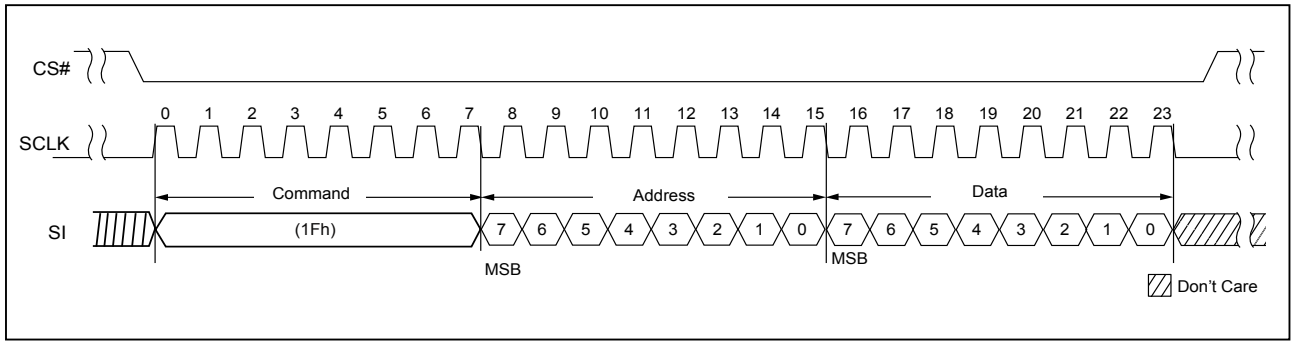


Figure 8. SET FEATURE (1Fh) Timing



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8-3. READ Operations

The device supports "Power-on Read" function, after power up, host may issue the Read From Cache command, and the device will automatically load the data of the 1st page of 1st block from array to cache. The host micro-controller may directly read the data from the cache buffer.

The device supports conventional read mode and continuous read modes.

If the configuration register bit “CONT” = 0, the device is in conventional read mode. The page read operation and page read cache Random/sequential operation is supported in the conventional read mode. If the configuration register bit “CONT” = 1, the device is in continuous read mode and only continuous read operation is supported. During the continuous read mode, the page read cache related commands are not supported (Page Cache Sequential (31h), Page Read Cache Random (30h) and Page Read Cache End (3Fh)).

Table 5. Supported Read Command Table for Different Modes

Read command	Command Code	Read Mode	
		Conventional Read Mode	Continuous Read Mode
Page Read	13h	V	V
Page Read Cache Random	30h	V	
Page Read Cache Sequential	31h	V	
Page Read Cache End	3Fh	V	

Table 6. Data Output Range Per Page

Configuration Register Bit "CONT"	Read Mode	Data Length per Page			
		ECC Enabled		ECC Disabled	
		1Gb/2Gb	4Gb	1Gb/2Gb	4Gb
CONT=0	Conventional Read mode	2048+64	4096+128	2048+128	4096+256
CONT=1	Continuous Read mode	2048	4096	-	-

8-3-1. PAGE READ (13h)

The page read operation transfers data from array to cache by issuing the page read (13h)command followed by the 24-bit address (including the dummy/block/page address).

The device will have a period of time (tRD) being busy after the CS# goes high. The 0Fh (GET FEATURE) or 05h (RDSR) may be used to poll the operation status.

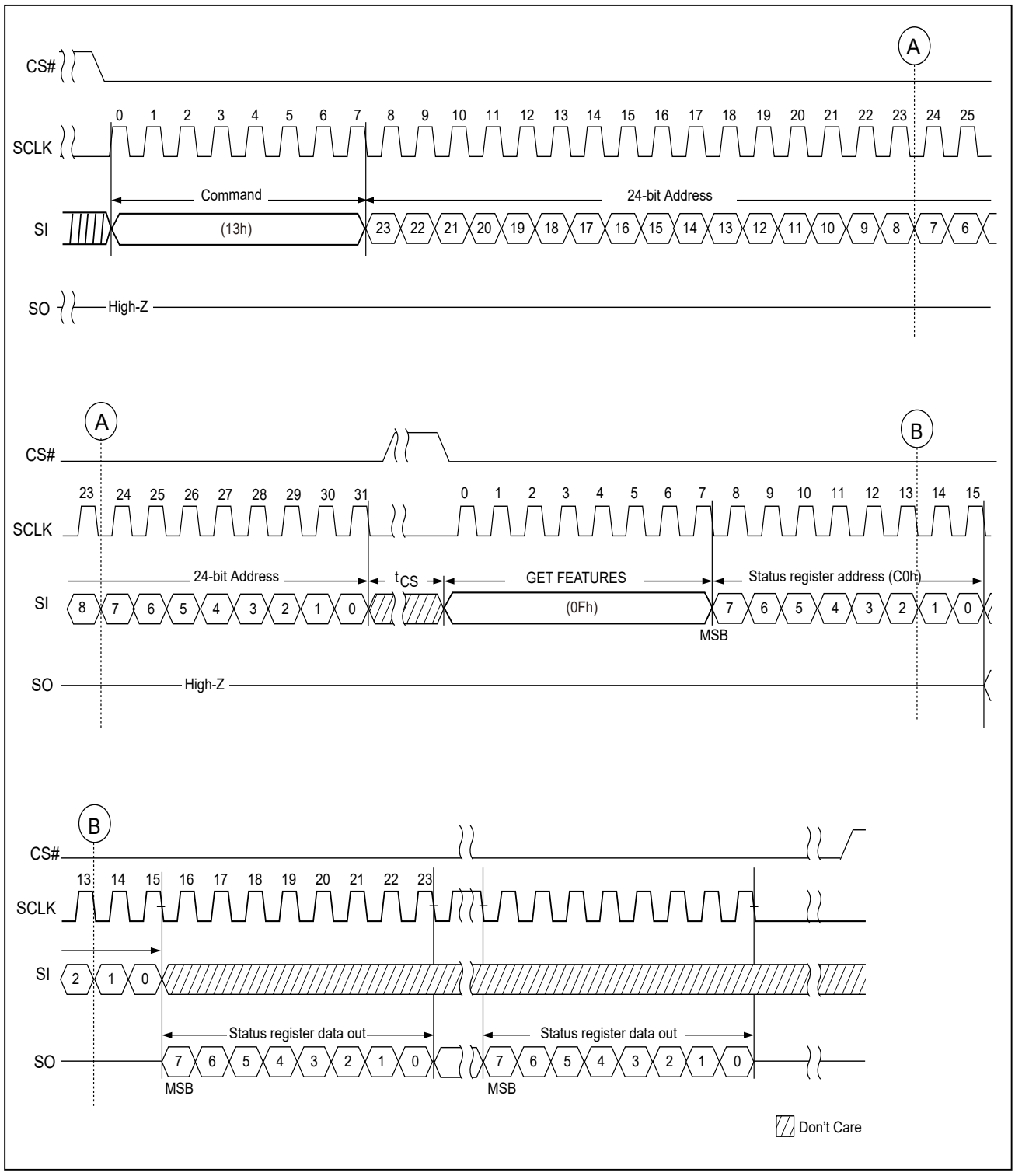
After read operation is completed, the Read from Cache (03H or 0Bh), Read from cache (x2) (3Bh), Read from cache (x4) (6Bh), read from cache dual IO (1-2-2) (BBh) and Read from cache Qual IO (1-4-4) (EBh) may be issued to fetch the data.

8-3-2. QE bit

The Quad Enable (QE) bit, volatile bit, while it is "0" (factory default), it performs non-Quad and WP#, HOLD# are enabled. While QE is "1", it performs Quad I/O mode and WP#, HOLD# are disabled. In another word, if the system goes into four I/O mode (QE=1), the feature of Hardware Protection Mode(HPM) and HOLD# will be disabled. Upon power cycle, the QE bit will go into the factory default setting "0".

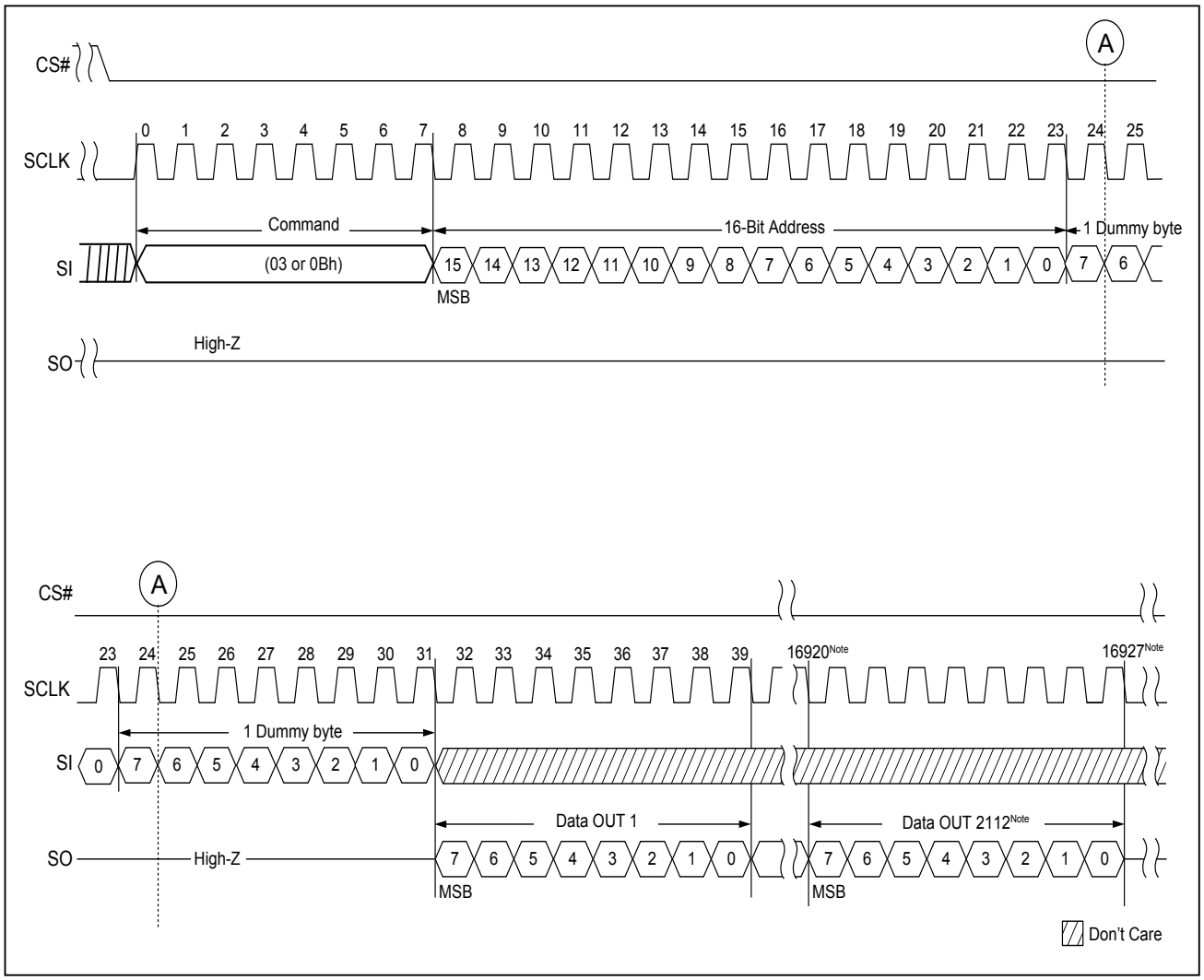
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Figure 9. PAGE READ (13h) Timing x1



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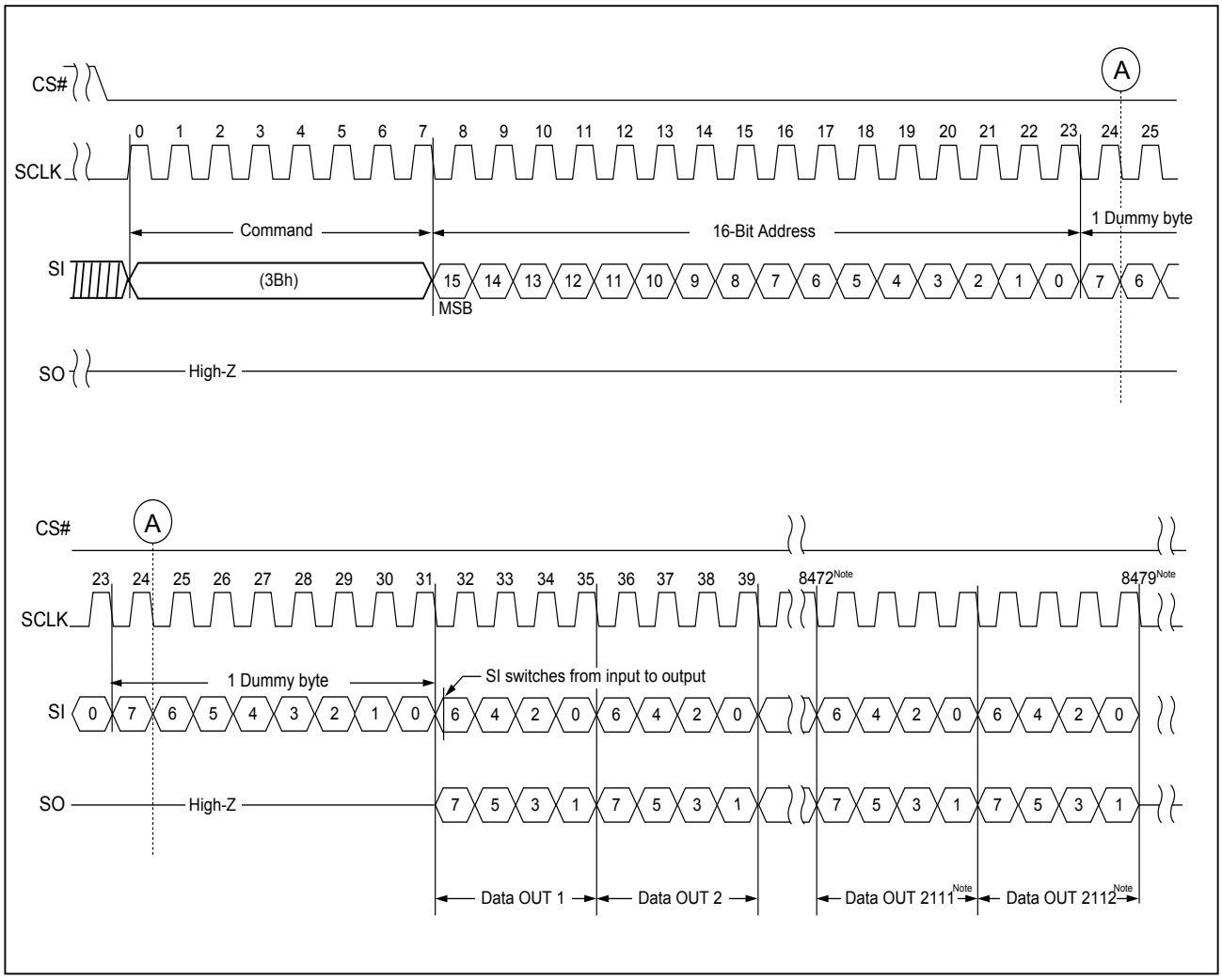
Figure 10. READ From CACHE (03h or 0Bh) Timing



Note: *2KB+64B as example.*

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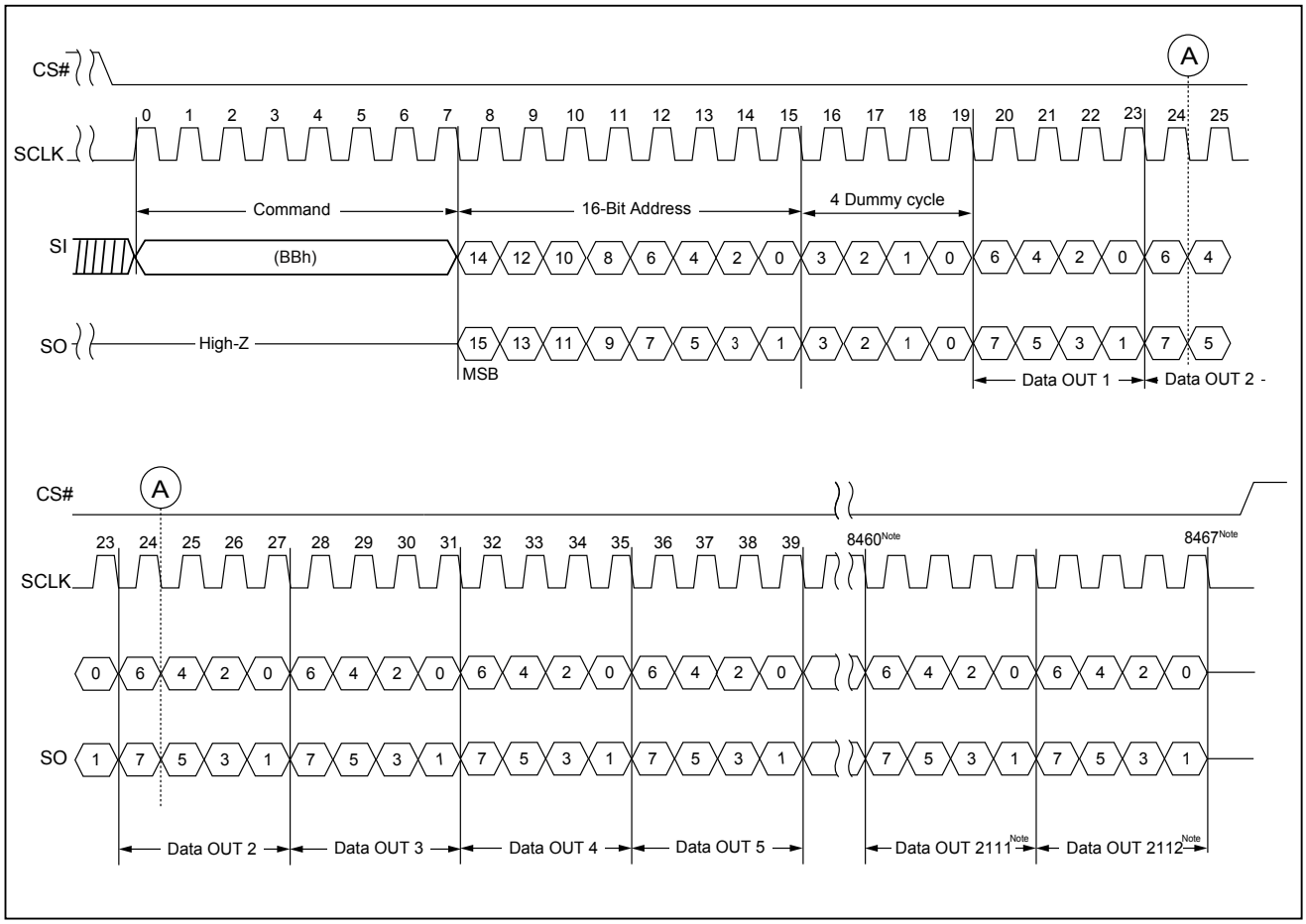
Figure 11. READ FROM CACHE x 2



Note: *2KB+64B as example.*

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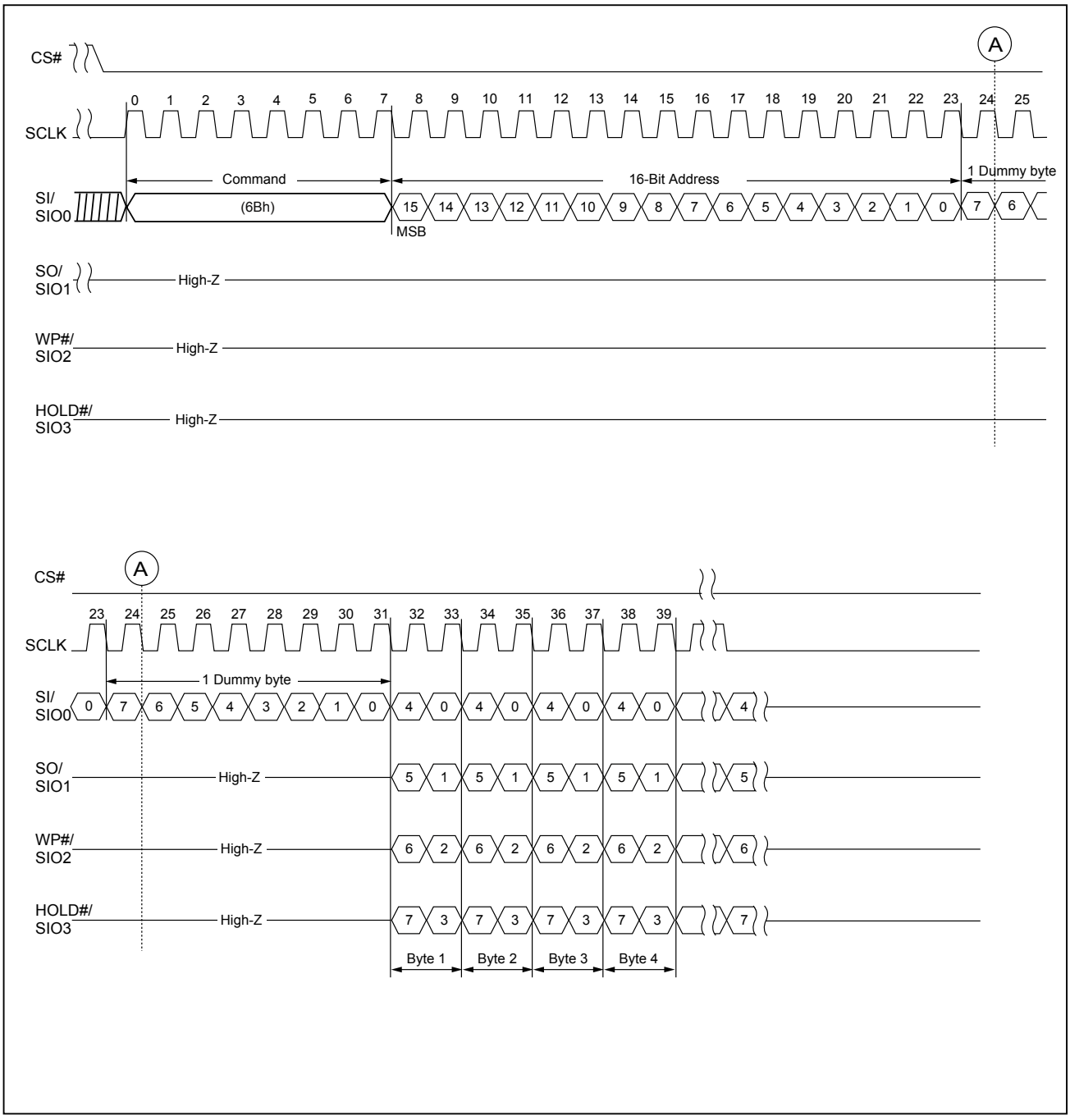
Figure 12. Read From Cache Dual IO 1-2-2



Note: *2KB+64B as example.*

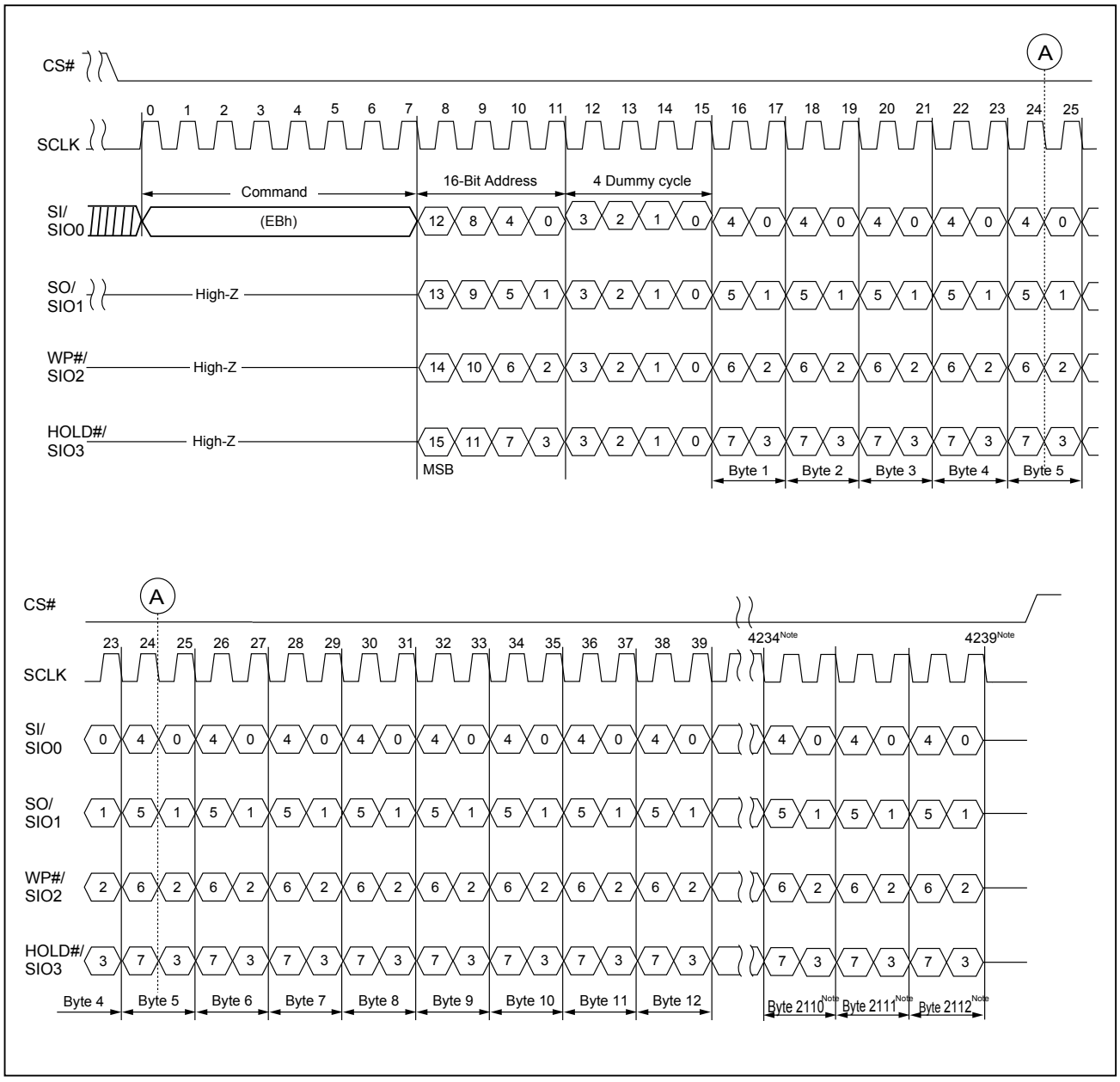
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Figure 13. READ FROM CACHE x 4



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Figure 14. Read From Cache Quad IO 1-4-4



Note: *2KB+64B as example.*

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8-3-3. Page Read Cache Random (30h)/Page Read Cache Sequential (31h)/Page Read Cache End (3Fh)

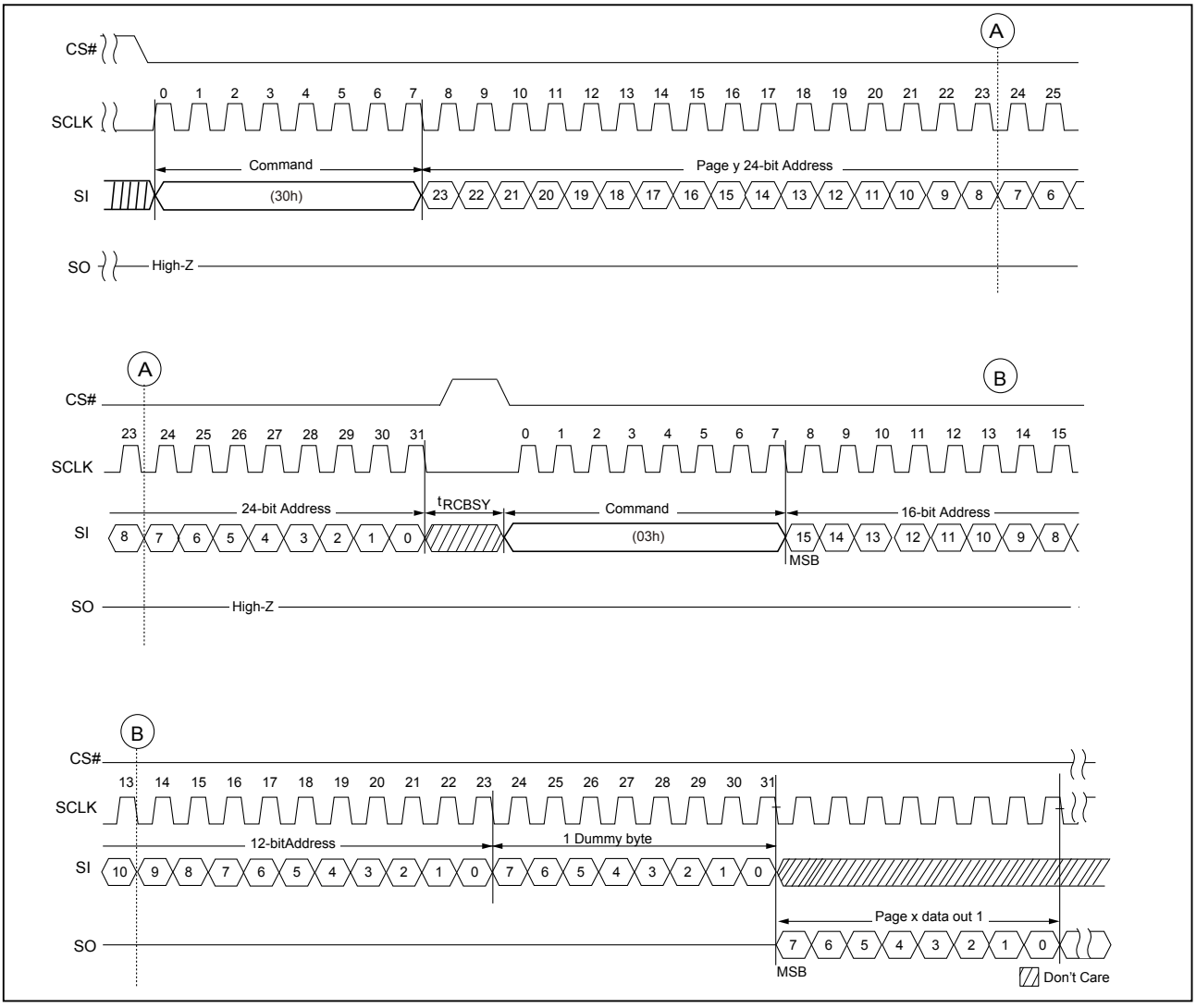
The page read cache sequential operation is for throughput enhancement by using the internal cache buffer. It allows the consecutive pages to be read-out without giving next page address, which reduces the latency time from tRD to tRCBSY between pages or blocks. While the data is read out on one page, the data of next page can be read into the cache buffer.

After writing the 13h command and giving the 24-bit address, the device will have a period of time (tRD) being busy after the CS# goes high. The 0Fh (GET FEATURE) or 05h (RDSR) may be used to poll the operation status. After the status of successfully completed, following the page read cache sequential (31h) or the page read cache random (30h) command being sent to Serial Flash device; the Serial Flash device will be at a busy time of tRCBSY for the next page data transferring to cache. And then following the cache read command (03h/0Bh/3Bh/6Bh/BBh/EBh) may get the prior page data output from cache at the same time.

To confirm the last page to be read-out during the cache read sequential operation, a 3Fh command is needed to replace the 31h or 30h command prior to the last data-out.

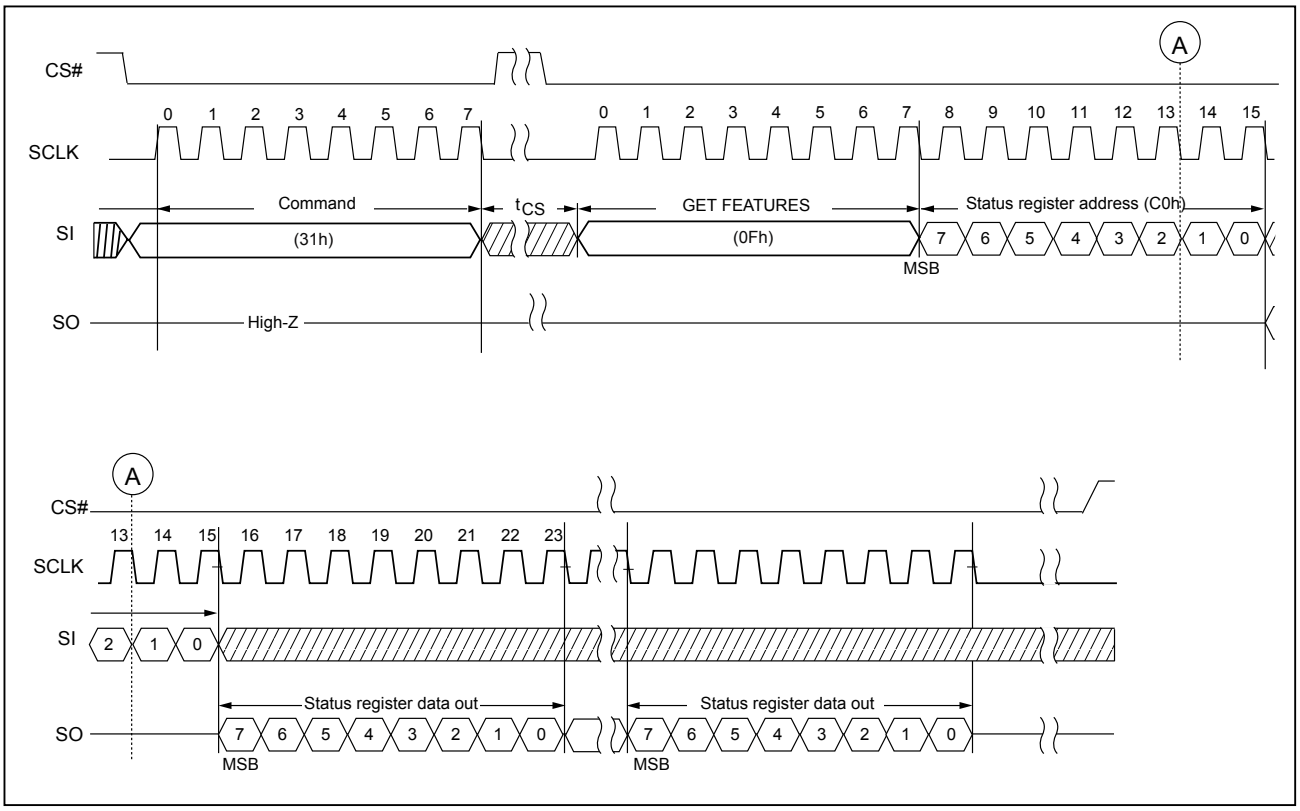
The PAGE READ CACHE SEQUENTIAL command is also valid for the consecutive page cross block.

Figure 15. Page Read Cache Random (30h)



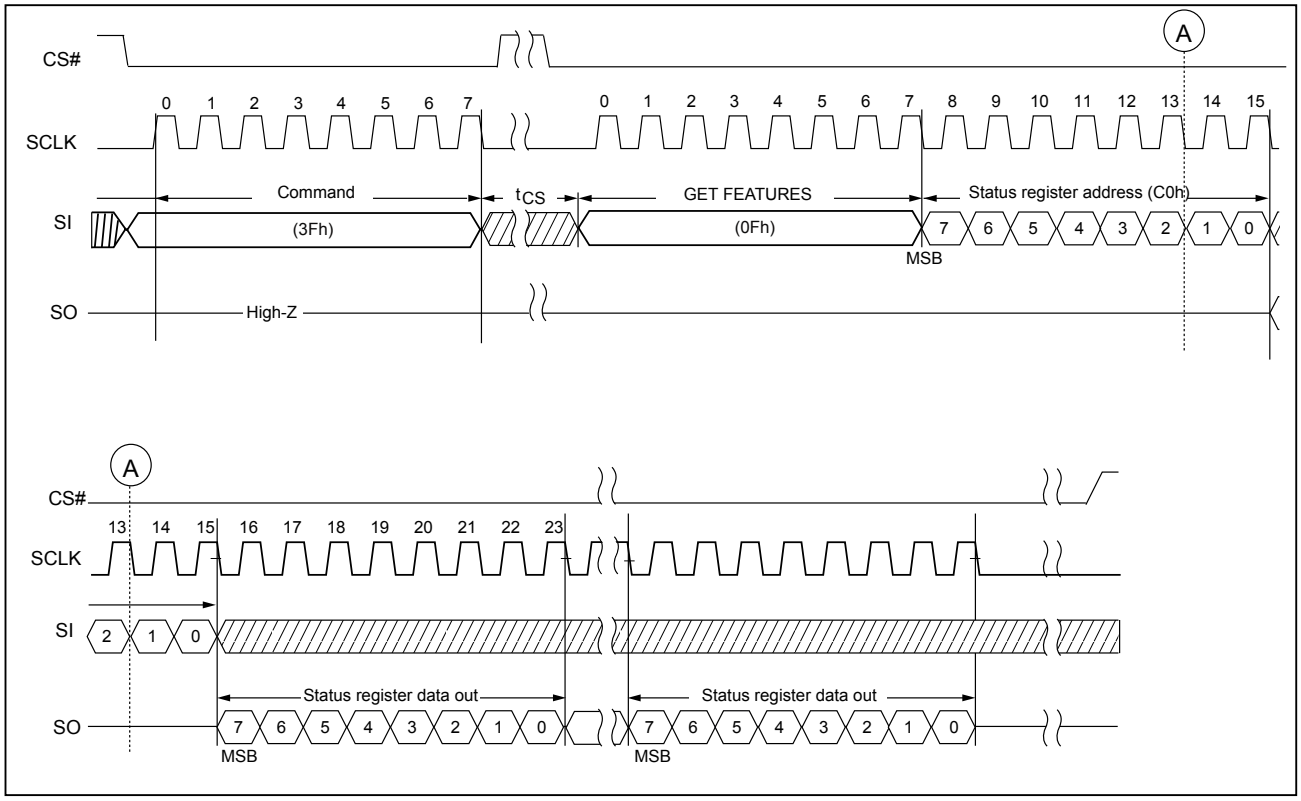
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Figure 16. Page Read Cache Sequential (31h)



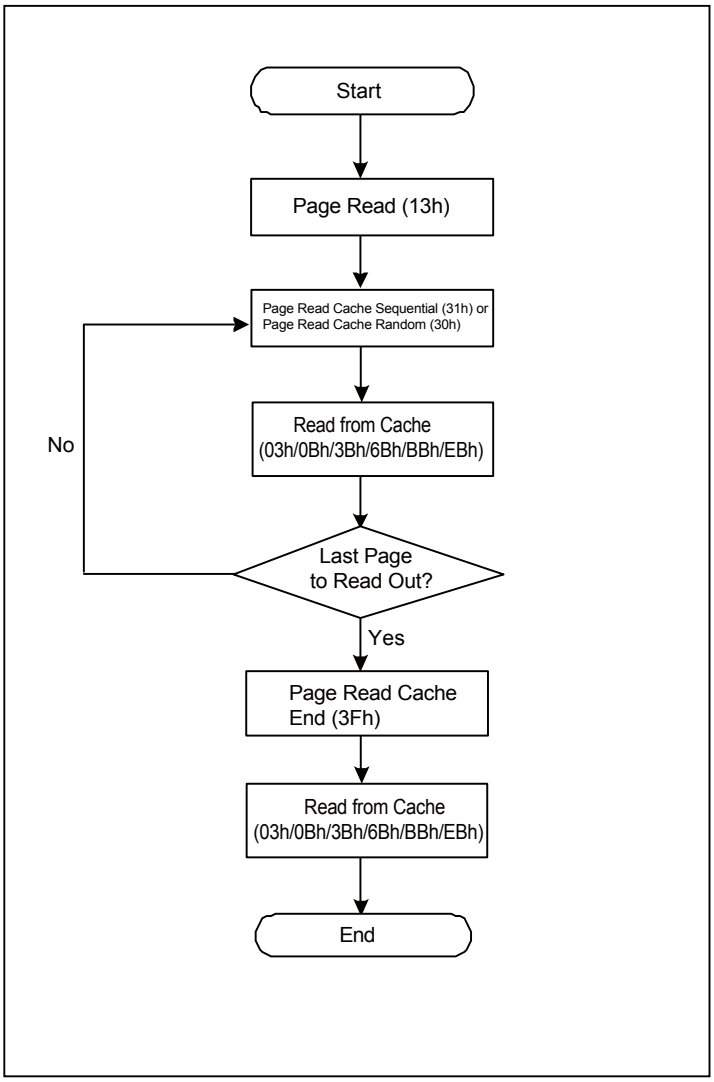
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Figure 17. Page Read Cache End (3Fh)



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Figure 18. Page Read Cache Flow



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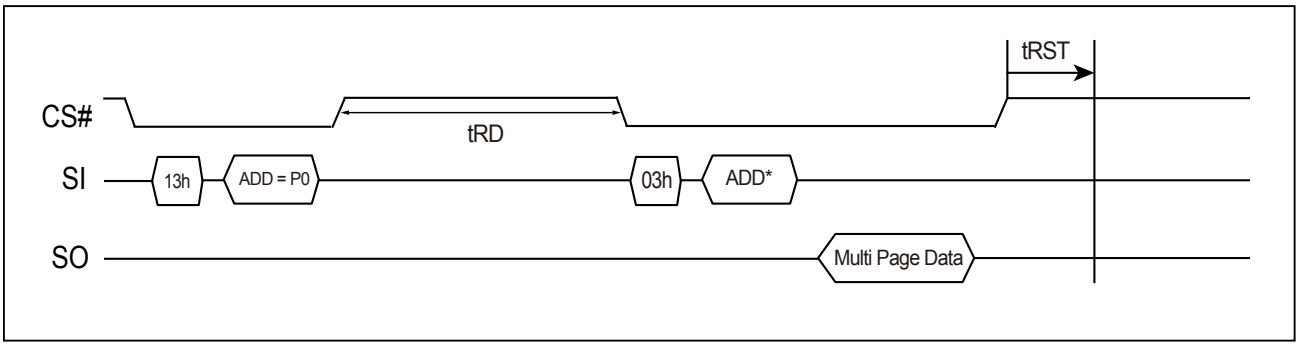
8-3-4. Continuous Read Operation

This device also supports the continuous read operation which allows the host to read out the data continuously from page to page with just first read latency.

The continuous read operation including: firstly, starting with the page read command and the 1st page data will be read into the cache after the read latency tRD. Secondly, Issuing the Read From Cache commands (03h/0Bh/3Bh/6Bh/BBh/EBh) to read out the data from cache continuously. After all the data is read out, the host should pullCS# high to terminate this continuous read operation and wait a 6us of tRST for the NAND device resets read operation.

The data output for each page will always start from byte 0 and a full page data (2KB) should be read out for each page.

Figure 19. Continuous Read Waveform



**: Address is Don't care.*

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Table 7. Command Set - Continuous Read Operation Enabled

SPI_NOR_EN = 0, **CONT = 1**

Mode	1st Byte	2nd Byte	3rd Byte	4th Byte	5th Byte	6th Byte	7th Byte	8th Byte
Get Feature	0Fh	ADD	Data					
Read Status	05h	Data						
Set Feature	1Fh	ADD	Data					
Page Read	13h	RADD2	RADD1	RADD0				
Read From Cache x1	03h	DUMMY	DUMMY	DUMMY	DATA~			
Read From Cache x1 (Alternative)	0Bh	DUMMY	DUMMY	DUMMY	DATA~			
Read From Cache x2	3Bh	DUMMY	DUMMY	DUMMY	DATA~*2			
Read From Cache x4	6Bh	DUMMY	DUMMY	DUMMY	DATA~*4			
Read From Cache Dual IO 1-2-2	BBh	DUMMY*2	DUMMY*2	DUMMY*2	DATA~*2			
Read From Cache Quad IO 1-4-4	EBh	DUMMY*4	DUMMY*4	DUMMY*4	DUMMY*4	DATA~*4		
Read ID	9Fh	DUMMY	MID	DID1	DID2			
Block Erase	D8h	RADD2	RADD1	RADD0				
Program Execute	10h	RADD2	RADD1	RADD0				
Program Load x1	02h	CADD1	CADD0	DATA~				
Program Load random Data x1	84h	CADD1	CADD0	DATA~				
Program Load x4	32h	CADD1	CADD0	DATA~*4				
Program Load Random Data x4	34h	CADD1	CADD0	DATA~*4				
Write Enable	06h							
Write Disable	04h							
Reset	FFh							
Read ECCSR	7Ch	DUMMY	SR_ECC					
Write BBM	A1h	LBA	LBA	PBA	PBA			
Read BBM*1	A5h	DUMMY	LBA0	LBA0	PBA0	PBA0	LBA1	LBA1~
ECC Warning Page Address	A9h	DUMMY	RADD2_L	RADD1_L	RADD0_L	RADD2_F	RADD1_F	RADD0_F

Note: *Address is Don't Care for reach from cache command (03h/0Bh/3Bh/6Bh/BBh/EBh) in Continuous read operation.*

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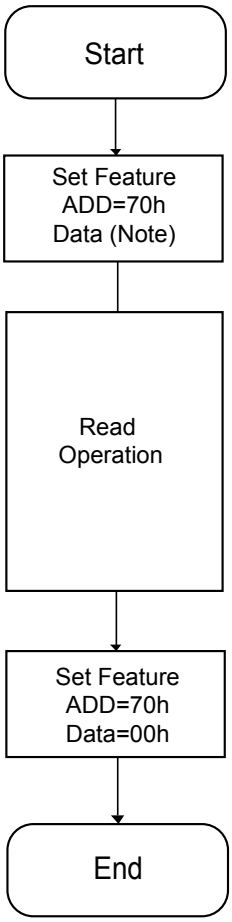
8-3-5. Special Read for Data Recovery

When the ECC fails to correct the data error of Serial Flash device, there's a special read for data recovery method which host executes the Special Read for Data Recovery operation and may recover the lost data again. After that, it is needed to move the data to another good block.

The Special Read for Data Recovery operation is enabled by Set Feature function (**"Table 8. Feature Settings"**).

There are 5 modes for the user to recover the lost data. The procedure of entering and exiting the operation is shown as Figure below.

Figure 20. Procedure of Entering/Exiting the Special Read for Data Recovery operation



Note: *Please refer to the* **"Table 8. Feature Settings"**

Table 8. Feature Settings

Definition		SPEC_RD2	SPEC_RD1	SPEC_RD0	Value
Special Read for Data Recovey	Disable (Default)	0	0	0	00h
	Mode 1	0	0	1	01h
	Mode 2	0	1	0	02h
	Mode 3	0	1	1	03h
	Mode 4	1	0	0	04h
	Mode 5	1	0	1	05h

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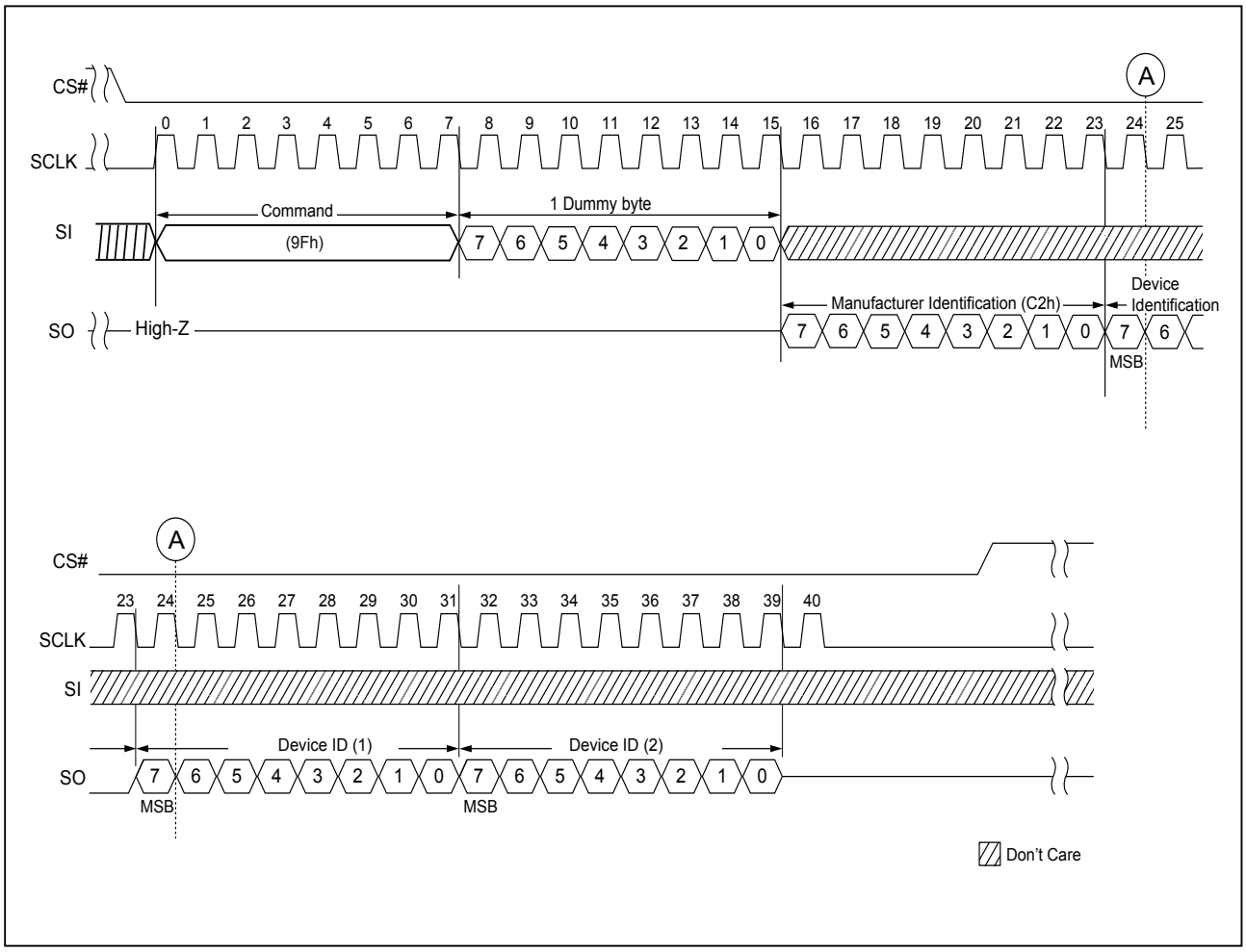
8-4. READ ID (9Fh)

The READ ID command is shown as the table below.

Table 9. READ ID Table

Byte	Description		I/O7	I/O6	I/O5	I/O4	I/O3	I/O2	I/O1	I/O0	Value
Byte 0	Manufacturer ID (Macronix)		1	1	0	0	0	0	1	0	C2h
Byte 1	Device ID 1	1Gb	1	0	0	1	0	1	1	0	96h
		2Gb	1	0	1	0	0	1	1	0	A6h
		4Gb	1	0	1	1	0	1	1	1	B7h
Byte 2	Device ID 2		0	0	0	0	0	0	1	1	03h

Figure 21. READ ID (9Fh) Timing



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8-5. Parameter Page

The parameter page is accessed by the following command flows:

Issue 1Fh (SET FEATURE) command with Secure OTP enable (B0h for address & 40h for data) → Issue 13h (PAGE READ) with 01h address, issue 0Fh (GET FEATURE) with C0h feature address or 05h (RDSR) to poll the status of read completion. → Issue 03h (READ FROM CACHE) with address A[11:0]=000h and read data → Issue 1Fh (SET FEATURE) with feature address B0h to disable Secure OTP feature (data byte = 00h) [exit parameter page read].

Table 10. Parameter Page - MX35UF1GE4AD

	Revision Information and Features Block		
Byte#	**Description**		**Data**
0-3	Parameter Page Signature		4Fh, 4Eh, 46h, 49h
4-5	Revision Number		00h, 00h
6-7	Features Supported (N/A)		00h, 00h
8-9	Optional Commands Supported		06h, 00h
10-31	Reserved		00h
	Manufacturer Information Block		
Byte#	**Description**		**Data**
32-43	Device Manufacturer (12 ASCII characters)		4Dh, 41h, 43h, 52h, 4Fh, 4Eh, 49h, 58h, 20h, 20h, 20h, 20h
44-63	Device Model (20 ASCII Characters)	MX35UF1GE4AD	4Dh, 58h, 33h, 35h, 55h, 46h, 31h, 47h, 45h, 34h, 41h, 44h, 20h, 20h, 20h, 20h, 20h, 20h, 20h, 20h, 20h, 20h
64	Manufacturer ID		C2h
65-66	Date Code		00h, 00h
67-79	Reserved		00h

Memory Organization Block			
Byte#	**Description**		**Data**
80-83	Number of Data Bytes per Page	2048-byte	00h, 08h, 00h, 00h
84-85	Number of Spare Bytes per Page	128-byte	80h, 00h
86-89	Number of Data Bytes per Partial Page	512-byte	00h, 02h, 00h, 00h
90-91	Number of Spare Bytes per Partial Page	32-byte	20h, 00h
92-95	Number of Pages per Block		40h, 00h, 00h, 00h
96-99	Number of Blocks per Unit		00h, 04h, 00h, 00h
100	Number of Logical Units		01h
101	Number of Address Cycles (N/A)		00h
102	Number of Bits per Cell		01h
103-104	Bad Blocks Maximum per unit		14h, 00h
105-106	Block endurance		06h, 04h
107	Guarantee Valid Blocks at Beginning of Target		08h
108-109	Block endurance for guaranteed valid blocks		00h, 00h
110	Number of Programs per Page		04h
111	Partial Programming Attributes		00h
112	Number of ECC bits		00h
113	Number of Interleaved Address Bits (N/A)		00h
114	Interleaved Operation Attributes (N/A)		00h
115-127	Reserved		00h

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Electrical Parameters Block			
Byte#	**Description**		**Data**
128	I/O Pin Capacitance		0Ah
129-130	Timing Mode Support (N/A)		00h, 00h
131-132	Program Cache Timing (N/A)		00h, 00h
133-134	tPROG Maximum Page Program Time (uS)	760us	F8h, 02h
135-136	BE Maximum Block Erase time (uS)	6000us	70h, 17h
137-138	tRD_ECC Maximum Page Read time (uS)	80us	50h, 00h
139-140	tCCS Minimum (N/A)	0ns	00h, 00h
141-163	Reserved		00h
Vendor Blocks			
Byte#	**Description**		**Data**
164-165	Vendor Specific Revision Number		00h, 00h
166	Reserved		00h
167	Reliability enhancement function 2-7 Reserved(0) 1 1= Randomizer support, 0= Not support 0 1= Special read for data recovery support, 0= Not support		01h
168	NOR like features support 4-7: Reserved(0) 3 :1= XIP_RAM support, 0= Not support 2 :1= Automatic BBM support, 0= Not support 1 :1= Continuous Read support, 0= Not support 0 :1= BBM_table support, 0= Not support		03h
169	Number of special read for data recovery (N)		05h
170-253	Vendor Specific		00h
254-255	Integrity CRC		Set at Test ***(Note)***
Redundant Parameter Pages			
Byte#	**Description**		**Data**
256-511	Value of Bytes 0-255		Same as 0~255 Byte
512-767	Value of Bytes 0-255		Same as 0~255 Byte
768+	Additional Redundant Parameter Pages		

Note:
The Integrity CRC (Cycling Redundancy Check) field is used to verify that the contents of the parameters page were transferred correctly to the host.

The CRC shall be calculated using the following 16-bit generator polynomial:
$G(X) = X_{16} + X_{15} + X_2 + 1$

The host needs to find the parameter page of next copy if the CRC is not correct at current copy of parameter page. This procedure should be continue until the host get the correct CRC of the parameter page. The host may use bit-wise majority way to recover the content of parameter page from the copy of parameter page.

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Table 11. Parameter Page - MX35UF2GE4AD

	Revision Information and Features Block		
Byte#	**Description**		**Data**
0-3	Parameter Page Signature		4Fh, 4Eh, 46h, 49h
4-5	Revision Number		00h, 00h
6-7	Features Supported (N/A)		00h, 00h
8-9	Optional Commands Supported		06h, 00h
10-31	Reserved		00h
	Manufacturer Information Block		
Byte#	**Description**		**Data**
32-43	Device Manufacturer (12 ASCII characters)		4Dh, 41h, 43h, 52h, 4Fh, 4Eh, 49h, 58h, 20h, 20h, 20h, 20h
44-63	Device Model (20 ASCII Characters)	MX35UF2GE4AD	4Dh, 58h, 33h, 35h, 55h, 46h, 32h, 47h, 45h, 34h, 41h, 44h, 20h, 20h, 20h, 20h, 20h, 20h, 20h, 20h
64	Manufacturer ID		C2h
65-66	Date Code		00h, 00h
67-79	Reserved		00h

Memory Organization Block			
Byte#	**Description**		**Data**
80-83	Number of Data Bytes per Page	2048-byte	00h, 08h, 00h, 00h
84-85	Number of Spare Bytes per Page	128-byte	80h, 00h
86-89	Number of Data Bytes per Partial Page	512-byte	00h, 02h, 00h, 00h
90-91	Number of Spare Bytes per Partial Page	32-byte	20h, 00h
92-95	Number of Pages per Block		40h, 00h, 00h, 00h
96-99	Number of Blocks per Unit		00h, 08h, 00h, 00h
100	Number of Logical Units		01h
101	Number of Address Cycles (N/A)		00h
102	Number of Bits per Cell		01h
103-104	Bad Blocks Maximum per unit		28h, 00h
105-106	Block endurance		06h, 04h
107	Guarantee Valid Blocks at Beginning of Target		08h
108-109	Block endurance for guaranteed valid blocks		00h, 00h
110	Number of Programs per Page		04h
111	Partial Programming Attributes		00h
112	Number of ECC bits		00h
113	Number of Interleaved Address Bits (N/A)		00h
114	Interleaved Operation Attributes (N/A)		00h
115-127	Reserved		00h

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Electrical Parameters Block			
Byte#	**Description**		**Data**
128	I/O Pin Capacitance		0Ah
129-130	Timing Mode Support (N/A)		00h, 00h
131-132	Program Cache Timing (N/A)		00h, 00h
133-134	tPROG Maximum Page Program Time (uS)	760us	F8h, 02h
135-136	BE Maximum Block Erase time (uS)	6000us	70h, 17h
137-138	tRD_ECC Maximum Page Read time (uS)	80us	50h, 00h
139-140	tCCS Minimum (N/A)	0ns	00h, 00h
141-163	Reserved		00h
Vendor Blocks			
Byte#	**Description**		**Data**
164-165	Vendor Specific Revision Number		00h, 00h
166	Reserved		00h
167	Reliability enhancement function 2-7 Reserved(0) 1 1= Randomizer support, 0= Not support 0 1= Special read for data recovery support, 0= Not support		01h
168	NOR like features support 4-7: Reserved(0) 3 :1= XIP_RAM support, 0= Not support 2 :1= Automatic BBM support, 0= Not support 1 :1= Continuous Read support, 0= Not support 0 :1= BBM_table support, 0= Not support		03h
169	Number of special read for data recovery (N)		05h
170-253	Vendor Specific		00h
254-255	Integrity CRC		Set at Test ***(Note)***
Redundant Parameter Pages			
Byte#	**Description**		**Data**
256-511	Value of Bytes 0-255		Same as 0~255 Byte
512-767	Value of Bytes 0-255		Same as 0~255 Byte
768+	Additional Redundant Parameter Pages		

Note:
The Integrity CRC (Cycling Redundancy Check) field is used to verify that the contents of the parameters page were transferred correctly to the host.

The CRC shall be calculated using the following 16-bit generator polynomial:
$G(X) = X_{16} + X_{15} + X_2 + 1$

The host needs to find the parameter page of next copy if the CRC is not correct at current copy of parameter page. This procedure should be continue until the host get the correct CRC of the parameter page. The host may use bit-wise majority way to recover the content of parameter page from the copy of parameter page.

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Table 12. Parameter Page - MX35UF4GE4AD

	Revision Information and Features Block		
Byte#	**Description**		**Data**
0-3	Parameter Page Signature		4Fh, 4Eh, 46h, 49h
4-5	Revision Number		00h, 00h
6-7	Features Supported (N/A)		00h, 00h
8-9	Optional Commands Supported		06h, 00h
10-31	Reserved		00h
	Manufacturer Information Block		
Byte#	**Description**		**Data**
32-43	Device Manufacturer (12 ASCII characters)		4Dh, 41h, 43h, 52h, 4Fh, 4Eh, 49h, 58h, 20h, 20h, 20h, 20h
44-63	Device Model (20 ASCII Characters)	MX35UF4GE4AD	4Dh, 58h, 33h, 35h, 55h, 46h, 34h, 47h, 45h, 34h, 41h, 44h, 20h, 20h, 20h, 20h, 20h, 20h, 20h, 20h
64	Manufacturer ID		C2h
65-66	Date Code		00h, 00h
67-79	Reserved		00h

Memory Organization Block			
Byte#	**Description**		**Data**
80-83	Number of Data Bytes per Page	4096-byte	00h, 10h, 00h, 00h
84-85	Number of Spare Bytes per Page	256-byte	00h, 01h
86-89	Number of Data Bytes per Partial Page	1024-byte	00h, 04h, 00h, 00h
90-91	Number of Spare Bytes per Partial Page	64-byte	40h, 00h
92-95	Number of Pages per Block		40h, 00h, 00h, 00h
96-99	Number of Blocks per Unit		00h, 08h, 00h, 00h
100	Number of Logical Units		01h
101	Number of Address Cycles (N/A)		00h
102	Number of Bits per Cell		01h
103-104	Bad Blocks Maximum per unit		28h, 00h
105-106	Block endurance		06h, 04h
107	Guarantee Valid Blocks at Beginning of Target		08h
108-109	Block endurance for guaranteed valid blocks		00h, 00h
110	Number of Programs per Page		04h
111	Partial Programming Attributes		00h
112	Number of ECC bits		00h
113	Number of Interleaved Address Bits (N/A)		00h
114	Interleaved Operation Attributes (N/A)		00h
115-127	Reserved		00h

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Electrical Parameters Block			
Byte#	**Description**		**Data**
128	I/O Pin Capacitance		0Ah
129-130	Timing Mode Support (N/A)		00h, 00h
131-132	Program Cache Timing (N/A)		00h, 00h
133-134	tPROG Maximum Page Program Time (uS)	800us	20h, 03h
135-136	BE Maximum Block Erase time (uS)	6000us	70h, 17h
137-138	tRD_ECC Maximum Page Read time (uS)	120us	78h, 00h
139-140	tCCS Minimum (N/A)	0ns	00h, 00h
141-163	Reserved		00h
Vendor Blocks			
Byte#	**Description**		**Data**
164-165	Vendor Specific Revision Number		00h, 00h
166	Reserved		00h
167	Reliability enhancement function 2-7: Reserved(0) 1 : 1= Randomizer support, 0= Not support 0 : 1= Special read for data recovery support, 0= Not support		01h
168	NOR like features support 4-7: Reserved(0) 3 : 1= XIP_RAM support, 0= Not support 2 : 1= Automatic BBM support, 0= Not support 1 : 1= Continuous Read support, 0= Not support 0 : 1= BBM_table support, 0= Not support		03h
169	Number of special read for data recovery (N)		05h
170-253	Vendor Specific		00h
254-255	Integrity CRC		Set at Test ***(Note)***
Redundant Parameter Pages			
Byte#	**Description**		**Data**
256-511	Value of Bytes 0-255		Same as 0~255 Byte
512-767	Value of Bytes 0-255		Same as 0~255 Byte
768+	Additional Redundant Parameter Pages		

Note:
The Integrity CRC (Cycling Redundancy Check) field is used to verify that the contents of the parameters page were transferred correctly to the host.

The CRC shall be calculated using the following 16-bit generator polynomial:
$G(X) = X_{16} + X_{15} + X_2 + 1$

The host needs to find the parameter page of next copy if the CRC is not correct at current copy of parameter page. This procedure should be continue until the host get the correct CRC of the parameter page. The host may use bit-wise majority way to recover the content of parameter page from the copy of parameter page.

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8-6. UniqueID Page with PUF Type Code Structure

The UniqueID page is accessed by the following command flows:

Issue 1Fh (SET FEATURE) command with Secure OTP enable (B0h for address & 40h for data) → Issue 13h (PAGE READ) with 00h address, issue 0Fh (GET FEATURE) with C0h feature address or 05h (RDSR) to poll the status of read completion → Issue 03h (READ FROM CACHE) with address A[11:0]=000h and read data → Issue 1Fh (SET FEATURE) with feature address B0h to disable Secure OTP function (data byte = 00h) [exit unique ID read].

The MX35UFxGE4AD unique ID adopts Macronix PUF-like code structure, which is truly random and the numbers of "0" bit almost equal to numbers of "1" bit. The unique ID is 32-byte and with 16 copies for back-up purpose. The host need to XOR the 1st 16-byte unique data and the 2nd 16-byte complement data to get the result, if the result is FFh, the unique ID data is correct; otherwise, host need to repeat the XOR with the next copy of Unique ID data.

8-7. Internal ECC Status

8-7-1. Internal ECC Enabled/Disabled

The internal ECC logic may detect 9-bit error and correct 8-bit error. The default state of the internal ECC is enabled. To enable/disable the internal ECC, it is operated by the Set Feature operation to enable internal ECC or disable the internal ECC, and then check the internal ECC state by Get Feature operation.

The internal ECC is enabled by using Set Feature command (1Fh) and followed by feature address (B0h) and then set Bit4 (ECC enabled) as "1". To disable the internal ECC can be done by using the Set Feature command (1Fh) and followed by the feature address (B0h) and then set Bit4 (ECC enabled) as "0".

When the internal ECC is enabled, after the data transfer time (tRD) is completed, a Status Read operation is required to check any uncorrectable read error happened. Please refer to **"Table 21. Status Register Bit Descriptions"**.

The constraint of the internal ECC enabled operation:

- The ECC protection coverage: please refer to **"Table 13. The Distribution of ECC Segment and Spare Area - 1Gb/2Gb"**, **"Table 14. The Distribution of ECC Segment and Spare Area - 4Gb"** and **"Table 15. The Distribution of ECC Segment and Spare Area - 4Gb (Cont'd)"** below. Only the grey areas are under internal ECC protection when the internal ECC is enabled.
- The number of partial-page program is not 4 in an ECC segment, user needs to program main area and relative spare area (M1: 12B) at one program operation. For partial page program, although there are eight ECC segments (for 4Gb) and four ECC segments (for 1Gb/2Gb), user still needs to follow the NOP=4 page program condition.

Table 13. The Distribution of ECC Segment and Spare Area - 1Gb/2Gb

Area	Main Area (0)	Main Area (1)	Main Area (2)	Main Area (3)	Spare(0)			Spare(1)			Spare(2)			Spare(3)			Spare2 (0)	Spare2 (1)	Spare2 (2)	Spare2 (3)
					R1	M2	M1	R1	M2	M1	R1	M2	M1	R1	M2	M1				
Addr. (Start)	000h	200h	400h	600h	800h	802h	804h	810h	812h	814h	820h	822h	824h	830h	832h	834h	840h	850h	860h	870h
Addr. (End)	1FFh	3FFh	5FFh	7FFh	801h	803h	80Fh	811h	813h	81Fh	821h	823h	82Fh	831h	833h	83Fh	84Fh	85Fh	86Fh	87Fh
Size	512(B)	512(B)	512(B)	512(B)	2(B)	2(B)	12(B)	2(B)	2(B)	12(B)	2(B)	2(B)	12(B)	2(B)	2(B)	12(B)	16(B)	16(B)	16(B)	16(B)
Data Type	User	User	User	User	R	User	User	R	User	User	R	User	User	R	User	User	ECC	ECC	ECC	ECC

Notes: *R1: Reserved*

M2: Metadata 2
M1: Metadata 1
Grey area: Under ECC protection

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Table 14. The Distribution of ECC Segment and Spare Area - 4Gb

Area	Main Area (0)	Main Area (1)	Main Area (2)	Main Area (3)	Main Area (4)	Main Area (5)	Main Area (6)	Main Area (7)	Spare(0)			Spare(1)			Spare(2)			Spare(3)		
									R1	M2	M1	R1	M2	M1	R1	M2	M1	R1	M2	M1
Addr. (Start)	000h	200h	400h	600h	800h	A00h	C00h	E00h	1000h	1002h	1004h	1010h	1012h	1014h	1020h	1022h	1024h	1030h	1032h	1034h
Addr. (End)	1FFh	3FFh	5FFh	7FFh	9FFh	BFFh	DFFh	FFFh	1001h	1003h	100Fh	1011h	1013h	101Fh	1021h	1023h	102Fh	1031h	1033h	103Fh
Size	512(B)	512(B)	512(B)	512(B)	512(B)	512(B)	512(B)	512(B)	2(B)	2(B)	12(B)	2(B)	2(B)	12(B)	2(B)	2(B)	12(B)	2(B)	2(B)	12(B)
Data Type	User	User	User	User	User	User	User	User	R	User	User	R	User	User	R	User	User	R	User	User

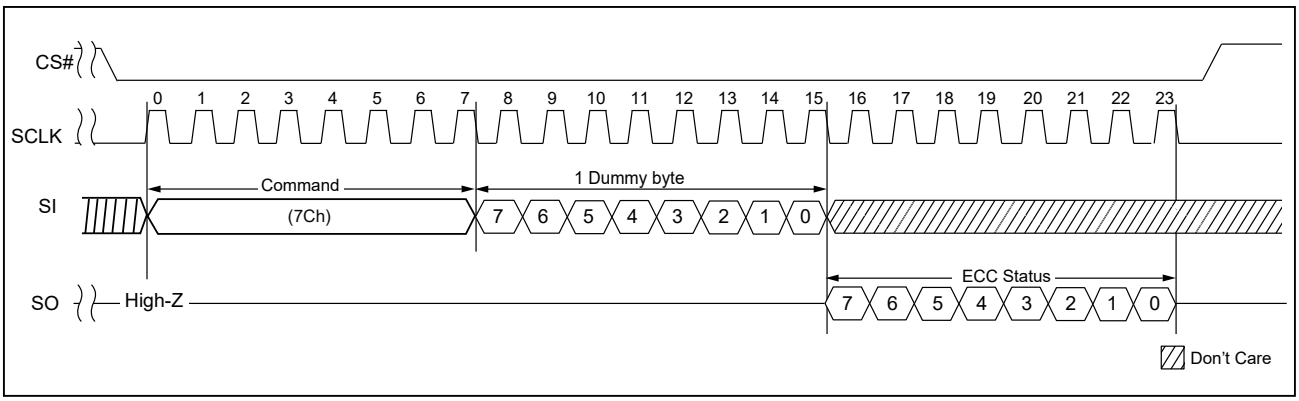
Table 15. The Distribution of ECC Segment and Spare Area - 4Gb (Cont'd)

Area	Spare(4)			Spare(5)			Spare(6)			Spare(7)			Spare2 (0)	Spare2 (1)	Spare2 (2)	Spare2 (3)	Spare2 (4)	Spare2 (5)	Spare2 (6)	Spare2 (7)
	R1	M2	M1	R1	M2	M1	R1	M2	M1	R1	M2	M1								
Addr. (Start)	1040h	1042h	1044h	1050h	1052h	1054h	1060h	1062h	1064h	1070h	1072h	1074h	1080h	1090h	10A0h	10B0h	10C0h	10D0h	10E0h	10F0h
Addr. (End)	1041h	1043h	104Fh	1051h	1053h	105Fh	1061h	1063h	106Fh	1071h	1073h	107Fh	108Fh	109Fh	10AFh	10BFh	10CFh	10DFh	10EFh	10FFh
Size	2(B)	2(B)	12(B)	2(B)	2(B)	12(B)	2(B)	2(B)	12(B)	2(B)	2(B)	12(B)	16(B)	16(B)	16(B)	16(B)	16(B)	16(B)	16(B)	16(B)
Data Type	R	User	User	R	User	User	R	User	User	R	User	User	ECC	ECC	ECC	ECC	ECC	ECC	ECC	ECC

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8-7-2. Read ECCSR (7Ch) command for ECC Status Read

Besides the Get Feature(with feature address of C0h) may collect the internal ECC status; the 7Ch command may read out the error bits number for the worst segment of the page(s). This command reports two kinds of ECC status. The first kind is the ECC status for the current page, the second kind is the ECC status for the accumulated pages



Error #	ECCSR[3:0]
0	0000
1	0001
2	0010
3	0011
4	0100
5	0101
6	0110
7	0111
8	1000
>8	1111

bit7	bit6	bit5	bit4	bit3	bit2	bit1	bit0
ECC Status for the accumulated pages				ECC Status for the current page			
ECCSR[3]	ECCSR[2]	ECCSR[1]	ECCSR[0]	ECCSR[3]	ECCSR[2]	ECCSR[1]	ECCSR[0]

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8-8. Flexible ECC Bit Flip Threshold Setting & Read ECC Warning Page Address

Flexible ECC Bit Flip Threshold Setting: Host can set the ECC warning criterion by themselves. This Serial Flash offers “BFT[3:0]” for the user to set their own ECC warning criterion. The Chip will report the warning status when on the status feature bits ECC_S[1:0] error bit number is larger or equal to the BFT.

Table 16. Flexible ECC Bit Flip Threshold Setting & Read ECC Warning Page Address

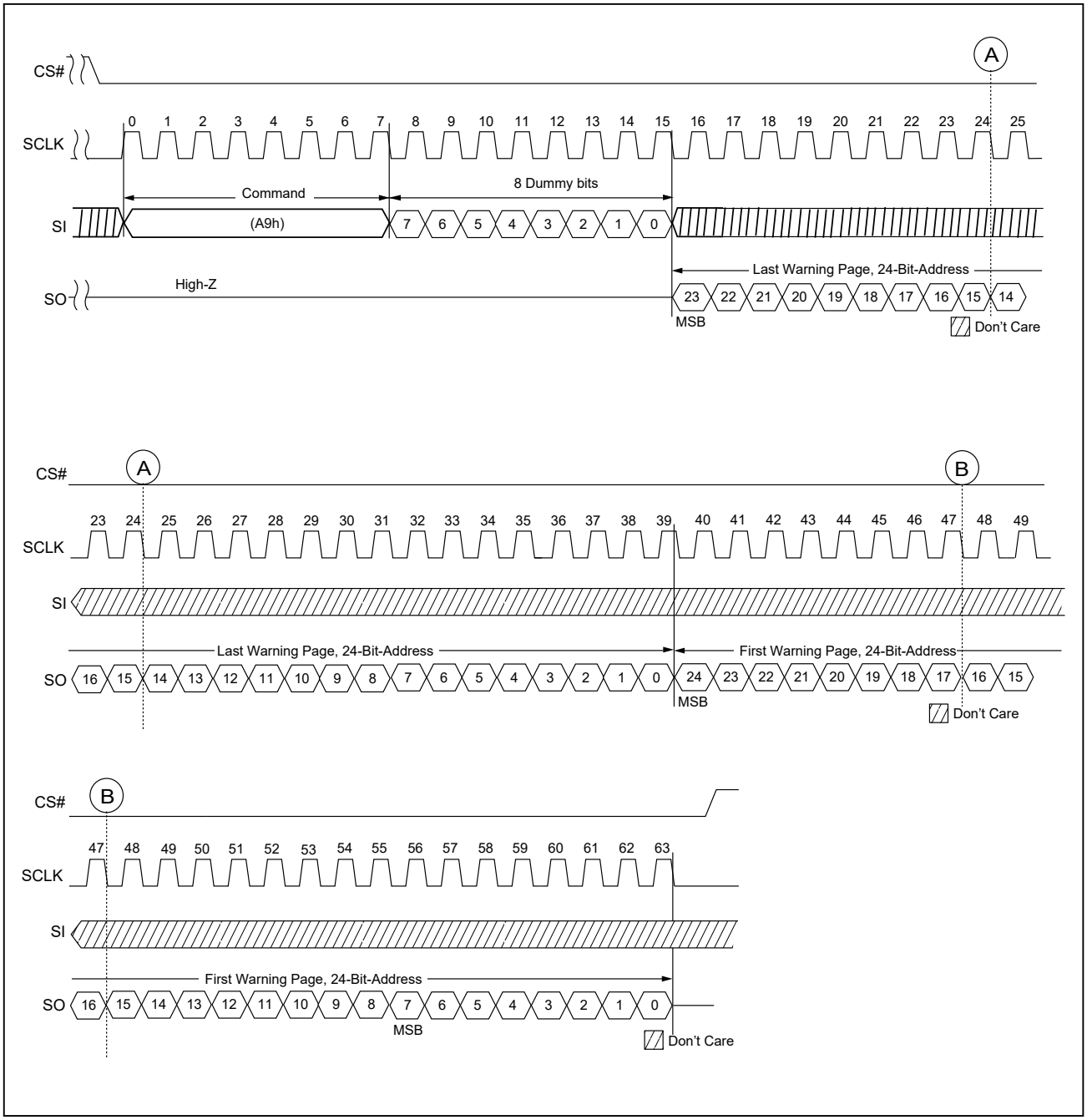
ADD	Register	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Default Value
10h	Configuration	BFT3	BFT2	BFT1	BFT0				ENPGM	F0h

BFT[3:0]	
0000	Detect uncorreted error
0001	Detect ≥1 bit error
0010	Detect ≥2 bit error
0011	Detect ≥3 bit error
0100	Detect ≥4 bit error
0101	Detect ≥5 bit error
0110	Detect ≥6 bit error (suggestion)
0111	Detect ≥7 bit error
1000	Detect ≥8 bit error
1001	Detect uncorrected error
1010	Detect uncorrected error
1011	Detect uncorrected error
1100	Detect uncorrected error
1101	Detect uncorrected error
1110	Detect uncorrected error
1111	Detect uncorrected error (default)

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Read ECC warning page address: Host can get the 1st and last page addresses which reaches the ECC warning criterion. During continuous read operation, the chip will record the 1st and last page address with error bit number is larger or equal to BFT[3:0] . Host can issue the “Read ECC warning Page address” command to read out these two page addresses

Figure 22. ECC Warning Timing



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8-9. Program Operations

8-9-1. PAGE PROGRAM

With following operation sequences, the PAGE PROGRAM operation programs the page from byte 1 to byte 4224 (4Gb) and byte 1 to byte 2112 (1Gb/2Gb).

WRITE ENABLE (06h) → PROGRAM LOAD (02h) → PROGRAM LOAD RANDOM DATA (84h) if needed → PROGRAM EXECUTE (10h) → GET FEATUR from command to read status (0Fh) or RDSR (05h).

WEL bit is set with the WRITE ENABLE (06h) issued. The program operation will be ignored if 06h command not issued. In a single page, four partial page programs are allowed. Exceeded bytes (Page address is larger than 4224(4Gb) or 2112(1Gb/2Gb) for "PROGRAM LOAD" or "PROGRAM LOAD RANDOM DATA", the exceeding bytes will be ignored. When CS goes high, the "PROGRAM LOAD" or "PROGRAM LOAD RANDOM DATA" operation" terminates. Please note the figure below for PROGRAM LOAD.

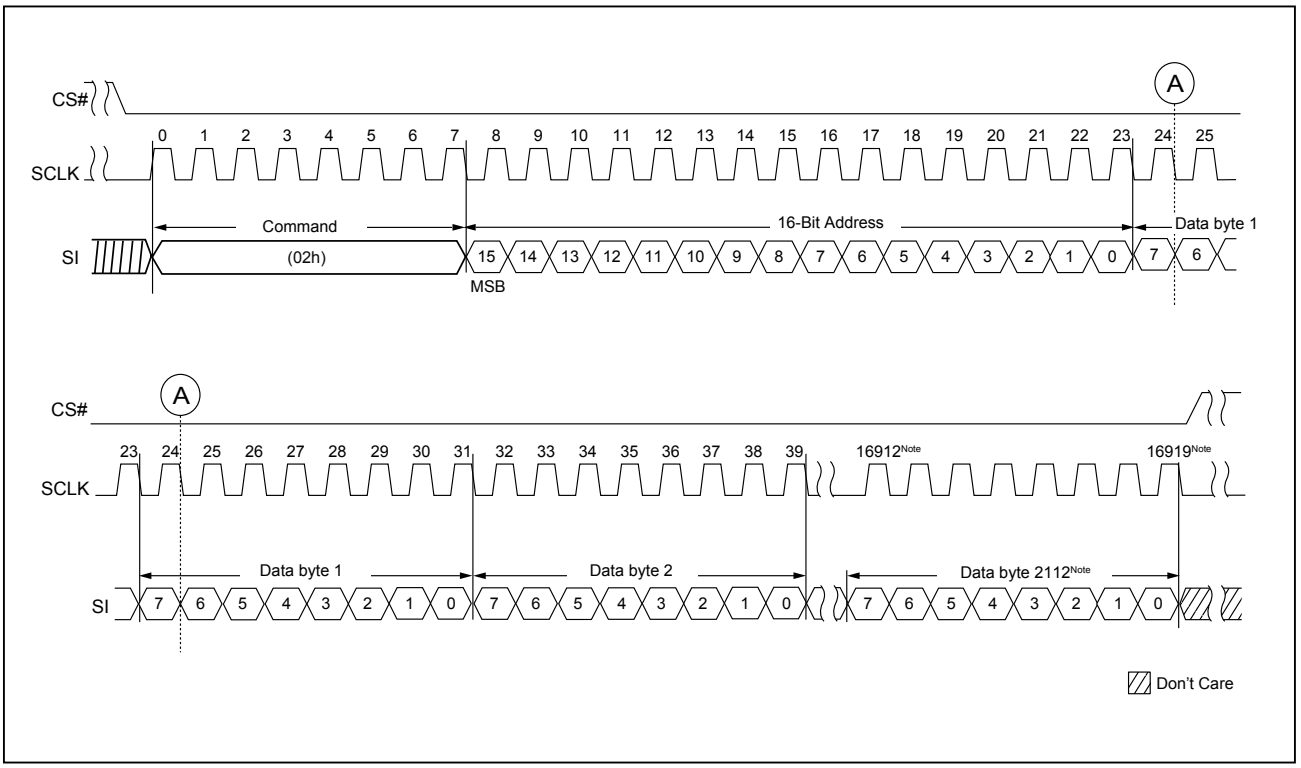
After PROGRAM LOAD is done, the programming of data should be as following steps: issue 10h (PROGRAM EXECUTE) with 1byte command code, 24 bits address → code programming to memory and busy for tPROG → Program complete.

The page program operation in a block should start from the low address to high address.

During programming, status to be polled by the status register.

Operation shows in the Figure below.

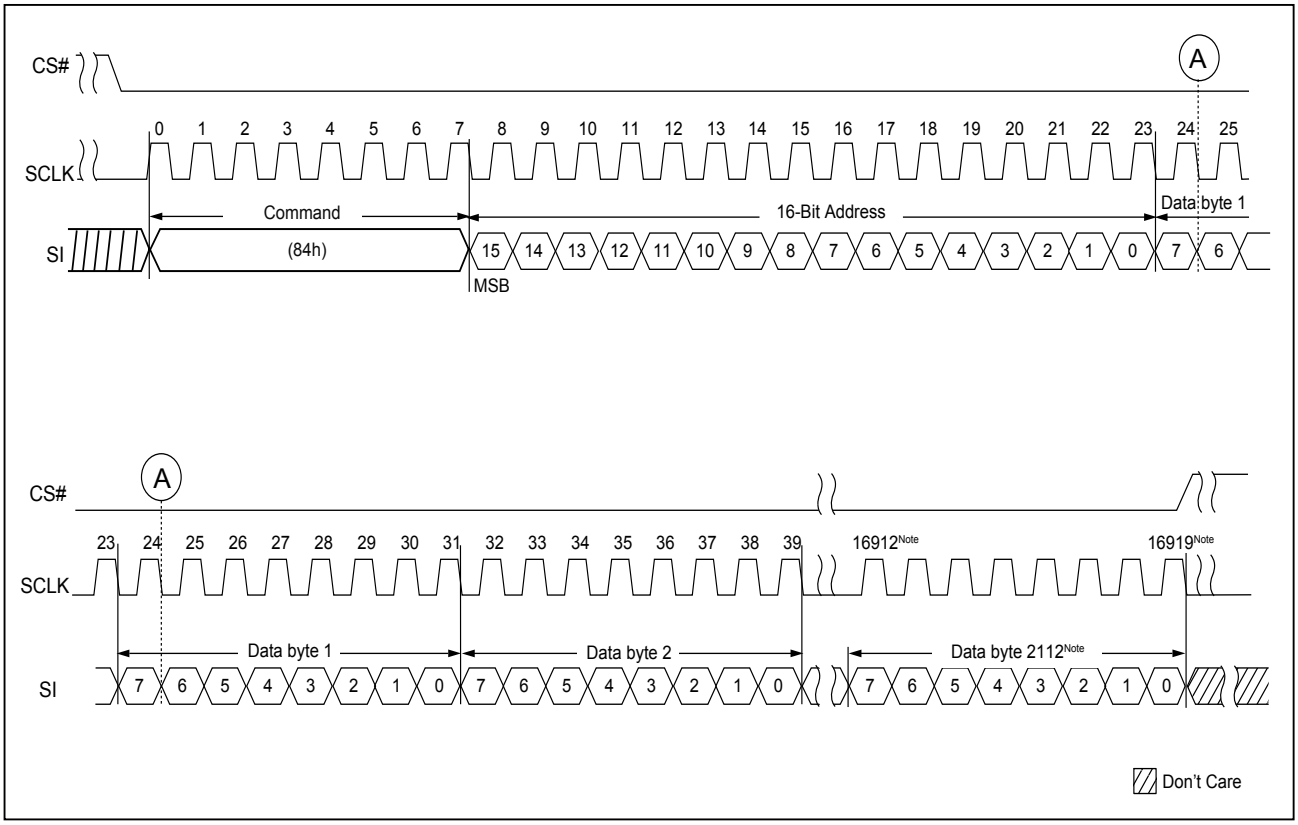
Figure 23. PROGRAM LOAD (02h) Timing



Note: *2KB+64B as example.*

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Figure 24. PROGRAM LOAD RANDOM DATA (84h) Timing



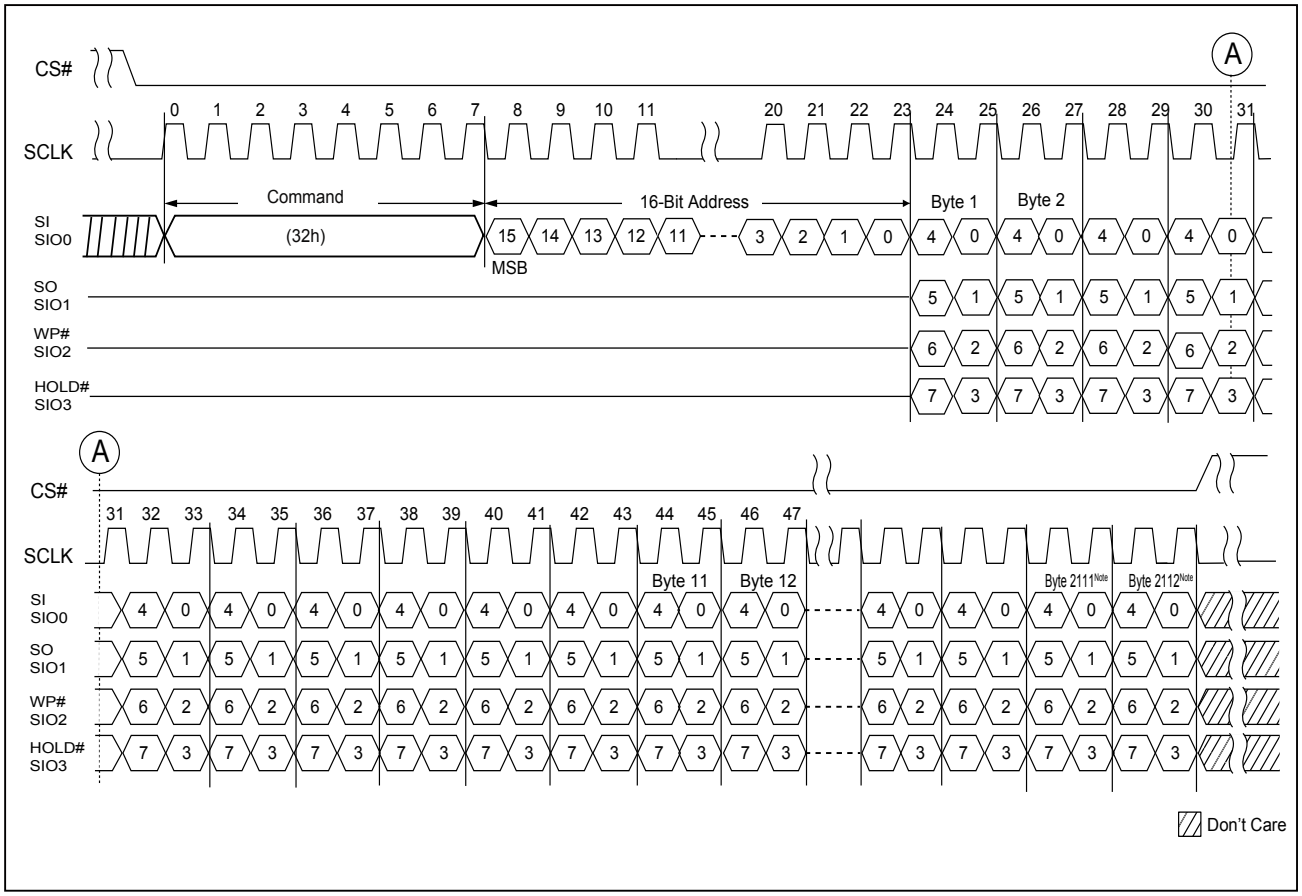
Note: *2KB+64B as example.*

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8-9-2. QUAD IO PAGE PROGRAM

QUAD IO PAGE PROGRAM conducts the 4KB(for 4Gb) and 2KB(for 1Gb/2Gb) program with 4 I/O mode. The steps are: WRITE ENABLE (06h) → PROGRAM LOAD X4 (32h) → PROGRAM LOAD RANDOM DATA (34h) if needed → PROGRAM EXECUTE (10h) → Poll status by issuing GET FEATURE (0Fh) or RDSR (05h).

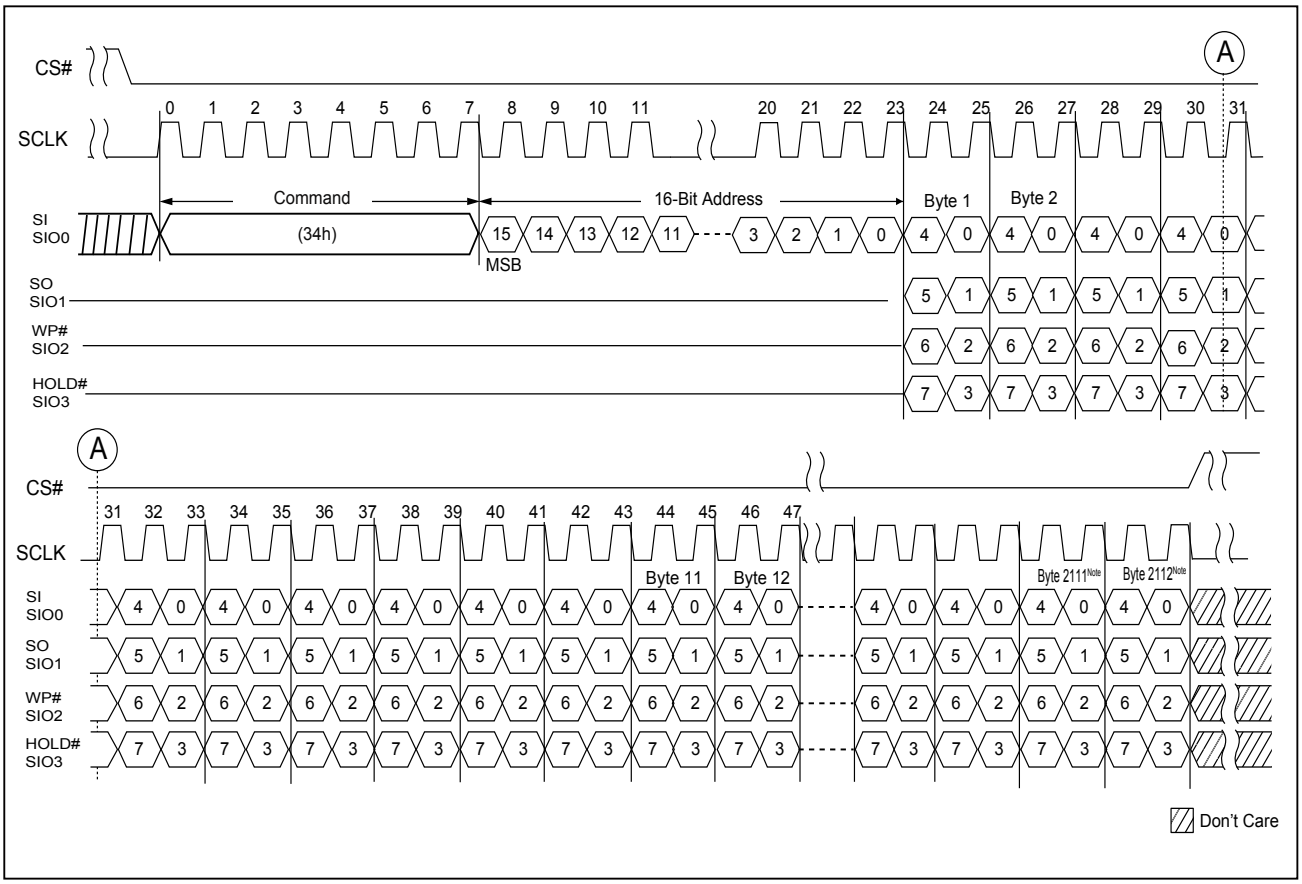
Figure 25. PROGRAM LOAD X4 (32h) Timing



Note: *2KB+64B as example.*

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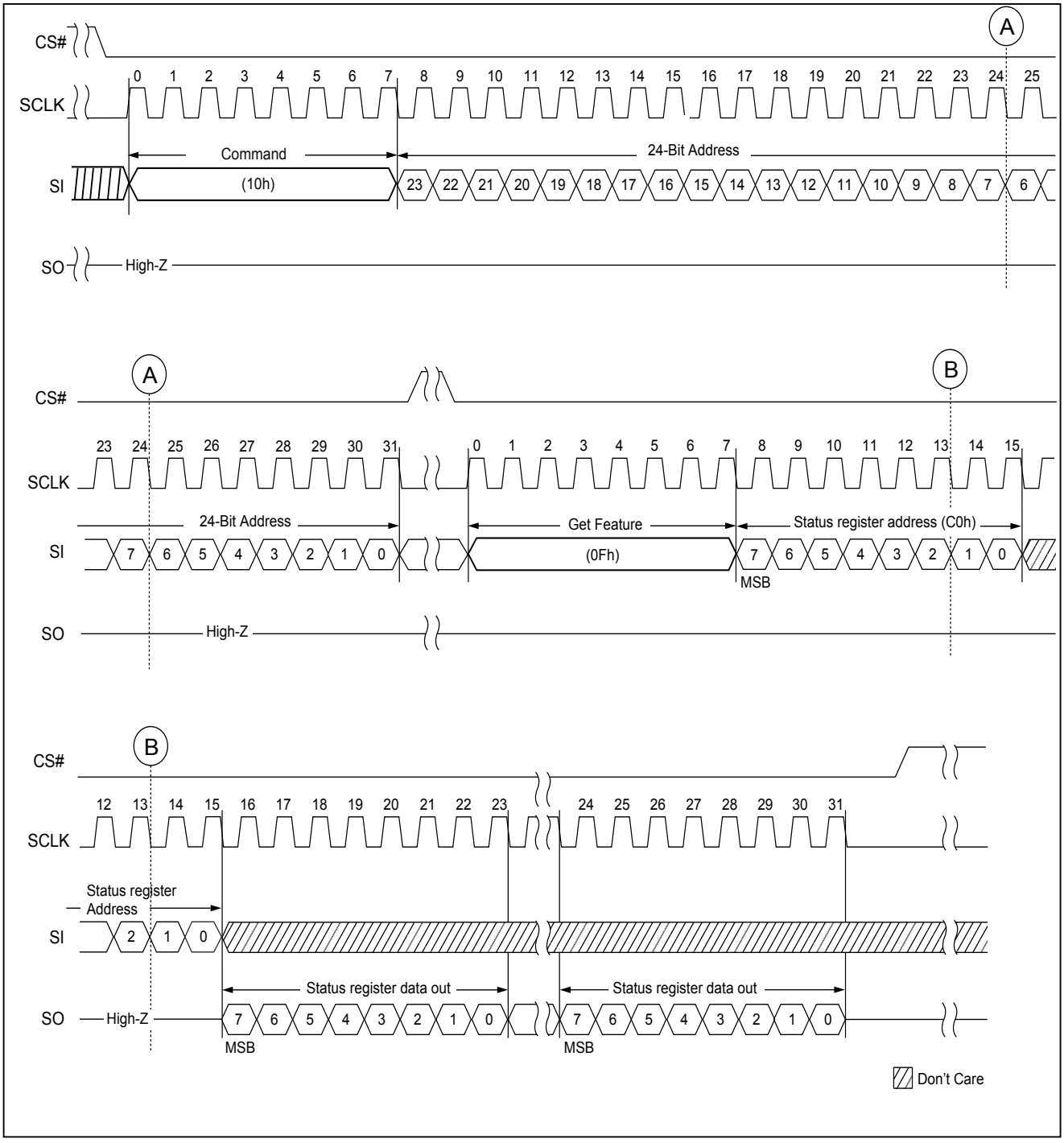
Figure 26. QUAD IO PROGRAM RANDOM INPUT (34h) Timing



Note: *2KB+64B as example.*

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Figure 27. PROGRAM EXECUTE (10h) Timing



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8-10. BLOCK OPERATIONS

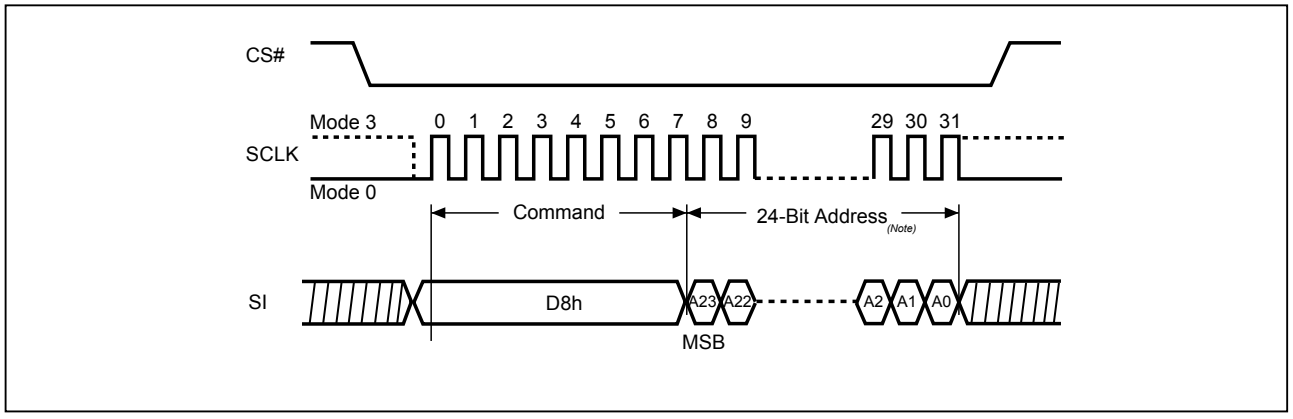
Block Erase (D8h)

The Block Erase (D8h) instruction is for erasing the data of the chosen block to be "1". The instruction is used for a block of 256KB(for 4Gb) or 128KB(for 1Gb/2Gb) erase operation. A Write Enable (WREN) instruction be executed to set the Write Enable Latch (WEL) bit before sending the Block Erase (D8h). Any address of the block is a valid address for Block Erase (D8h) instruction. The CS# must go high exactly at the byte boundary (the least significant bit of address byte been latched-in); otherwise, the instruction will be rejected and not executed. Finally, a Get Feature(0Fh) or RDSR (05h) instruction to check the status is necessary.

The sequence of issuing Block Erase instruction is: CS# goes low→ send Block Erase instruction code→ 24-bit address on SI→CS# goes high.

The self-timed Block Erase Cycle time (tBE) is initiated as soon as Chip Select (CS#) goes high. The Get Feature (0Fh) instruction with Address (C0h) or RDSR (05h) may check the status of the operation during the Block Erase cycle is in progress (please refer to the waveform **"Figure 7. GET FEATURE (0Fh) Timing"** and **"Table 8. Feature Settings"**). The OIP bit is "1" during the tBE timing, and is cleared to "0" when Block Erase Cycle is completed, and the Write Enable Latch (WEL) bit is cleared.

Figure 28. Block Erase (BE) Sequence



Note: *The 24-bit Address includes: 17-bit row address and 7-bit dummy (for 2Gb/4Gb), or 16-bit row address and 8-bit dummy (for 1Gb).*

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9. SPI NOR Compatible Command

Considering some SoC(or MCU) of host system must adopt the read protocol of SPI NOR like, this device provide the SPI_NOR_EN of configuration register bit to enable the read protocol of SPI NOR like for Read From Cache commands. The SPI_NOR_EN bit is OTP type once it is enable and cannot disable.

It is recommended to set the SPI_NOR_EN bit by programmer machine in advance before power on while attempts to adopt the read protocol of SPI NOR like.

Please refer to **"Figure 33. Special OTP Configuration Register Program Operation (for V2/OTP Type of Configuration Register Bits)"**.

Table 17. Command Set - SPI NOR Like Protocol Enabled

(SPI_NOR_EN = 1, CONT=0)

Mode	1st Byte	2nd Byte	3rd Byte	4th Byte	5th Byte	6th Byte	7th Byte	8th Byte
Get Feature	0Fh	ADD	**Data**					
Read Status	05h	Data						
Set Feature	1Fh	ADD	Data					
Page Read	13h	RADD2	RADD1	RADD0				
Page Read Cache Random	30h	RADD2	RADD1	RADD0				
Page Read Cache Sequential	31h							
Page Read Cache End	3Fh							
Read From Cache x1	03h	DUMMY	CADD1	CADD0	DATA~			
Read From Cache x1 (Alternative)	0Bh	DUMMY	CADD1	CADD0	DUMMY	DATA~		
Read From Cache x2 Note3	3Bh	CADD1	CADD0	DUMMY	DATA~*2			
Read From Cache x4 Note3	6Bh	CADD1	CADD0	DUMMY	DATA~*4			
Read From Cache Dual IO 1-2-2 Note3	BBh	CADD1*2	CADD0*2	DUMMY*2	DATA~*2			
Read From Cache Quad IO 1-4-4 Note3	EBh	CADD1*4	CADD0*4	DUMMY*4	DUMMY*4	DATA~*4		
Read ID	9Fh	DUMMY	MID	DID1	DID2			
Block Erase	D8h	RADD2	RADD1	RADD0				
Program Execute	10h	RADD2	RADD1	RADD0				
Program Load x1	02h	CADD1	CADD0	DATA~				
Program Load Random Data x1	84h	CADD1	CADD0	DATA~				
Program Load x4 Note3	32h	CADD1	CADD0	DATA~*4				
Program Load Random Data x4 Note3	34h	CADD1	CADD0	DATA~*4				
Write Enable	06h							
Write Disable	04h							
Reset	FFh							
Read ECCSR	7Ch	DUMMY	SR_ECC					
Write BBM	A1h	LBA	LBA	PBA	PBA			
Read BBM Note1	A5h	DUMMY	LBA0	LBA0	PBA0	PBA0	LBA1	LBA1~
ECC Warning Page Address Note2	A9h	DUMMY	RADD2_L	RADD1_L	RADD0_L	RADD2_F	RADD1_F	RADD0_F

Notes: *1. A5h command may read the 40 links of BBM_table (LBAx/PBAx)*
2. RADDx_L: Last Warning Page Address, RADDx_F: First Warning Page Address
*3. *2 stands for the dual I/O phase and *4 for quad I/O mode.*

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Table 18. Command Set - SPI NOR Like Protocol Enabled & Continuous Read Operation

(**SPI_NOR_EN = 1**, **CONT=1**)

Mode	1st Byte	2nd Byte	3rd Byte	4th Byte	5th Byte	6th Byte	7th Byte	8th Byte
Get Feature	0Fh	ADD	Data					
Read Status	05h	Data						
Set Feature	1Fh	ADD	Data					
Page Read	13h	RADD2	RADD1	RADD0				
Read From Cache x1	03h	DUMMY	DUMMY	DUMMY	DATA~			
Read From Cache x1 (Alternative)	0Bh	DUMMY	DUMMY	DUMMY	DUMMY	DATA~		
Read From Cache x2[Note3]	3Bh	DUMMY	DUMMY	DUMMY	DATA~[*2]			
Read From Cache x4[Note3]	6Bh	DUMMY	DUMMY	DUMMY	DATA~[*4]			
Read From Cache Dual IO 1-2-2[Note3]	BBh	DUMMY[*2]	DUMMY[*2]	DUMMY[*2]	DATA~[*2]			
Read From Cache Quad IO 1-4-4[Note3]	EBh	DUMMY[*4]	DUMMY[*4]	DUMMY[*4]	DUMMY[*4]	DATA~[*4]		
Read ID	9Fh	DUMMY	MID	DID1	DID2			
Block Erase	D8h	RADD2	RADD1	RADD0				
Program Execute	10h	RADD2	RADD1	RADD0				
Program Load x1	02h	CADD1	CADD0	DATA~				
Program Load Random Data x1	84h	CADD1	CADD0	DATA~				
Program Load x4[Note3]	32h	CADD1	CADD0	DATA~[*4]				
Program Load Random Data x4[Note3]	34h	CADD1	CADD0	DATA~[*4]				
Write Enable	06h							
Write Disable	04h							
Reset	FFh							
Read ECCSR	7Ch	DUMMY	SR_ECC					
Write BBM	A1h	LBA	LBA	PBA	PBA			
Read BBM[Note1]	A5h	DUMMY	LBA0	LBA0	PBA0	PBA0	LBA1	LBA1~
ECC Warning Page Address[Note2]	A9h	DUMMY	RADD2_L	RADD1_L	RADD0_L	RADD2_F	RADD1_F	RADD0_F

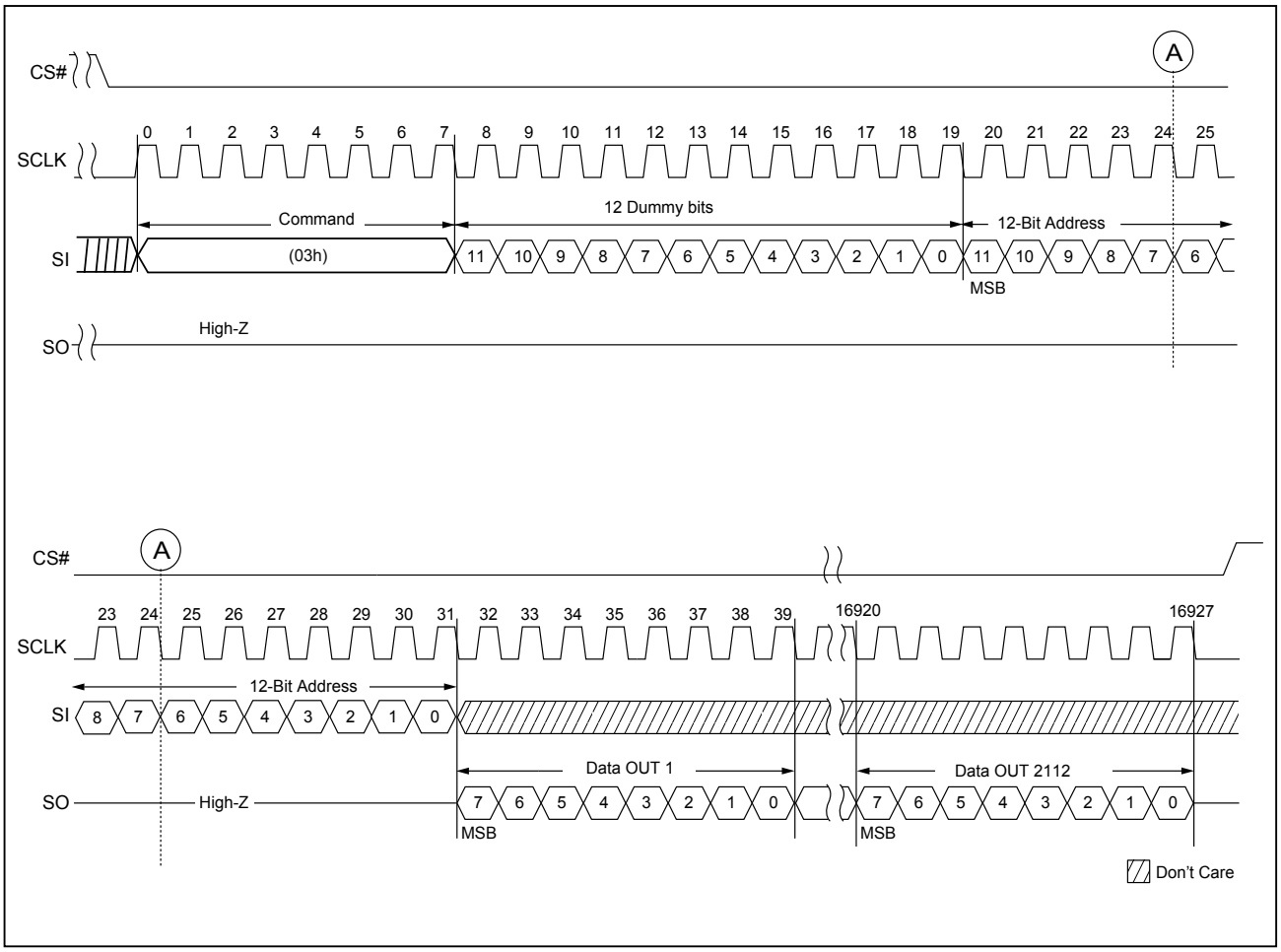
Notes: *1. A5h command may read the 40 links of BBM_table (LBAx/PBAx)*

2. RADDx_L: Last Warning Page Address, RADDx_F: First Warning Page Address

*3. *2 stands for the dual I/O phase and *4 for quad I/O mode*

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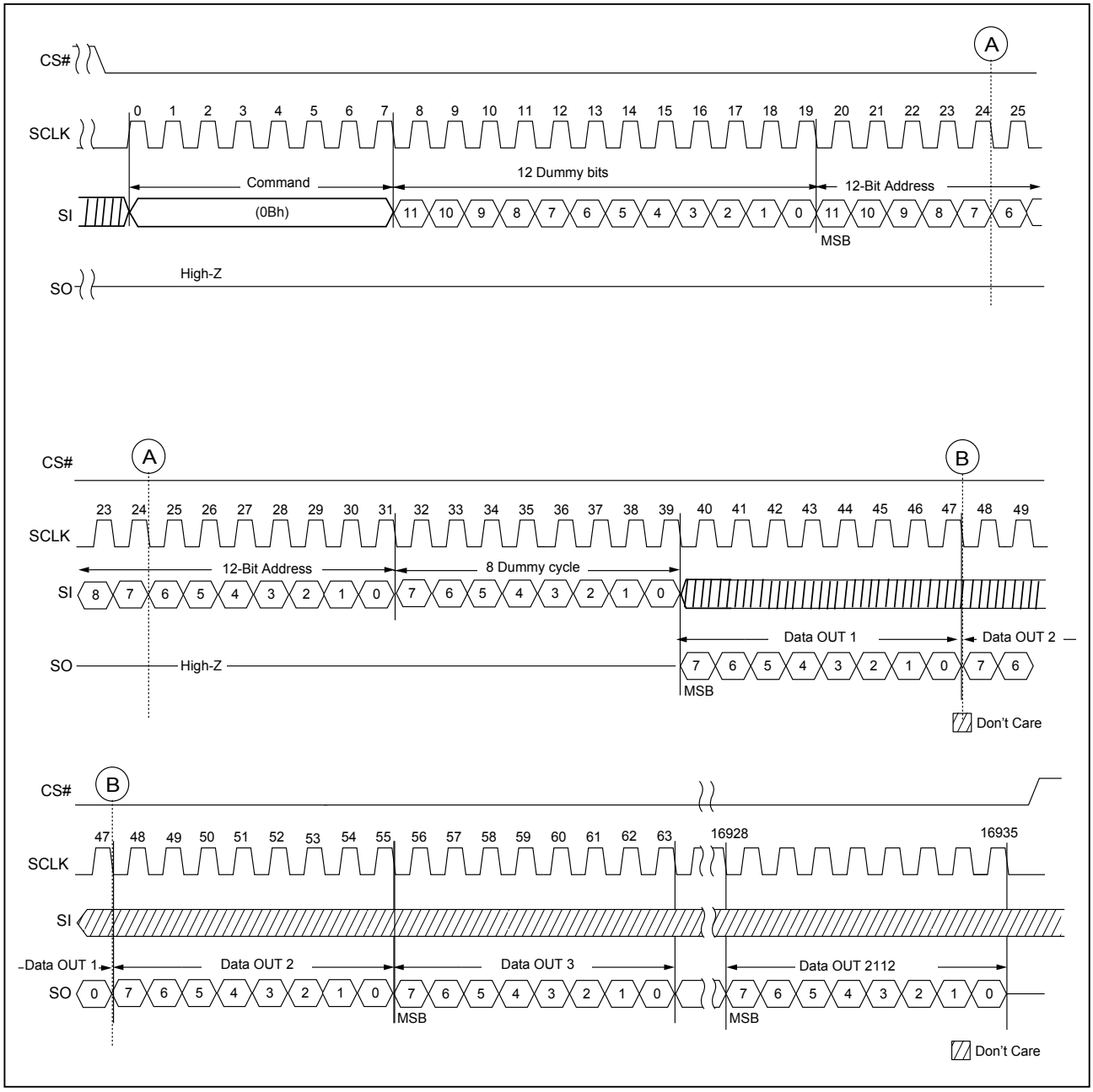
Figure 29. Read From Cache x1 (NOR like)



***Note**: For SPI NOR Like Protocol command ('SPI_NOR_EN'=1), the Read From Cache command (03h) can run up to 20MHz only.*

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Figure 30. Read From Cache x1 (Alternative, NOR like)



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10. Feature Register

Feature register defines various register's definitions (Block Protection, Secure OTP, Status register). The definition of each register is defined in **"Table 19. Definition of Protection Bits"**.

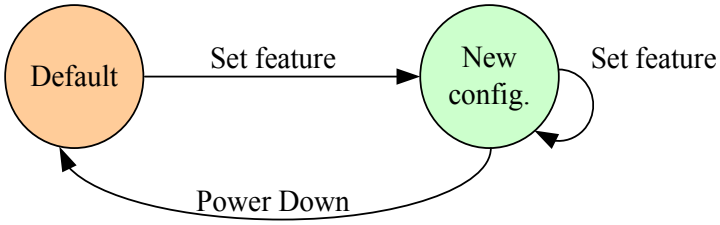
10-1. Configuration Feature Operation

10-1-1. Type: Volatile Register [Symbol: V]

Default value: can not be changed

Set feature command to change configuration register

Figure 31. Setting of Volatile Configuration Register

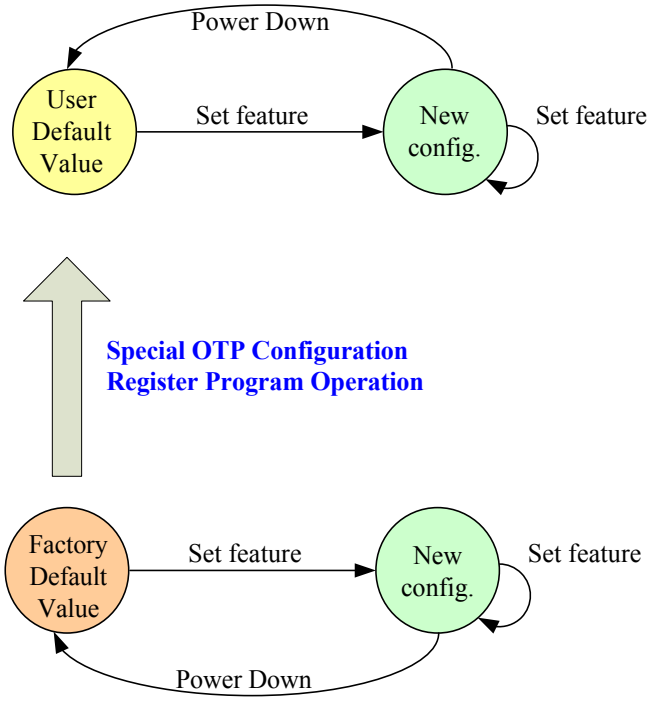


10-1-2. Type: Volatile Register with OTP Fuse Default Value [Symbol: V2]

Default value: can be changed by special OTP Configuration Register program operation.

Set feature command to change value of configuration register. Those configuration register bits of type V2 are: CONT, BFT[3:0], DS_IO[1:0].

Figure 32. Setting of Volatile Configuration Register (Type: V2)



10-1-3. Type: One-time Setting Register [Symbol: OTP]

- SPI_NOR_EN, OTPRWSP bit

The OTP Configuration Register bits can be only changed from 0 to 1 through Special OTP Configuration Register Program Operation.

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10-2. OTP "Configuration" Register Solid Protection

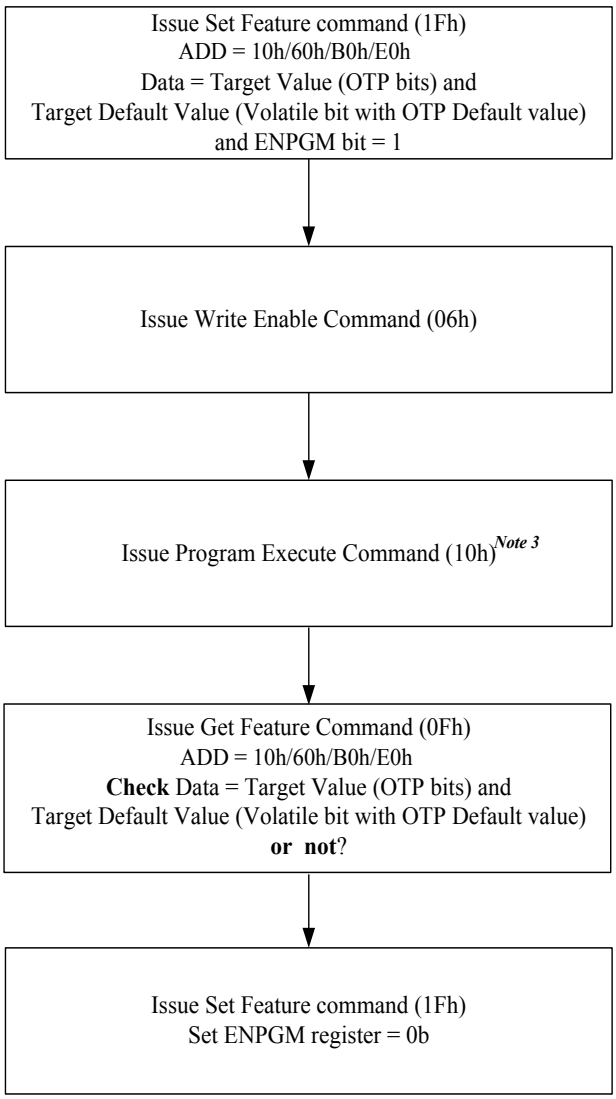
To avoid the OTP register bits and OTP Fuse value of V2 type Register bits to be programmed accidentally, this chip provide OTPRWSP (OTP register write solid protection) register to prevent it.

If OTPRWSP register bit is not programmed, the V2/OTP type registers (e.g. CONT, BFT[3:0], DS_IO[1:0], SPI_NOR_EN, OTPRWSP) can be programmed; after the OTPRWSP register is programmed, the V2/OTP type registers can not be programmed anymore.

User should program OTPRWSP register even though they do not want to change the V2/OTP register. This can avoid the accidental programming of the V2/OTP register during later usage.

For those "V" type registers in the ADD=10h/60h/B0h/E0h, please must keep as "0" value while use the 'Special OTP configuration register program operation'.

Figure 33. Special OTP Configuration Register Program Operation (for V2/OTP Type of Configuration Register Bits)



Notes:

1. *OTP Configuration Registers can be programmed together or individually by this programming flow.*
2. *It is recommended to program OTPRWSP register for V2/OTP Configuration Register solid protection. The related V2/OTP Configuration Registers can't be changed anymore, while OTPRWSP=1b.*
3. *User need check 'OIP' bit to get device ready before get the new register data.*

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10-3. Block Protection Feature

The Block Protection feature includes three block protection bits (BPx), Block Protection Register Write Disable (BPRWD). Inverse bit (INVERT), complement bit (COMPLEMENTARY) and Solid Protection Bit (SP).

Soft Protection Mode (SPM)

The SPM uses the BPx bits, INVERT, and COMPLEMENTARY bits to allow part of memory to be protected as read only. The protected area definition is shown as **"Table 19. Definition of Protection Bits"**. The protected areas are more flexible which may protect various area by setting value of BP0-BP2 and Invert bit, and Complementary bit. These are volatile bits and can be modified by set feature command.

After power-up, the chip is in protection state, that is, the feature bits BPx is 1, all other bits (BPRWD, INVERT, COMPLEMENTARY and SP) are 0. The Set feature instruction (1Fh) with feature address (A0h) may change the value of the block protection bits and un-protect whole chip or a certain area for further program/erase operation. For example, after the power-on, the whole chip is protected from program/erase operation, the top 1/64 area may be un-protected by using the Set feature instruction (1Fh) with the feature address (A0h) to change the values of BP2 and BP1 from "1" to "0" as the Block protection register bits in **"Table 22. Configuration Register Bit Descriptions"**.

Hardware Protection Mode (HPM) & Solid Protection Mode (SDPM)

Under the Hardware Protection mode and Solid Protection Mode, the (BPx, INVERT, COMPLEMENTART) bits can not be changed.

Hardware Protection Mode: The device enters HPM if BPRWD bits is set to 1 and WP#/SIO2 is driven to 0.

Note 1: *HPM also requires SP bit to be 0 state .*

Note 2: *The Quad mode is not supported in HPM.*

Solid Protection Mode: If SP bit is set to 1, the device enters SDPM. After that, the selected block is solid protected and can not be un-protected until next power cycle.

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Table 19. Definition of Protection Bits

BP2	BP1	BP0	Invert	Complementary	Protection Area
0	0	0	x	x	all unlocked
0	0	1	0	0	upper 1/64 locked
0	1	0	0	0	upper 1/32 locked
0	1	1	0	0	upper 1/16 locked
1	0	0	0	0	upper 1/8 locked
1	0	1	0	0	upper 1/4 locked
1	1	0	0	0	upper 1/2 locked
1	1	1	x	x	all locked (default)
0	0	1	1	0	lower 1/64 locked
0	1	0	1	0	lower 1/32 locked
0	1	1	1	0	lower 1/16 locked
1	0	0	1	0	lower 1/8 locked
1	0	1	1	0	lower 1/4 locked
1	1	0	1	0	lower 1/2 locked
0	0	1	0	1	lower 63/64 locked
0	1	0	0	1	lower 31/32 locked
0	1	1	0	1	lower 15/16 locked
1	0	0	0	1	lower 7/8 locked
1	0	1	0	1	lower 3/4 locked
1	1	0	0	1	block 0
0	0	1	1	1	upper 63/64 locked
0	1	0	1	1	upper 31/32 locked
0	1	1	1	1	upper 15/16 locked
1	0	0	1	1	upper 7/8 locked
1	0	1	1	1	upper 3/4 locked
1	1	0	1	1	block0

Note: *Block #0 is at lower portion.*

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10-4. Secure OTP (One-Time-Programmable) Feature

There is an Secure OTP area which has 30 full pages (30 x 4224B for 4Gb or 30 x 2112B for 1Gb/2Gb) from page 02h to page 1Fh guarantee to be good for system device serial number storage or other fixed code storage. The Secure OTP area is a non-erasable and one-time-programmable area, which is default to “1” and allows partial page program to be “0”, once the Secure OTP protection mode is set, the Secure OTP area becomes read-only and cannot be programmed again.

The Secure OTP operation is operated by the Set Feature instruction with feature address (B0h) to access the Secure OTP operation mode and Secure OTP protection mode.

To check the Serial Flash device is ready or busy in the Secure OTP operation mode, the status register bit 0 (OIP bit) may report the status by Get Feature command operation.

To exit the Secure OTP operation or protect mode, it can be done by writing "0" to both Bit7 (Secure OTP protect bit) and bit6 (Secure OTP enable bit) for returning to the normal operation.

Secure OTP Read

1. Issuing the Set Feature instruction (1Fh)
2. Sending the Feature address (B0h) and set the "Secure OTP Enabled Bit" as "1".
3. Issuing normal Page Read command (13h)

Secure OTP Program (if the "Secure OTP Protection Bit" is "0") for

1. Issuing the Set Feature instruction (1Fh)
2. Sending the Feature address (B0h) and set the "Secure OTP Enabled Bit" as "1".
3. Issuing WRITE ENABLE command (06h)
4. Issuing Page Program command (02h)
5. Issuing program execute command (10h)

Secure OTP Protection

1. Issuing the Set Feature instruction (1Fh)
2. Sending the Feature address (B0h) and set both the "Secure OTP Protection Bit" and "Secure OTP Enabled Bit" as "1".
3. Issuing program execute command (10h)

Table 20. Secure OTP States

Secure OTP Protection Bit[Note1]	Secure OTP Enabled Bit	State
0	0	**Normal operation**
0	1	**Access the Secure OTP for reading or programming**
1	0	**Not applicable**
1	1	**Secure OTP Protection by using the Program Execution command (10h)[Note2]**

Note 1. *OTP protection bit is volatile.*

Note 2. *Once the "Secure OTP Protection Bit" and "Secure OTP Enabled Bit" are set as "1", the secure OTP becomes read only.*

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11. Configuration Registers and Status Registers

The device provides several registers which includes Block Protection registers and configuration registers to set the feature configurations as well as the status register to output the device status.

The resulting information is outlined in **"Table 21. Status Register Bit Descriptions"** & **"Table 22. Configuration Register Bit Descriptions"**.

11-1.Status Register

11-1-1. Get Feature command (0Fh)

MX35UFxGE4AD provides a status register that outputs the device status by writing a Get Feature command (0Fh) with the feature address (C0h), and then the IO pins output the status. Refer to **"Figure 7. GET FEATURE (0Fh) Timing"**.

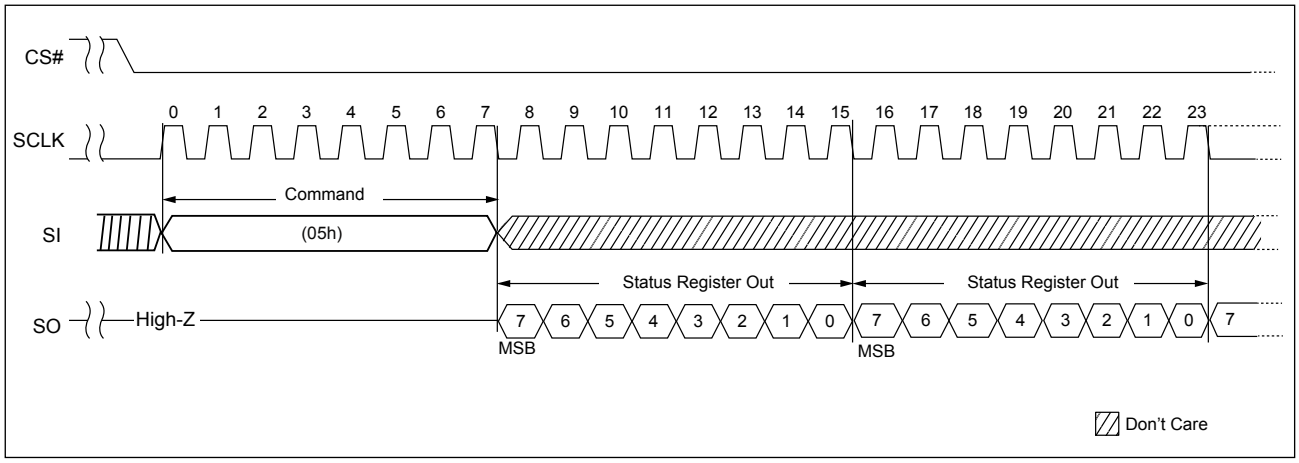
The Get Feature (0Fh) command with the feature address(C0h) will keep the device at the status read mode unless next valid command is issued. The resulting information is outlined as **"Table 21. Status Register Bit Descriptions"**.

11-1-2. Read Status command (RDSR, 05h)

In additional to read the chip status by Get Feature command, this device also supports the SPI NOR Read Status command (05h). The Read Status command can be issued any time (even during read/program/erase operation), it is recommended to check the Operation in Program (OIP) bit or Cache Read Busy (CRBSY) before sending a new instruction when a read, program or erase operation is in progress.

The sequence of issuing RDSR instruction is CS# goes low→ send RDSR instruction code →Status register data out on SO.

Figure 34. Read Status Register (RDSR)



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Table 21. Status Register Bit Descriptions

Register	Feature bits	Type	Description
Status	CRBSY	V	Chip busy status for Cache Read operation 0b: Chip is ready and can accepted new command for cache operation 1b: Chip is busy and cannot accept new command for cache read operation
	BBMT_F	V	BBM table is full or not 0b: BBM table is not full and new L2P link can be added 1b: BBM table is full and new L2P link cannot be added
	ECC_S[1:0]	V	The bit shows the status of ECC as below: 00b = 0 bit error 01b = bit error are detected and been corrected, bit error count is less than the bit flip threshold 10b = bit error and can not be corrected. 11b = bit error are detected and been corrected, bit error count is equal or more than the bit flip threshold. If CONT=0, the value of ECC_Sx(S1:S0) bits will be cleared as “00b” by reset command. After the page read or page read cache operation is completed, the bits will be updated to reflect the ECC status of the current output page. The ECC_Sx(S1:S0) value reflects the ECC status of the content of the POR page (the default POR page is the page 0 of the block 0) after a power-on reset. If CONT=1, the value of ECC_Sx(S1:S0) bits will not be cleared by the reset command. After the continuous read operation is completed, the bits will be updated to reflect the ECC status of the accumulated pages in the current continuous read operation. The ECC_Sx(S1:S0) value reflects the ECC status of the content of the accumulated pages which starts from the POR page after a power-on reset. If the internal ECC is disabled by the Set feature command, the ECC_ Sx(S1:S0) are invalid.
	P_FAIL	V	The bit value shows the status of program failure or if host program any invalid address or protected area (including protected blocks or protected Secure OTP area). 0: Passed 1: Failed The bit value will be cleared (as "0") by RESET command or during the program execute command operation.
	E_FAIL	V	The bit value shows the status of erase failure or if host erase any invalid address or protected area (including protected blocks or protected Secure OTP area). 0: Passed, 1: Failed The bit value will be cleared (as "0") by RESET command or at the beginning of the block erase command operation.
	WEL	V	Status bit for write enable successful or not. The bit value will be cleared (as "0") by issuing Write Disable command(04h) or after the program/erase operation completion. 0b: the chip is write protected and cannot accept any program/erase command 1b: the chip is not write protected and can accept the program/erase command
	OIP	V	Chip busy Status bit 0b: Chip is ready 1b: Chip is busy

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Table 22. Configuration Register Bit Descriptions

Register	Feature bits	Type	Description
Special Read for Data Recovery	SPEC_RD[2:0]	V	Special Read for data recovery option
Configuration	ENPGM	V	Enable the special OTP configuration register program operation 0b: Disabled 1b: Enabled
	BFT[3:0]	V2	ECC bit flip threshold
	OTPRWSP	OTP	V2/OTP type feature register write solid protection 0b: V2/OTP feature register are not solid protected 1b: V2/OTP feature register are solid protected (after OTPRWSP bit is programmed)
	SPI_NOR_EN	OTP	Enable SPI NOR Interface 0b: SPI NOR Interface is NOT selected 1b: SPI NOR Interface is selected
	CONT	V2	Enable Continuous read operation mode 0b: Not enabled 1b: Enabled
	QE	V	Quad enable 0b: Not enabled 1b: Enabled
	OTP_PROT	V	Secure OTP protection 0b: Not enabled 1b: Enabled
	OTPEN	V	Secure OTP enable 0b: Not enabled 1b: Enabled
	ECC_EN	V	Internal ECC enabled 0b: Not enabled 1b: Enabled (default)
	DS_IO[1:0]	V2	I/O Strength Feature, refer to **"Table 4. I/O Strength Feature Table"**
Block Protection	BPRWD	V	Block protection on register write protect 0b: Block protection register is not protected 1b & WP# = HI: Block protection register is not protected 1b & WP# = Low: Block protection register is protected
	BP[2:0], Invert, Complementary	V	Block protection registers
	SP	V	Enabled the block protection register write solid protection function 0b: Block protection register is not solid protected 1b: Block protection register is solid protected

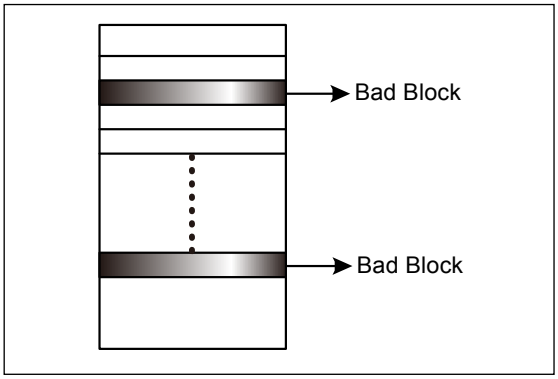
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12. SOFTWARE ALGORITHM

12-1. Invalid Blocks (Bad Blocks)

The bad blocks are included in the device while it gets shipped. During the time of using the device, the additional bad blocks might be increasing; therefore, it is necessary to check the bad block marks and avoid using the bad blocks. Furthermore, please read out the bad block information before any erase operation since the bad block marks may be cleared by any erase operation.

Figure 35. Bad Blocks



While the device is shipped, the value of all data bytes of the good blocks are FFh. The 1st byte of the 1st and 2nd page in the spare area for bad block will be 00h. The erase operation at the bad blocks is not recommended.

After the device is installed in the system, the bad block checking is recommended. **"Figure 36. Bad Block Test Flow"** shows the brief test flow by the system software managing the bad blocks while the bad blocks were found. When a block gets damaged, it should not be used any more.

Due to the blocks are isolated from bit-line by the selected gate, the performance of good blocks will not be impacted by bad ones.

Table 23. Valid Blocks

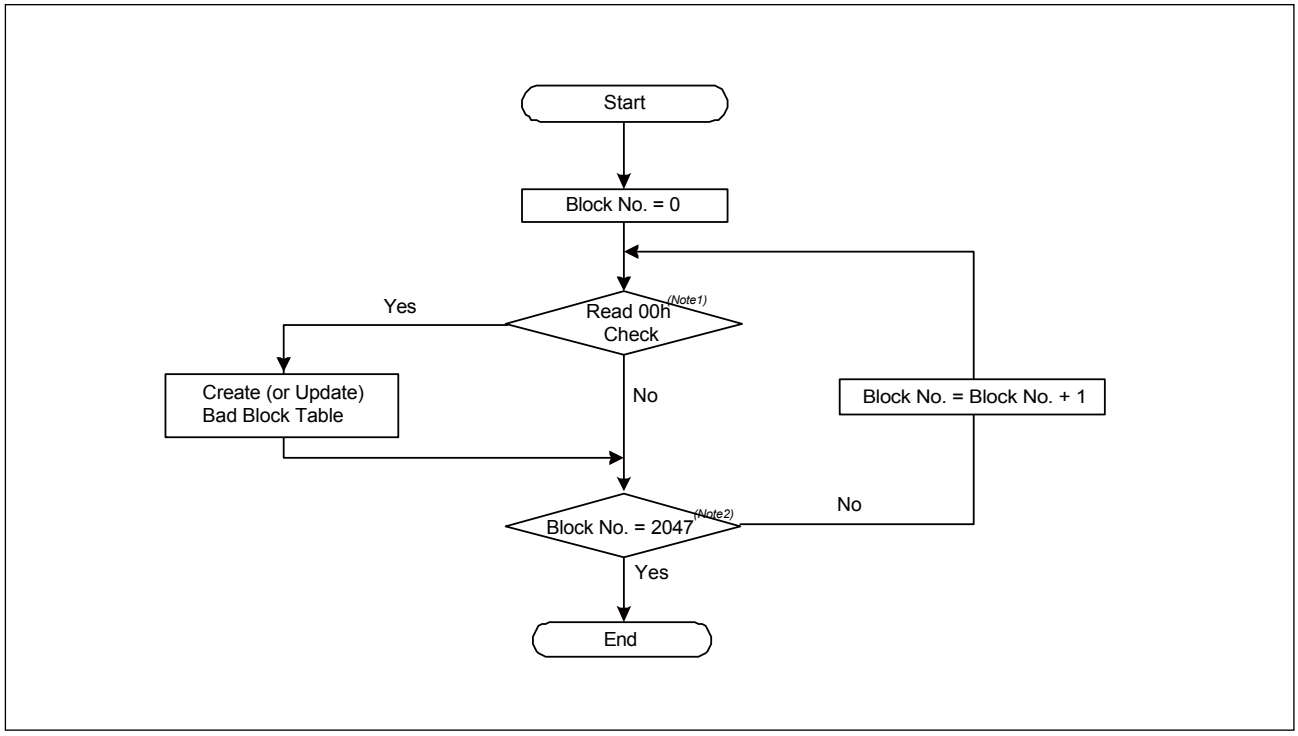
	Density	Min.	Typ.	Max.	Unit	Remark
Valid (Good) Block Number	4Gb	2008		2048	Block	Block 0-7 is guaranteed to be good
	2Gb	2008		2048	Block	Block 0-7 is guaranteed to be good
	1Gb	1004		1024	Block	Block 0-7 is guaranteed to be good

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12-2. Bad Block Test Flow

Although the initial bad blocks are marked by the flash vendor, they could be inadvertently erased and destroyed by a user that does not pay attention to them. To prevent this from occurring, it is necessary to always know where any bad blocks are located. Continually checking for bad block markers during normal use would be very time consuming, so it is highly recommended to initially locate all bad blocks and build a bad block table and reference it during normal Serial flash use. This will prevent having the initial bad block markers erased by an unexpected program or erase operation. Failure to keep track of bad blocks can be fatal for the application. For example, if boot code is programmed into a bad block, a boot up failure may occur. **"Figure 36. Bad Block Test Flow"** shows the recommended flow for creating a bad block table. There is a simple way to build the bad block table, by utilizing the internal "Bad Block management" table in the device and maintain the link of logical to physical block address.

Figure 36. Bad Block Test Flow



Note 1: *Read 00h check is at the 1st byte of the 1st and 2nd pages of the block spare area.*

Note 2: *Block No.=1023 for 1Gb.*

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Bad Block Management Function

The BBM table supports 40 links.

The BBM table is an OTP Non-volatile memory

1. The BBM table is written by “Write BBM” command (A1h) and input the address of LBA & PBA, and then wait a tPROG time.
2. The user can read the BBM by “read BBM” command (A5h)

Figure 37. BBM Table

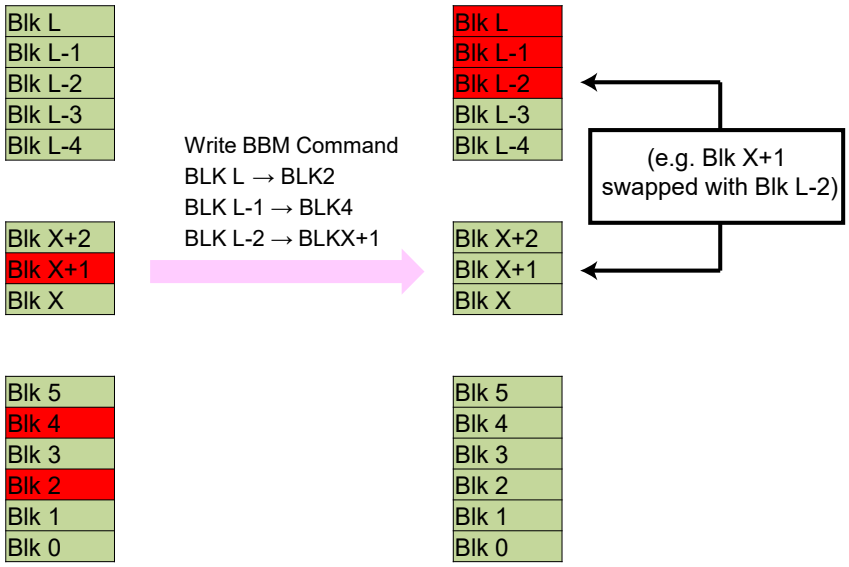
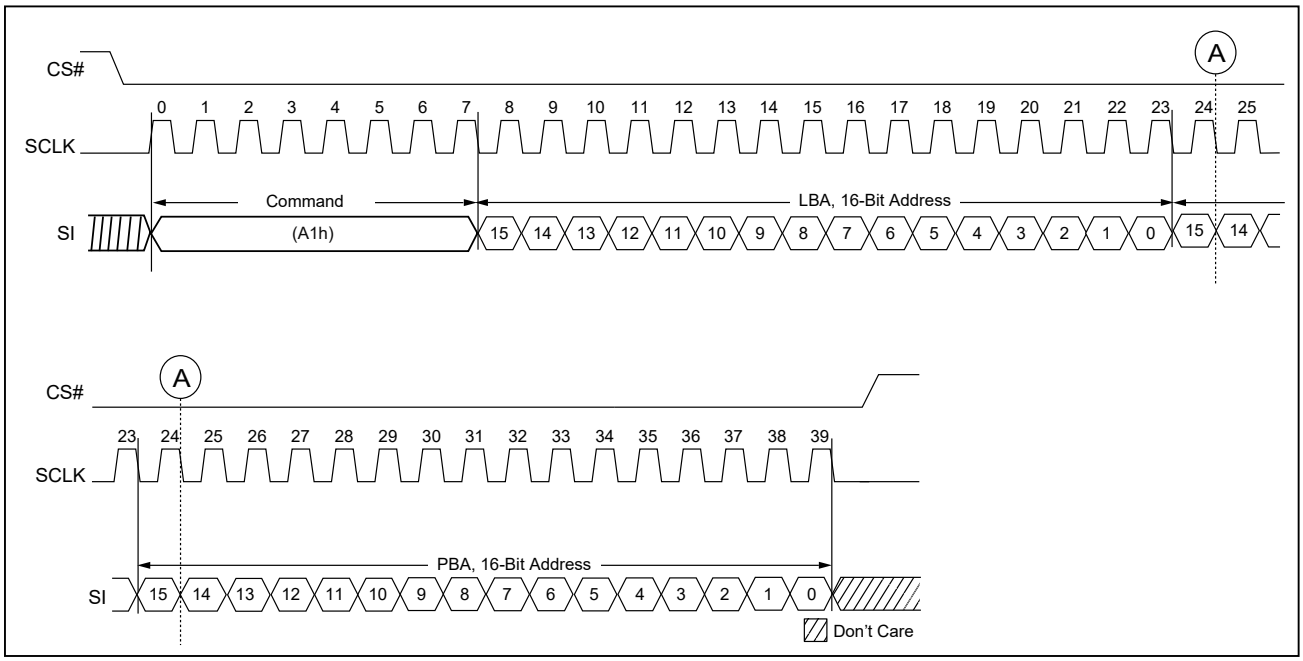
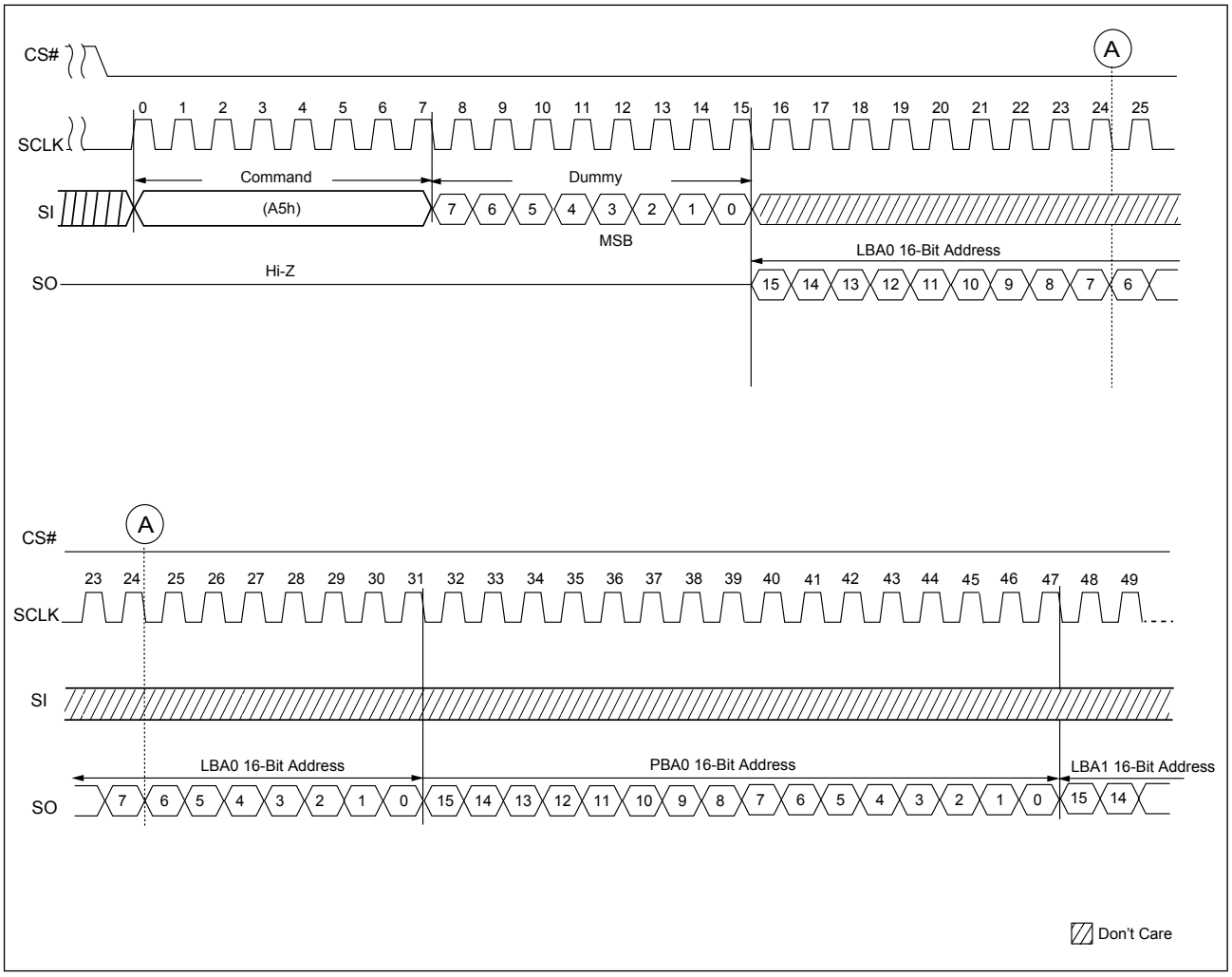


Figure 38. Write BBM Command (A1h)



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Figure 39. Read BBM Command (A5h)



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Figure 40. Bad Block Management

The user can read the BBM table full or not by “get feature” command for BBMT_F status bit.

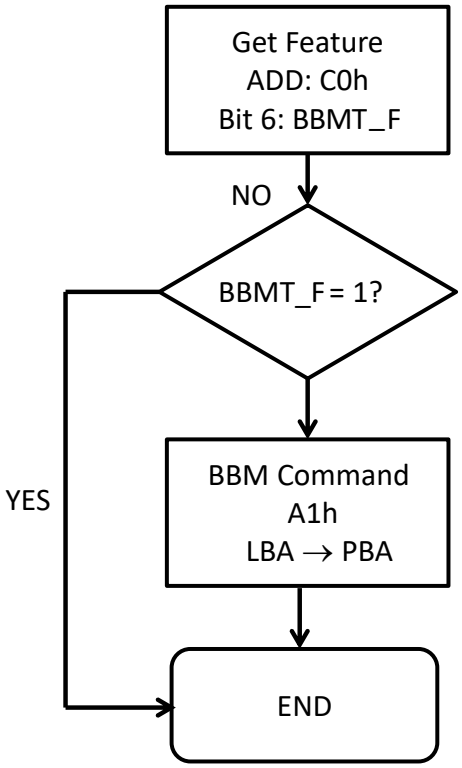


Table 24. BBM Address Definition

When user read out the BBM table, the LBA[15:14] has special meaning which indicates this link is enable and valid status.

ADD	bit7	bit6	bit5	bit4	bit3	bit2	bit1	bit0
LBA[15:8]	ENABLE	INVALID	0	0	0	LRA[16]*Note*	LRA[15]	LRA[14]
LBA[7:0]	LRA[13]	LRA[12]	LRA[11]	LRA[10]	LRA[9]	LRA[8]	LRA[7]	LRA[6]
PBA[15:8]	0	0	0	0	0	PRA[16]*Note*	PRA[15]	PRA[14]
PBA[7:0]	PRA[13]	PRA[12]	PRA[11]	PRA[10]	PRA[9]	PRA[8]	PRA[7]	PRA[6]

Note: *LRA[16]/PRA[16] is not applicable for 1Gb.*

ENABLE	INVALID	Description
0	0	This link is not used
1	0	This link is enabled and valid
1	1	This link is enabled but invalid
0	1	This case does not exist

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12-3. Failure Phenomena for Read/Program/Erase Operations

The device may fail during a Read, Program or Erase operation. The following possible failure modes should be considered when implementing a highly reliable system:

Table 25. Failure Modes

Failure Mode	Detection and Countermeasure	Sequence
Erase Failure	**Status Read after Erase**	Block Replacement
Programming Failure	**Status Read after Program**	Block Replacement
Read Failure	**Read Failure**	Special Read

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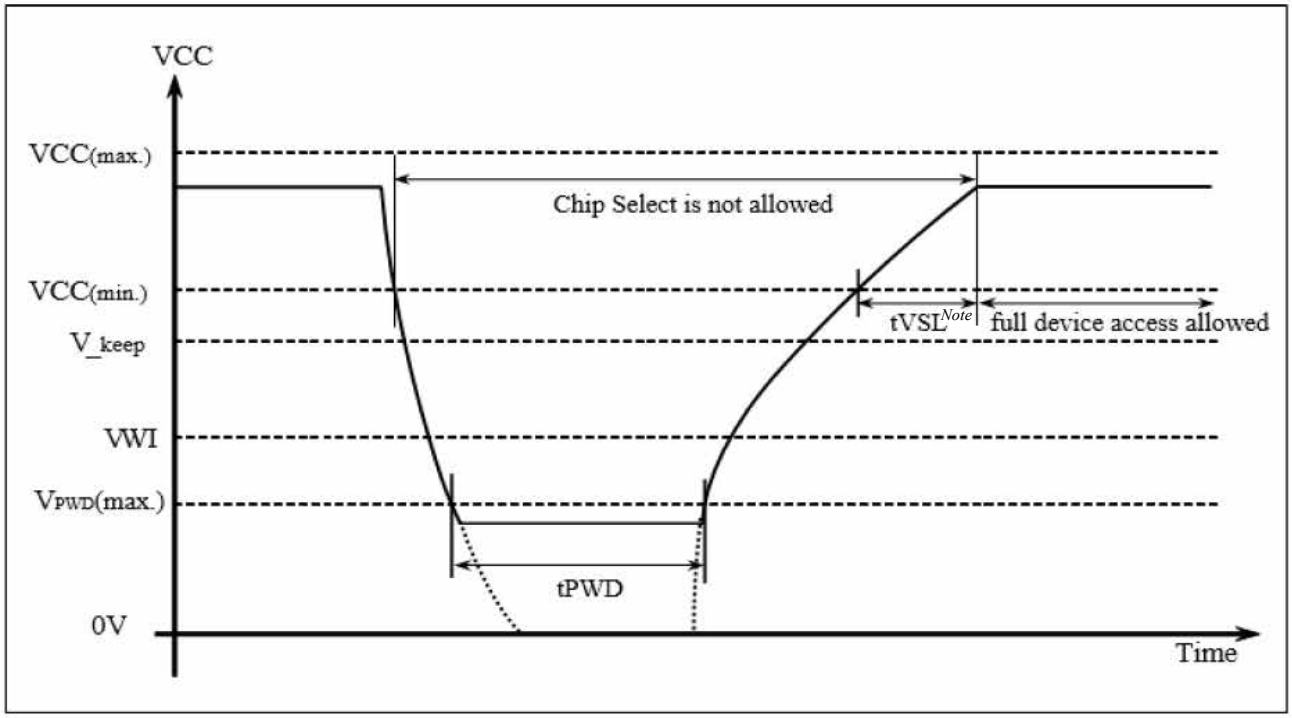
13. DEVICE POWER-UP

13-1. Power-up

After the Chip reaches the power on level, the internal power on reset sequence will be triggered. During the internal power on reset period, no any external command is accepted. The device can be fully accessible when VCC reaches the power-on level and wait 5ms.

During power-up, it is recommended that CS# should follow the voltage applied on VCC, and SCLK/SI/WP#/HOLD# should either keep low or follow the voltage applied on VCC.

Figure 41. Power Up/Down and Voltage Drop



Note: *After VCC ramp up to VCC(min) during power on, the user can issue the read status command to check 'OIP' bit for the chip busy status.*

Table 26. Power-Up/Down Voltage and Timing

Symbol	Parameter	Min.	Max.	Unit
V_{PWD}	VCC voltage needs to be below V_{PWD} for proper initialization to occur		0.9	V
$V_{_keep}$	Voltage threshold where re-initialization is necessary if VDD drop below to $V_{_KEEP}$	1.5		V
tPWD	The minimum duration to ensure initialization occurs	300		us
tVSL	VCC(min.) to device operation	5000		us
VCC	VCC Power Supply	1.7	1.95	V
VWI	Write Inhibit Voltage	1.0	1.5	V

Note: *These parameters are characterized only.*

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14. PARAMETERS

14-1. ABSOLUTE MAXIMUM RATINGS

Temperature under Bias	-50°C to +125°C
Storage temperature	-65°C to +150°C
All input voltages with respect to ground (Note 2)	-0.6V to 2.4V
VCC supply voltage with respect to ground (Note 2)	-0.6V to 2.4V
ESD protection	>2000V

Notes:

1. *The reliability of device may be impaired by exposing to extreme maximum rating conditions for long range of time.*
2. *Permanent damage may be caused by the stresses higher than the "Absolute Maximum Ratings" listed.*
3. *During voltage transitions, all pins may overshoot Vss to -1.0V and Vcc to +1.0V for periods up to 20ns, please refer to* **"Figure 42. Maximum Negative Overshoot Waveform"** *and* **"Figure 43. Maximum Positive Overshoot Waveform"**.

Figure 42. Maximum Negative Overshoot Waveform

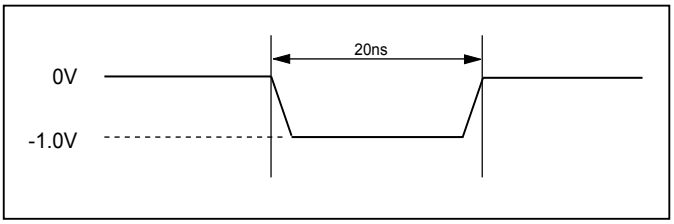


Figure 43. Maximum Positive Overshoot Waveform

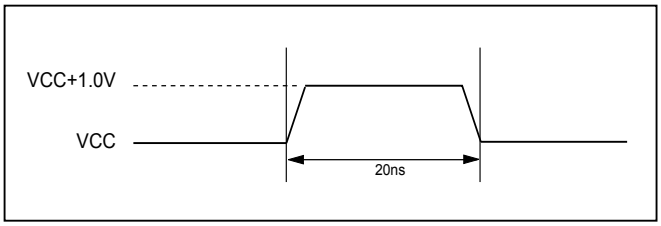


Table 27. AC Testing Conditions

Testing Conditions	Value	Unit
Input pulse level	0 to VCC	V
Output load capacitance	1TTL+CL(30)	pF
Input rising & falling time	5	ns
Input timing measurement reference levels	VCC/2	V
Output timing measurement reference levels	VCC/2	V

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Table 28. Capacitance

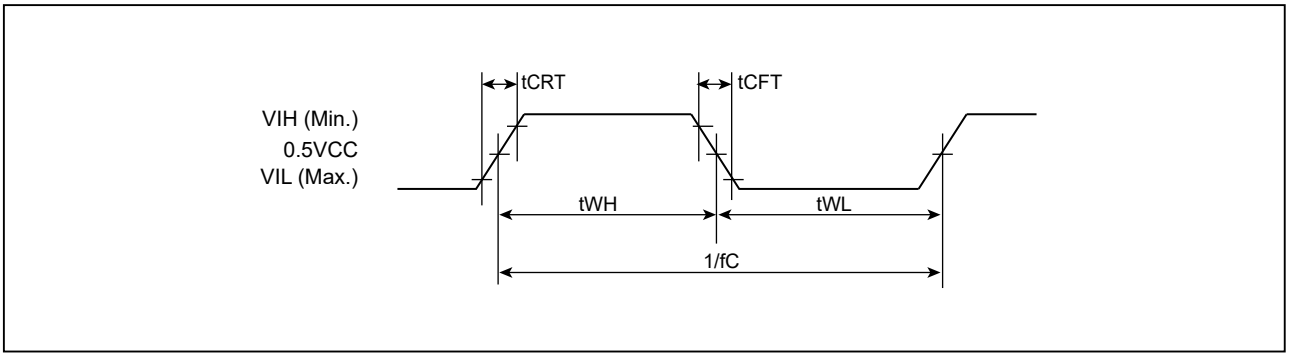
TA = +25°C, F = 1 MHz

Symbol	Parameter	Min.	Typ.	Max.	Units	Conditions
CIN	Input capacitance			10	pF	VIN = 0V
COUT	Output capacitance			10	pF	VOUT = 0V

Table 29. Operating Range

Temperature	VCC	Tolerance
-40°C to + 85°C	+1.8V	1.7-1.95V

Figure 44. SCLK TIMING DEFINITION



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Table 30. DC Characteristics

Symbol	Parameter	Min.	Typical	Max.	Unit	Test Conditions
ILI	Input leakage current			± 10	uA	VIN= 0 to VCC MAX
ILO	Output leakage current			± 10	uA	VOUT= 0 to VCC MAX
ISB1	VCC standby current (CMOS)			110	uA	VIN=VCC or GND, CS#=VCC
ICC1	VCC active current (Read for non-continuous read operation)		19	40	mA	f=133MHz, Iout = 0mA
			12	30	mA	f=80MHz, Iout = 0mA
ICC2	VCC active current (Read for continuous read operation)		31	40	mA	f=80MHz, Iout = 0mA
ICC3	VCC active current (Program)		26	40	mA	
ICC4	VCC active current (Erase)		14	30	mA	
VIL	Input low level	-0.3		0.2VCC	V	
VIH	Input high level	0.8VCC		VCC + 0.3	V	
VOL	Output low voltage			0.2	V	IOL= 1mA
VOH	Output high voltage	VCC-0.2			V	IOH= -20uA

Table 31. General Timing Characteristics

Symbol	Parameter		Note	Min.	Max.	Unit
fC	**Serial Clock Frequency for all command**		1	D.C.	133	MHz
tCHHH	**HOLD# Hold Time (relative to SCLK)**			3.375	-	ns
tCHHL	**HOLD Hold Time (relative to SCLK)**			3.375	-	ns
tCS	**CS# Diselect Time**			30	-	ns
tCHSH	**CS# Active Hold Time (relative to SCLK)**			3.375	-	ns
tSLCH	**CS# Active Setup Time (relative to SCLK)**			3.375	-	ns
tSHCH	**CS# Not Active Setup Time (relative to SCLK)**			3.375	-	ns
tCHSL	**CS# Not Active Hold Time (relative to SCLK)**			3.375	-	ns
tDIS	**Output Disable Time**			-	9	ns
tHC	**HOLD Setup Time (relative to SCLK)**			3.375	-	ns
tHD	**HOLD# Setup Time (relative to SCLK)**			3.375	-	ns
tHDDAT	**Data Input Hold Time**			2	-	ns
tHO	**Data Output Hold time**			1.5	-	ns
tHZ	**HOLD# to Output High-Z**			-	12	ns
tLZ	**HOLD# to Output Low-Z**			-	7	ns
tSUDAT	**Data In Setup Time**			2	-	ns
tV	**Serial Clock Low to Output Valid**	**30pF**		-	6	ns
		15pF		-	5	ns
tWH	**Serial Clock High Time**			0.45 x 1/fC	-	ns
tWL	**Serial Clock Low Time**			0.45 x 1/fC	-	ns
tCRT	**Clock Rise Time (peak to peak)**			0.5		V/ns
tCFT	**Clock Fall Time (peak to peak)**			0.5		V/ns
tWPH	**Write protect Hold Time**			100	-	ns
tWPS	**Write protect Setup Time**			20	-	ns
tVSL	**VCC(min.) to device operation**			5		ms
tRST	**Device reset time (Idle/ Read/ Program/ Erase)**		2	-	6/6/10/500	us

Notes:

1*: fC(max) is 20MHz for read from cache x1 (03h) if SPI NOR interface is enabled ('SPI_NOR_EN'=1) and the fC(max) is 80MHz for sequential page of continuous read operation.*

2: *the tRST is 5ms for the first RESET command after Power-on.*

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Table 32. Program/ Read/ Erase Characteristics (1Gb/2Gb)

Symbol	Parameter	Min.	Typ.	Max.	Unit
tRD	Data transfer time from Serial Flash array to data register	-	70	80	us
tRD_OTP	Data transfer time from Serial Flash array to data register for OTP Page	-	-	85	us
tRCBSY	Dummy busy time for cache read	-	50	80	us
tPROG	Page Programming time	-	360	760	us
tERS	Block Erase Time	-	4	6	ms
NOP	Number of partial-page programming operation supported			4	Cycle

Table 33. Program/ Read/ Erase Characteristics (4Gb)

Symbol	Parameter	Min.	Typ.	Max.	Unit
tRD	Data transfer time from Serial Flash array to data register	-	110	120	us
tRD_OTP	Data transfer time from Serial Flash array to data register for OTP Page	-	-	125	us
tRCBSY	Dummy busy time for cache read	-	95	120	us
tPROG	Page Programming time	-	400	800	us
tERS	Block Erase Time	-	4	6	ms
NOP	Number of partial-page programming operation supported			4	Cycle

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Figure 45. WP# Setup Timing and Hold Timing during SET FEATURE when BPRWD=1

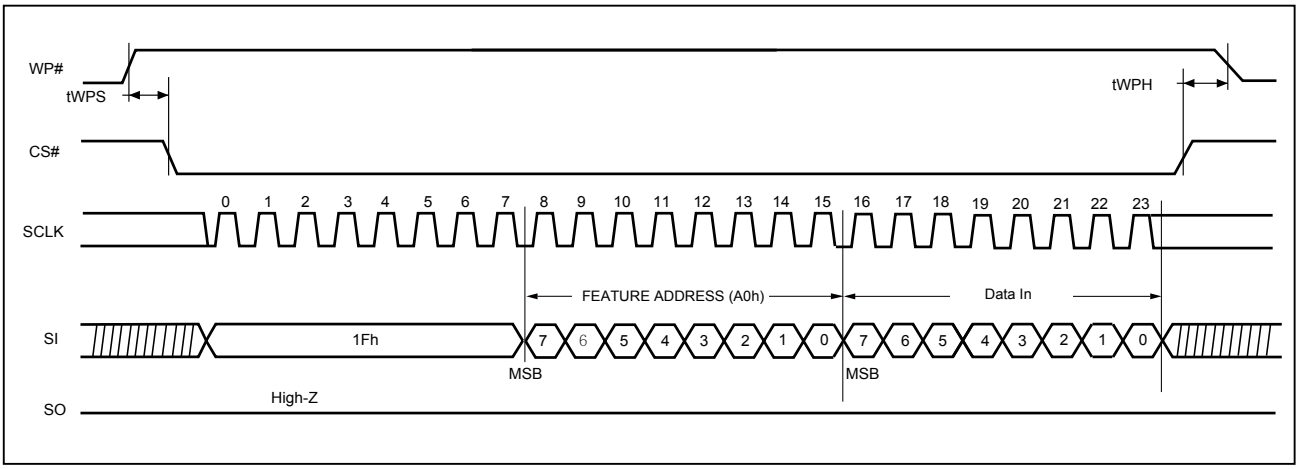


Figure 46. Serial Input Timing

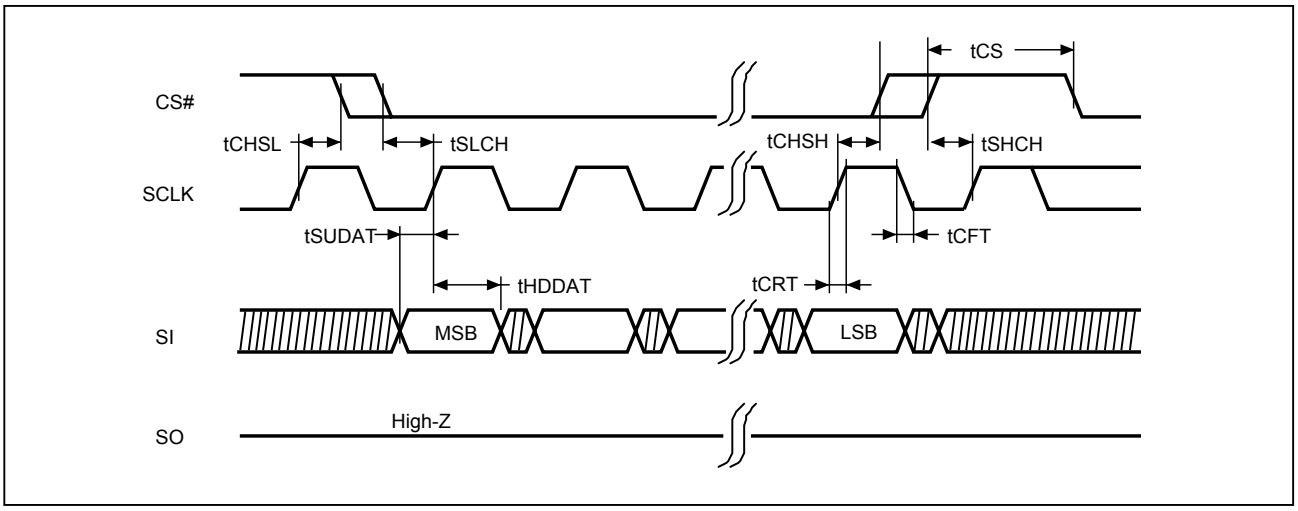
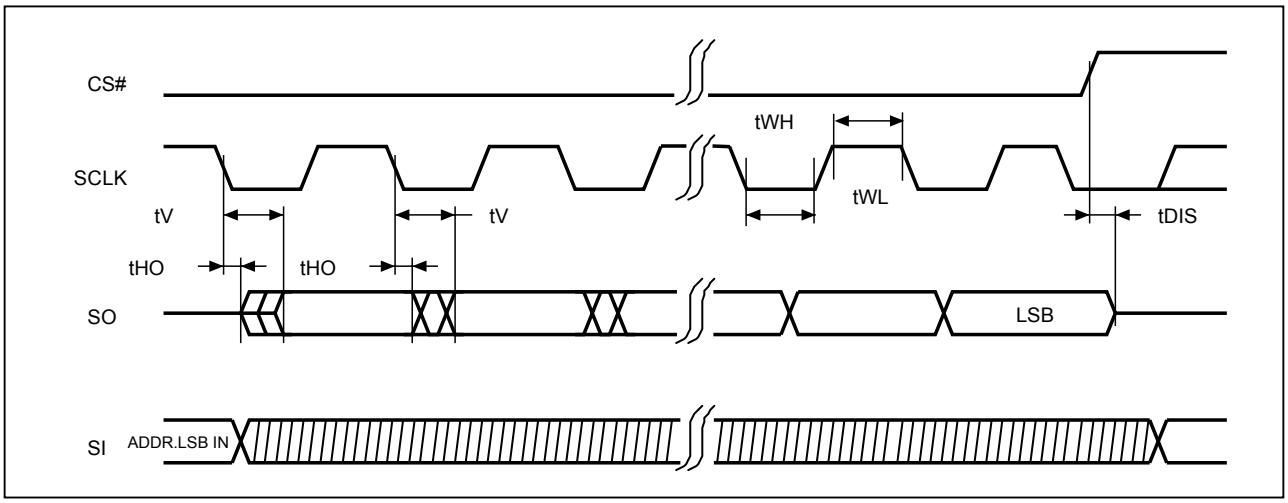
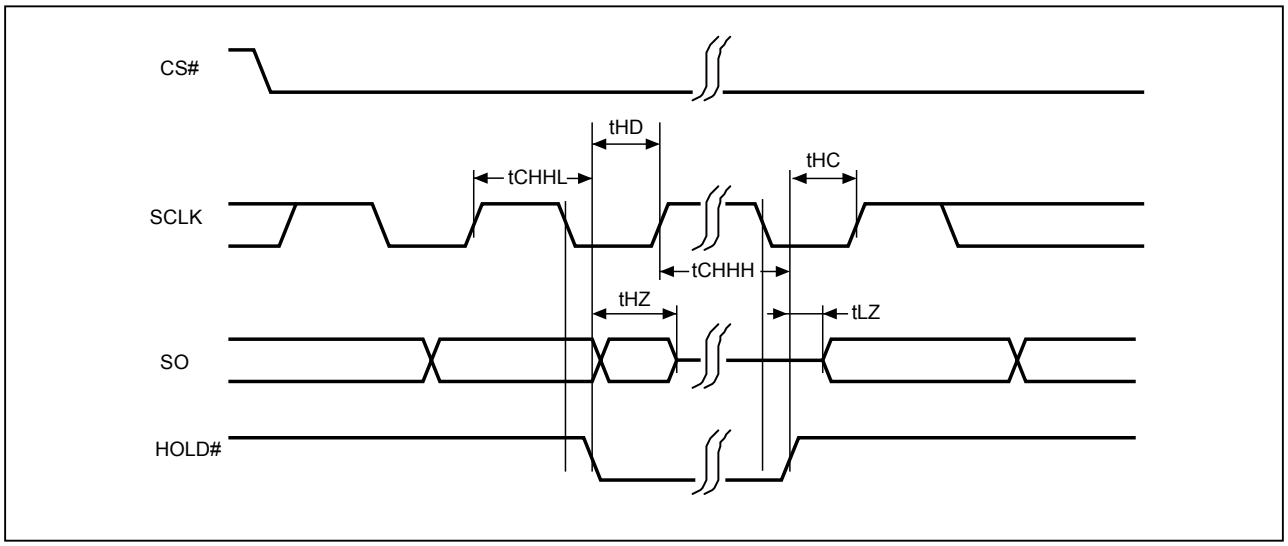


Figure 47. Serial Output Timing



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Figure 48. Hold Timing



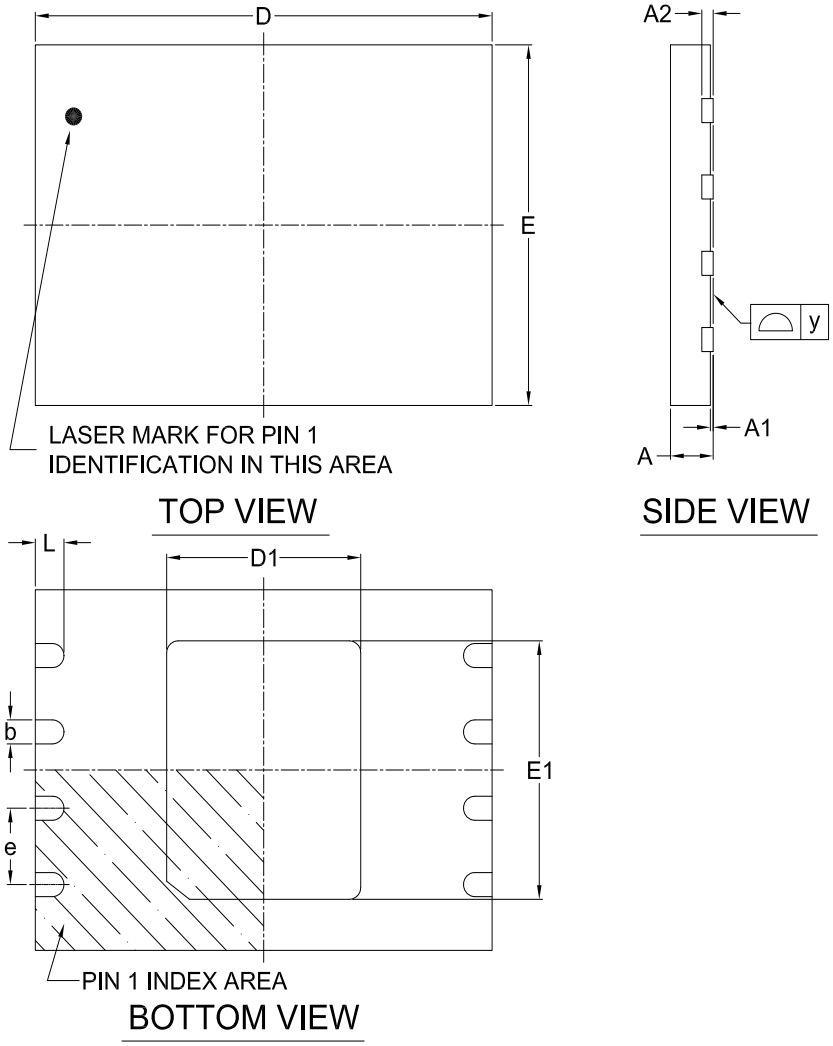
Note: *SI is "don't care" during HOLD operation.*

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15. PACKAGE INFORMATION

15-1. 8-WSON (8x6x0.8mm)

Doc. Title: Package Outline for WSON 8L (8x6x0.8MM, LEAD PITCH 1.27MM, E.P. 3.4x4.3MM)



Note:

This package has an exposed metal pad underneath the package. It is recommended to leave the metal pad floating or to connect it to the same ground as the GND pin of the package. Do not connect the metal pad to any other voltage or signal line on the PCB. Avoid placing vias or traces underneath the metal pad. Connection of this metal pad to any other voltage or signal line can result in shorts and/or electrical malfunction of the device.

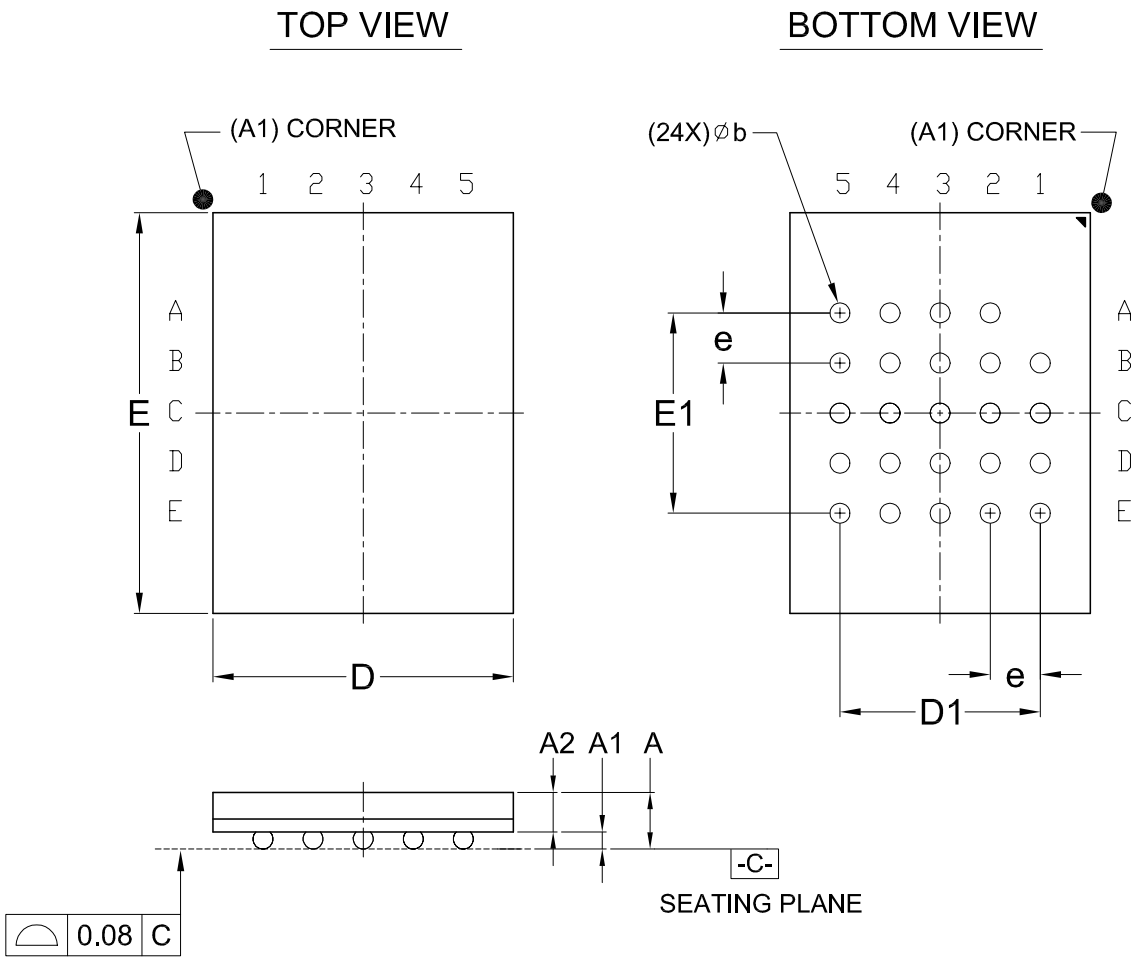
Dimensions (inch dimensions are derived from the original mm dimensions)

SYMBOL / UNIT		A	A1	A2	b	D	D1	E	E1	L	e	y
mm	Min.	0.70	---	---	0.35	7.90	3.35	5.90	4.25	0.45	---	0.00
	Nom.	---	---	0.20	0.40	8.00	3.40	6.00	4.30	0.50	1.27	---
	Max.	0.80	0.05	---	0.48	8.10	3.45	6.10	4.35	0.55	---	0.05
Inch	Min.	0.028	---	---	0.014	0.311	0.132	0.232	0.167	0.018	---	0.00
	Nom.	---	---	0.008	0.016	0.315	0.134	0.236	0.169	0.020	0.05	---
	Max.	0.032	0.002	---	0.019	0.319	0.136	0.240	0.171	0.022	---	0.002

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15-2. 24-BGA (6x8x1.2mm)

Doc. Title: Package Outline for CSP 24BALL (6x8x1.2MM, BALL PITCH 1.0MM, BALL DIAMETER 0.4MM, 5x5 BALL ARRAY)



Dimensions (inch dimensions are derived from the original mm dimensions)

SYMBOL / UNIT		A	A1	A2	b	D	D1	E	E1	e
mm	Min.	---	0.25	0.65	0.35	5.90	---	7.90	---	---
	Nom.	---	0.30	---	0.40	6.00	4.00	8.00	4.00	1.00
	Max.	1.20	0.35	---	0.45	6.10	---	8.10	---	---
Inch	Min.	---	0.010	0.026	0.014	0.232	---	0.311	---	---
	Nom.	---	0.012	---	0.016	0.236	0.157	0.315	0.157	0.039
	Max.	0.047	0.014	---	0.018	0.240	---	0.319	---	---

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16. REVISION HISTORY

Revision	Descriptions	Page
January 22, 2021		
0.00	Initial Release.	ALL
October 13, 2021		
0.01	1. Changed title from "Advanced Information" to "Preliminary".	ALL
	2. Revise SPI clock rate for normal read as 104MHz	P5,68
	3. Modified tDIS values	P68
December 24, 2021		
1.0	1. Removed title of "Preliminary".	ALL
	2. Changed the SPI clock rate of normal read from 104MHz back to 133MHz.	P5,69
	3. Added **"Table 3. Register status of Reset (FFh) command operation"**.	P14
	4. Re-phrase on ECC segment description.	P37
	5. Supplement of 'special OTP configuration register program operation' and added Note 3.	P53
	6. Removal statement of WP# keeps low at power-on/off on 'DEVICE POWER-UP' section and supplement on the state of CS#/SCLK/SI/WP#/HOLD# during power-up.	P66
	7. Modified DC/AC table: added typical spec of ICC1 to ICC4, 4Gb continuous read SPI clock rate is revised from 104MHz to 80MHz.	P69
	8. Added notes for 24-BGA products.	P7
	9. Revised 4Gb spec of tRD/tRD_OTP/tRCBSY and added typical spec of tRD	P5,36,70
January 12, 2022		
1.1	1. Correction on misprint.	P6-7
February 21, 2022		
1.2	1. Supplement the page program in a block should start from low address to high address.	P42

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